TOSHIBA

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2009-9

PRODUCT GUIDE

MOSFETs

SEMICONDUCTOR

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POWER MOSFETS

Toshiba's MOSFET devices meet the needs of a wide range of ultra-high-density applications.

CONTENTS

1 Features and Structures 3

2 Toshiba's MOSFET Product Lines and Part Numbering Schemes 4

2-1 MOSFET Product Lines 4

2-2 Part Numbering Schemes 5

3 Selection Guide (By Absolute Maximum Ratings) 6

4 Low-V_{DSS} MOSFETs (in Small SMD Packages) 16

4-1 Packaging Options 16
- SSM Series
- TPC Series

4-2 Application Examples and Block Diagrams 17
- Cell Phone (Power Supply Circuit)
- Notebook PC (Power Supply Circuit)
- Lithium-Ion Secondary Battery (Battery Protection Circuits)
- Motor Driver (Power Driver Circuit)

4-3 Low-V_{DSS} MOSFET Roadmaps 19
- Roadmap for Trench MOSFETs
- Package Options

4-4 Low-V_{DSS}, High-Speed MOSFETs 21
- Synchronous Rectification DC-DC Converters
  – Block Diagram, Timing Chart and Power Loss Factors
  – Summary Results of Power Loss Simulation and Key Parameters for MOSFETs
  – Efficiency Improvement by Thermally Enhanced Package and New Process Technology
  – MOSBD (MOSFET with SBD)
- High-Speed MOSFET Offerings

4-5 Low-V_{DSS}, Low-$R_{DS(ON)}$ MOSFETs (for Lithium-Ion Battery Protection) 26
- Lithium-Ion Battery Protection Circuit Trend
- MOSFET Roadmap
- Low-ON-resistance N-Channel Power MOSFETs
- Low-ON-resistance P-Channel Power MOSFETs

4-6 Semi-Power MOSFET Offerings 28
- Semi-Power P-Channel Single MOSFETs
- Semi-Power N-Channel Single MOSFETs
- Semi-Power Dual MOSFETs
- MOSFET with a Schottky Barrier Diode
- VS-6 Series … [Part Number: TPC6xxx]
- VS-8 Series … [Part Number: TPCF8xxx]
- PS-8 Series … [Part Number: TPCP8xxx]
- Chip LGA Series ... [Part Number: TPCL4xxx]
- STP2 Series ... [Part Number: TPCT4xxx]
- TSON Advance Series … [Part Number: TPCC8xxx]
- TSSOP Advance Series … [Part Number: TPCM8xxx]
- SOP-8 Series … [Part Number: TPC8xxx]
- SOP Advance Series … [Part Number: TPCA8xxx]
- DPAK Series ... [Part Number: TKxxPxxxM1]

4-7 Standard MOSFET Series (I_D < 500 mA) 36
- Single MOSFETs
- Dual MOSFETs

5 Low-V_{DSS}, High-Q_g MOSFETs 37

5-1 TO-220SM(W) Series 37

5-2 U-MOS (Trench Type) Series 38

5-3 U-MOS Series for Synchronous Rectification (V_{DSS} = 60 V to 150 V) 39

6 Mid- and High-V_{DSS} MOSFETs 40

6-1 π-MOSVII Series (V_{DSS} = 450 V to 650 V) 40

6-2 Super-Junction DTMOS Series (V_{DSS} = 600 V, 650 V) 41

6-3 High-speed π-MOS Series (V_{DSS} = 450 V to 600 V) 42

6-4 π-MOS Series 43

7 MOSFET Part Numbers 46

7-1 Alphanumeric Index of Part Numbers 46

8 Product Obsolescence 53

8-1 End-of-Life Products 53

9 Packaging 55

9-1 Compact Surface-Mount Packages 55

9-2 Through-Hole Packages 66

1 Features and Structures

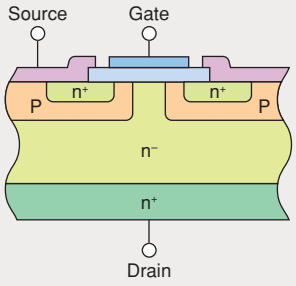
1) No carrier storage effect; superior frequency and switching characteristics
2) Rugged and no current concentration
3) Voltage-controlled device, hence low drive power
4) Easy parallel connection

■ Toshiba MOSFETs have the following additional features:

1) Guaranteed avalanche capability.....	Allows an absorber circuit to be simplified
2) Improved functioning of built-in diodes	Enhanced circuit design flexibility
3) High ruggedness	Increased margin for circuit design
4) High-speed switching	Higher speed in end-product's operation
5) Low $R_{(DS)ON}$	Reduced end-product's power consumption
6) Smaller packages	Reduced end-product size
7) Low drive loss	Reduced end product's power

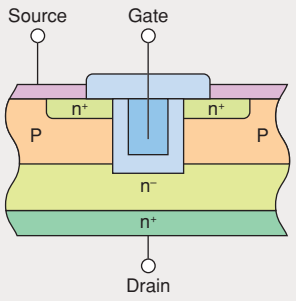
■ Structures of Toshiba MOSFETs

Double-Diffusion Structure



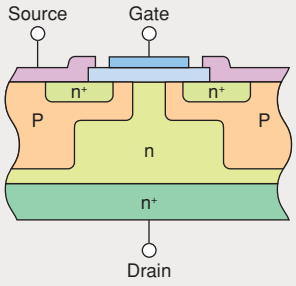
● π-MOS
Toshiba Power MOSFETs use a double-diffusion MOS (D-MOS) structure, which produces high-withstand voltage, to form channels. This structure is especially well suited to high-withstand voltage and high-current devices.
A high level of integration yields a high-performance Power MOSFET with low ON-resistance and low power loss.

Trench Structure



● U-MOS
Higher channel density is achieved by connecting channels vertically to form a U-groove at the gate region, a structure that yields a lower ON-resistance than other MOSFET structures.

Super-Junction Structure



● DTMOS
The super-junction structure, which has P-type pillar layers as shown left, realizes high withstand voltage and ON-resistance lower than the conventional theoretical limit of silicon.

2-1 MOSFET Product Lines

SSM Series (V_{DSS} = 12 V to 60 V)

Very compact and thin, the SSM Series is suitable for use in various electronic devices. The SSM Series is available in a wide range of packages and features low voltage drive.

■ Applications
- Cell phones
- Notebook PCs
- Portable electronic devices
- Small-signal switching

VS and PS Series (V_{DSS} = 12 V to 40 V)

Very compact and thin, the VS and PS Series are suitable for use in various electronic devices.

■ Applications
- Cell phones
- Notebook PCs
- Portable electronic devices

Chip LGA and STP Series (V_{DSS} = 20 V to 30 V)

The LGA and STP Series are housed in an ultra-small and thin package and are suitable for use in lithium-ion secondary battery protection circuits in various portable electronic devices.

■ Applications
- Lithium-ion secondary battery protection circuits

SOP and TSON Series (V_{DSS} = 20 V to 250 V)

The SOP and TSON Series are compact and thin, and require only a small mounting area. They are suitable for lithium-ion secondary battery protection circuits and notebook PCs.

■ Applications
- Lithium-ion secondary battery protection circuits
- Notebook PCs
- Portable electronic devices
- DC-DC converters

TO-220SM(W) Series (V_{DSS} = 40 V to 150 V)

The TO-220SM package, which uses Cu connectors and a wide source terminal, realizes low ON-resistance and a high current-carrying capability.

■ Applications
- Motor drivers
- Switching power supplies

Low-V_{DSS}, High-Q_g U-MOS Series (V_{DSS} = 40 V to 100 V)

High integration is achieved using a trench technology. Low-voltage drive (V_{GS} = 4 V) is possible due to ultra-low ON-resistance.

■ Applications
- Motor drivers
- Solenoids and lamp drivers

U-MOS Series for Synchronous Rectification (V_{DSS} = 60 V to 150 V)

Fabricated using a trench technology, the U-MOS Series is ideal for synchronous rectification on the secondary side of power supply circuits.

■ Applications
- Switching power supplies
- AC adapters
- Motor drivers

New π-MOSVII Series (V_{DSS} = 450 V to 650 V)

The latest addition to the π-MOS portfolio, the π-MOSVII Series offers reduced capacitances due to optimized chip design and is available with a greatly wider range of electrical characteristics.

■ Applications
- Switching power supplies
- AC adapters

Super-Junction DTMOS Series (V_{DSS} = 600, 650 V)

The super-junction DTMOS Series achieves low ON-resistance and low gate charge (Qg) due to the use of the latest super-junction structure.

■ Applications
- Switching power supplies
- AC adapters
- Motor drivers

High-Speed π-MOS Series (V_{DSS} = 450 V to 600 V)

The new High-Speed π-MOS Series achieves higher switching speed than the well-proven π-MOS Series. Two series are available: high-speed switching series and high-speed diode series.

■ Applications
- Inverters
- Switching power supplies
- Motor drivers
- AC adapters

2-2 Part Numbering Schemes

■ Small-Signal MOSFET (SSM) Series

SSM 3 K 101 TU

- **Package**
  - <3-pin>
    - F: S-Mini
    - FU: USM
    - FS: SSM
    - FV: VESM
    - T: TSM
    - TU: UFM
    - CT: CST3
    - CTB: CST3B
  - <4-pin>
    - CT: CST4
  - <5-pin>
    - F: SMV
    - FU: USV
    - FE: ESV
    - TU: UFV
  - <6-pin>
    - FU: US6
    - FE: ES6
    - TU: UF6
    - CTD: CST6D
- **Serial number of the products**
- **Polarity and internal configuration**
  - K: N-channel, single
  - J: P-channel, single
  - N: N-channel, dual
  - P: P-channel, dual
  - L: N-channel and P-channel (dual)
  - E: N-channel and P-channel (pre-wired as a load switch)
  - H: N-channel and SBD
  - G: P-channel and SBD
- **Pin count**
- **Small-Signal MOSFET**

■ Multi-Pin Series

TPCM8 0 01 -H

- **H: High-speed type**
  - None: Low-ON-resistance type
- **Serial number of the products**
- **0: N-channel, single**
  - 1: P-channel, single
  - 2: N-channel, dual
  - 3: P-channel, dual
  - 4: N-channel and P-channel, dual
  - A: N-channel and SBD
  - B: P-channel and SBD
  - J: P-channel and NPN
- **TPC6: VS-6 Series**
  - TPCF8: VS-8 Series
  - TPCP8: PS-8 Series
  - TPCC8: TSON Advance Series
  - TPCS8: TSSOP-8 Series
  - TPCM8: TSSOP Advance Series
  - TPC8: SOP-8 Series
  - TPCA8: SOP Advance Series
  - TPCT4: STP Series
  - TPCL4: Chip LGA

■ New Series

TK 55 A 10 J 1

- **Additional information**
  - 1: Low-capacitance type
  - 3: Low-ON-resistance type
  - 5: Fast body diode type
- **Series**
  - C: π-MOSVI
  - D: π-MOSVII
  - J: U-MOSIII
  - M: U-MOSVI
  - K: U-MOSIV
  - T: DTMOSI
  - U: DTMOSII
- **Voltage: 10% of the V_{DSS}**
- **Package**
  - A: TO-220SIS
  - D: TO-220(W)
  - F: TO-220SM(W)
  - J: TO-3P(N)
  - X: TFP
  - P: DPAK
  - Q: New PW-Mold2
- **Current rating**
- **TK: N-channel**
  - TJ: P-channel

■ Conventional Series

2SK＊＊＊＊

- N-channel MOS

2SJ＊＊＊＊

- P-channel MOS

Selection Guide (By Absolute Maximum Ratings)

V_{DSS} (V) / I_D (A)	12	20	24	30	40	50	60	100	150	180	200	250	400	450	500	525	550	600	650	V_{DSS} (V) / I_D (A)
0.05						⁎2SJ343(50)① ✣2SJ344(50)①															0.05
0.1		✣ SSM3K04FU(12)③ ✣ SSM3K16FU(15)③ ✣ SSM3J16FU(45)③ ☼ SSM3K04FS(12)③ ☼ SSM3K16FS(15)③ ☼ SSM3J16FS(45)③ ☼ SSM3J35FS(44)⑥ ✣ SSM3K03FV(12)③ ✣ SSM3K04FV(12)③ ✣ SSM3K16FV(15)③ ✣ SSM3J16FV(45)③ ✣ SSM3J35MFV(44)⑥ ✦ SSM3K16CT(15)③ ✦ SSM3J16CT(45)③ ✦ SSM3J35CT(44)⑥ ◿ SSM6N04FU(12)③ ◿ SSM6N16FU(15)③ ◿ SSM6P16FU(45)③ ◿ SSM6P35FU(44)⑥ ✚ SSM6N03FE(12)③ ✚ SSM6N16FE(15)③ ✚ SSM6P16FE(45)③ ✚ SSM6L16FE(15)③ ✚ SSM6P35FE(45)⑥ ∧ SSM5N16FU(15)③ ∧ SSM5P16FU(45)③ ✿ SSM5N03FE(12)③ ✿ SSM5N16FE(15)③ ✿ SSM5P16FE(45)③		⁎SSM3K15F(7)③ ⁎SSM3J15F(32)③ ✣ SSM3K15FU(7)③ ✣ SSM3J15FU(32)③ ☼ SSM3K15FS(7)③ ☼ SSM3J15FS(32)③ ✣ SSM3K15FV(7)③ ✣ SSM3J15FV(32)③ ✦ SSM3K15CT(7)③ ✦ SSM3J15CT(32)③ ◿ SSM6N15FU(7)③ ◿ SSM6P15FU(32)③ ∧ SSM5N15FU(7)③ ∧ SSM5P15FU(32)③ ✚ SSM6N15FE(7)③ ✚ SSM6P15FE(32)③ ✿ SSM5N15FE(7)③ ✿ SSM5P15FE(32)③ ☼ SSM3K44FS(7)⑥ ✣ SSM3K44MFV(7)⑥ ◿ SSM6N44FU(7)⑥ ✚ SSM6N44FE(7)⑥		✣ SSM3K17FU(40)② ◿ SSM6N17FU(40)②														0.1
0.18		☼ SSM3K35FS(20)⑥ ✣ SSM3K35MFV(20)⑥ ✦ SSM3K35CT(20)⑥ ◿ SSM6N35FU(20)⑥ ◿ SSM6L35FU(20)⑥ ✚ SSM6N35FE(20)⑥ ✚ SSM6L35FE(20)⑥																			0.18
0.2		✣ SSM3J05FU(4)③ ◿ SSM6P05FU(4)③ ∧ SSM5P05FU(4)③		⁎2SJ305(4)① ⁎2SK2009(2)① ✣ SSM3J09FU(4.2)③ ◿ SSM6P09FU(4.2)③			⁎SSM3K7002BF(3.3)⑥ ◿SSM6N7002BFU(3.3)⑥ ☼ SSM3K7002BFS(3.3)⑥ ◿SSM6N7002FU(3.3)③ ⁎SSM3K7002F(3.3)③ ◿SSM6N7002AFU(3.3)② ⁎SSM3K7002AF(3.3)② ⁎2SJ168(2)① ✣ SSM3K7002FU(3.3)③ ⁎2SK1062(1)① ✣ SSM3K7002AFU(3.3)② ✚SSM6N7002BFE(3.3)⑥													0.2
0.25		⁕ SSM6N37CTD(5.6)⑥																			0.25
0.33		△ SSM3J36TU(3.6)⑥ ☼ SSM3J36FS(3.6)⑥ ✣ SSM3J36MFV(3.6)⑥ ✺ SSM6P36TU(3.6)⑥ ✚ SSM6P36FE(3.6)⑥																			0.33
0.4		◿ SSM6L05FU(1.2)③ ◿ SSM6N05FU(1.2)③ ✣ SSM3K05FU(1.2)③ ∧ SSM5N05FU(1.2)③		◿ SSM6L09FU(1.2)③ ◿ SSM6N09FU(1.2)③ ✣ SSM3K09FU(1.2)③																	0.4
0.5		✪ SSM4K27CT(0.205)⑥ ✺ SSM6L10TU(0.145)⑥ ✺ SSM6L11TU(0.145)⑥ ✺ SSM6L12TU(0.145)⑥ ✺ SSM6N25TU(0.145)⑥ ✺ SSM6N36TU(1.52)⑥ ✺ SSM6P25TU(0.26)⑥ ✺ SSM6P26TU(0.23)⑥ ✚ SSM6J25FE(0.26)⑥ ✚ SSM6J26FE(0.23)⑥ ✚ SSM6K25FE(0.145)⑥ ✺ SSM6L36TU(1.52)⑥ ☼ SSM3K36FS(1.52)⑥ ✣ SSM3K36MFV(1.52)⑥ △ SSM3K36TU(1.52)⑥ ✚ SSM6N36FE(1.52)⑥ ✚ SSM6L36FE(1.52)⑥ ◿ SSM6N43FU(1.52)⑥ ☼ SSM3K43FS(1.52)⑥		✺ SSM6N24TU(0.145)⑥ ✚SSM6K24FE(0.145)⑥									▲ **2SK2998** (20)② ☆ **2SK3302** (18)② ◇ **2SK3471** (18)②						0.5
0.65		◿ SSM6J06FU(0.5)③																			0.65
0.72		✚ SSM6P41FE(0.3)⑥																			0.72
0.77		✚ SSM6N42FE(0.26)⑥																			0.77
0.8		✺ SSM6L13TU(0.143)⑥ ✺ SSM6N29TU(0.143)⑥ ✺ SSM6P28TU(0.234)⑥ ✚ SSM6J205FE(0.234)⑥		◿ SSM6J07FU(0.8)③																	0.8

Legend

Product series ① : π-MOSIII ② : π-MOSV ③ : π-MOSVI ④ : L²-π-MOSV ⑤ : L²-π-MOSVI ⑥ : U-MOS ⑦ : π-MOSVII ⑧ : π-MOSIV ⑨ : DTMOSI ⑩ : DTMOSII

Package ◇PW-Mini ♪VS-8 ♥VS-6 ♠PS-8 ✣STP ▲TO-92MOD ▼PW-Mold ♩New PW-Mold ⊙TSON Advance ♫New PW-Mold2 ▽DP ☆TPS ◀TSSOP Advance ⧗TSSOP-8 ★SOP-8 ☼SOP-8 Lead Clamp ▶SOP Advance ◆TO-220NIS ⊗TO-220SIS ■TO-220AB ⊞TO-220(W) ♣TFP ○TO-220FL/SM ✣TO-220SM(W) □TO-3P(N) ◎TO-3P(N)IS ●TO-3P(L) ⊞Chip LGA ⁎S-Mini ✣TSM ✣USM △UFM ☼SSM ✣VESM ✦CST3 ✧CST3B ✪CST4 ✣SMV ◿US6 ✺UF6 ✚ES6 ⁕CST6D ∧USV ✣UFV ✿ESV

Notes:
( ) = $R_{DS(ON)}$ max
$ = 10-V drive
# = 2.5-V drive
⁎ = 1.8-V drive
V = High-speed diode
N = N-ch
P = P-ch
CN = Complementary N-ch
CP = Complementary P-ch
NS = N-ch + SBD
PS = P-ch + SBD
[ ] = Under development
PD = P-ch + Driver (load switch)

3 Selection Guide (By Absolute Maximum Ratings)

VDSS (V) / ID (A)	12	20	24	30	40	50	60	100	150	180	200	250	400	450	500	525	550	600	800	900	1000	VDSS (V) / ID (A)
1	PS ⁜ SSM5G02TU (0.16)⑥ PS ⁜ SSM5G04TU (0.24)⑥ PD ✺ SSM6E01TU (0.16)⑥	△SSM3J111TU (0.48)⑥		PS ⁜ SSM5G01TU (0.8)⑥			◇ 2SJ360 (0.73)④ ▲ 2SJ507 (0.7)④	◇ 2SK2963 (0.7)④ ▲ 2SK2962 (0.7)④ ◇ 2SJ508 (1.9)④ ▲ 2SJ509 (1.9)④	▲ 2SK3670 (1.7)	◆ 2SJ313 (5.0) ▼ 2SJ338 (5.0) ◆ 2SK2013 (5.0) ▼ 2SK2162 (5.0)	◇ 2SK2992 (3.5)②	CP ★ TPC8404(2.55)② CN ★ TPC8404(1.7)②	▼ 2SK3498 (5.5)②	♫ 2SK4023 (4.6)② ☆ 2SK3374 (4.6)② ▼ 2SK3472 (4.6)②			♩ 2SK3371 (9)② ♫ 2SK4026 (9)②		■ 2SK2733 (9.0)① ▽ 2SK2845 (9)① ▼ 2SK3301 (20)①		1
1.1		◿SSM6K06FU (0.16)③		△SSM3J112TU (0.79)⑥																		1.1
1.2	✚ SSM6J23FE (0.16)⑥	△SSM3K106TU (0.53)⑦ ✺ SSM6P54TU (0.228)⑥ NS ⁜ SSM5H07TU (0.54)⑦ ✚ SSM6K31FE (0.54)⑦ ✚ SSM6K30FE (0.42)⑦																				1.2
1.3		◿SSM6J08FU (0.18)⑥ PS ♠ TPCP8BA1 (0.18)⑥		✚ SSM6J207FE (0.491)⑥							⧗ TPCS8004-H (0.8)⑥											1.3
1.4	NS ⁜ SSM5H03TU (0.3)⑥	✚ SSM6K22FE (0.17)⑥		△SSM3J118TU (0.48)⑥ ✺ SSM6P40TU (0.403)⑥ PS ⁜ SSM5G11TU (0.403)⑥ NS ⁜ SSM5H01TU (0.45)⑥ ✚ SSM6K210FE (0.371)⑥																		1.4
1.5	PS ⁜ SSM5G09TU (0.13)⑥	△SSM3K107TU (0.41)⑦ ✺ SSM6P39TU (0.213)⑥ NS ⁜ SSM5H05TU (0.16)⑥ NS ⁜ SSM5H08TU (0.16)⑥		⁘ SSM3J02T (0.5)③ △SSM3K128TU (0.36)⑥ PS ⁜ SSM5G10TU (0.213)⑥ ◿SSM6K07FU (0.22)③																		1.5
1.6		✚ SSM6N42FE (0.252)⑥ NS ⁜ SSM5H10TU (0.119)⑥ NS ♠ TPCP8AA1 (0.105)⑥ ✺ SSM6L39TU (0.119)⑥ ✺ SSM6N39TU (0.119)⑥ ◿SSM6K08FU (0.105)⑥		⁘ SSM3J313T (0.268)⑥ NS ⁜ SSM5H11TU (0.182)⑥ ✺ SSM6L40TU (0.182)⑥ ✺ SSM6N40TU (0.182)⑥																		1.6
1.7		△SSM3J113TU (0.169)⑥		⁘ SSM3J01T (0.4)③ ⁘ SSM3J305T (0.477)⑥								N ⧗ TPCS8008-H (0.58)②										1.7
1.8	PD ✺ SSM6E03TU (0.144)⑥	△SSM3J108TU (0.158)⑥ △SSM3J114TU (0.149)⑥ PD ✺ SSM6E02TU (0.136)⑥ ✚ SSM6J53FE (0.136)⑥									★ TPC8012-H (0.4)⑥											1.8
1.9				NS ⁜ SSM5H12TU (0.133)⑥ ✚ SSM6K208FE (0.133)⑥							N ⧗ TPCS8007-H (0.45)②											1.9
2		△SSM3J109TU (0.13)⑥ △SSM3K122TU (0.123)⑥ ✺ SSM6K405TU (0.126)⑥ ✚ SSM6J206FE (0.13)⑥ ✚ SSM6K204FE (0.126)⑥ ◇ SSM3J46CTB (0.103)⑥ ✻ SSM3J325F (0.155)⑥		△SSM3J117TU (0.225)⑥ △SSM3K127TU (0.123)⑥ ✺ SSM6J402TU (0.225)⑥			◇ 2SK2615 (0.3)④ ▲ 2SK2961 (0.3)④ ◇ 2SK3658 (0.3)④ ✺ SSM6K407TU (0.44)② ✺ SSM6K32TU (0.44)②					♥ 2SJ610 (2.55)②		⊗ 2SK3757 (2.45)③ ⊗ 2SK3766 (2.45)③	☆ 2SK2599 (3.2)② ♩ 2SK3373 (3.2)②			☆ 2SK2846 (5.0)② ♩ 2SK2865 (5.0)② ⊗ 2SK3767 (4.5)③ ♫ 2SK4002 (5)② ♫ TK2Q60D (4.3)⑦				2
2.1				△SSM3K116TU (0.1)⑥					N ⧗ TPCS8009-H (0.35)②													2.1
2.2		△SSM3J115TU (0.098)⑥ △SSM3K101TU (0.103)⑥		△SSM3K105TU (0.2)③				♠ TPCP8003-H (0.18)⑥ ★ TPC8214-H (0.18)⑥														2.2
2.3	△SSM3J110TU (0.094)⑥ ⁘ SSM3J304T (0.127)⑥			✚ SSM6K202FE (0.085)⑥																		2.3
2.4				⁘ SSM3J306T (0.225)⑥ △SSM3K124TU (0.12)⑦																		2.4
2.5		✺ SSM6J50TU (0.064)⑥		△SSM3K119TU (0.074)⑥ ⁘ SSM3K02T (0.2)③ ✺ SSM6J401TU (0.145)⑥			⁘ SSM3K318T (0.145)⑥				♩ 2SJ567 (2.0)② ♫ 2SJ680 (2.0)②							⊗ TK3A60DA (2.8)⑦		⊗ 2SK3566 (6.4)⑧		2.5
2.6		△ SSM3K102TU (0.071)⑥																				2.6
2.7	⁘ SM3J312T (0.091)⑥	P# ♥ TPC6105 (0.11)⑥ P✻♪ TPCF8301 (0.11)⑥ PS✻♪ TPCF8B01 (0.11)⑥ P✻♪ TPCF8103 (0.11)⑥		⁘ SSM3J14T (0.17)⑥																		2.7
2.8		✚ SSM6K203FE (0.061)⑥																				2.8
2.9				⁘ SSM3K303T (0.12)⑦																		2.9
3	⁘ SSM3J13T (0.07)⑥ ✺ SSM6J21TU (0.05)⑥	N#♪ TPCF8201 (0.049)⑥ NS#♪ TPCF8A01 (0.049)⑥ P#♪ TPCF8302 (0.059)⑥ P✻♪ TPCF8303 (0.058)⑥ △SSM3K104TU (0.056)⑥ ✺ SSM6K404TU (0.055)⑥		⁘ SSM3K12T (0.175)⑦ ✺ SSM6K34TU (0.077)⑥ NS ⁜ SSM5H14F (0.078)⑥				☆ 2SK2200 (0.35)④ ♩ 2SK2201 (0.35)④ ♫ 2SK4018 (0.35)④				♩ 2SK3462 (1.7)② ♫ 2SK4022 (1.7)②			◆ 2SK2862 (3.2)②			♫ 2SK4003 (2.2)③ ♫ (Short lead) 2SK3975 (2.2)③	■ 2SK2603 (3.6)① ○ 2SK2883 (3.6)①	■ 2SK2608 (4.3)① □ 2SK2719 (4.3)① ⊗ 2SK3564 (4.3)⑧		3
3.2		△SSM3K121TU (0.048)⑥ ✚ SSM6K211FE (0.047)⑥		CP♪ TPCF8402 (0.077)⑥ P♪ TPCF8304 (0.072)⑥ ⁘ SSM3K01T (0.12)③																		3.2
3.3		✚ SSM6J212FE (0.0434)⑥																				3.3
3.4				CP ♠ TPCP8402 (0.072)⑥	P ♠ TPCP8403 (0.070)⑥																	3.4
3.5		⁘ SSM3K301T (0.056)⑥ ✻ SSM3J327F (0.095)⑥		⁘ SSM3J314T (0.1)⑥													⊗ TK4A55DA (2.45)⑦		■ 2SK3085 (2.2)② ⊗ 2SK3567 (2.2)③ ⊗ TK4A60DA (2.2)⑦				3.5
3.6		⁘ SSM3J317T (0.107)⑥																				3.6
3.8		P ♠ TPCP8303 (0.04)⑥					N ★ TPC8218-H (0.057)⑥															3.8
3.9					N ♥ TPC6006-H (0.075)⑥																	3.9
4	✺ SSM6J51TU (0.054)⑥	△SSM3J120TU (0.038)⑥ ✺ SSM6K18TU (0.04)⑥		CN♪ TPCF8402 (0.05)⑥ CN ♠ TPCP8404 (0.05)⑥ CP ♠ TPCP8404 (0.05)⑥ ⁘ SSM3K316T (0.065)⑥ ⁘ SSM3K14T (0.067)⑥								N ▸ TPCA8008-H (0.58)②			⊗ TK4A50D (2.0)⑦		⊗ TK4A55D (1.9)⑦	⊗ TK4A60D (1.7)⑦		⊗ 2SK3798 (3.5)⑧	■ 2SK1119 (3.8) ○ 2SK1930 (3.8)	4

Legend

Product series
① : π-MOSIII ② : π-MOSV ③ : π-MOSVI
④ : L²-π-MOSV ⑤ : L²-π-MOSVI ⑥ : U-MOS ⑦ : π-MOSVII
⑧ : π-MOSIV ⑨ : DTMOSI ⑩ : DTMOSII

Package
◇PW-Mini ♪VS-8 ♥ VS-6 ♠ PS-8 ✧ STP ▲ TO-92MOD ▼PW-Mold ♩ New PW-Mold ⊙ TSON Advance
♫ New PW-Mold2 ▽ DP ☆TPS ◀ TSSOP Advance ⧗ TSSOP-8 ★ SOP-8
☼ SOP-8 Lead Clamp ▶ SOP Advance ◆ TO-220NIS ⊗ TO-220ISIS ■ TO-220AB ⊞ TO-220(W) ♣ TFP ○ TO-220FL/SM
❖ TO-220SM(W) □ TO-3P(N) ◎ TO-3P(N)IS ● TO-3P(L) ▦ Chip LGA
✻ S-Mini ⁘ TSM ✧ USM △ UFM ☼ SSM ✣ VESM ✦ CST3 ◇ CST3B ✪ CST4 ✣ SMV ◿ US6 ✺ UF6
✚ ES6 ✷ CST6D ∧ USV ❉ UFV ✿ ESV

Notes:
( ) = $R_{DS(ON)}$ max
$ = 10-V drive
# = 2.5-V drive
✻ = 1.8-V drive
¥ = High-speed diode
N = N-ch
P = P-ch
CN = Complementary N-ch
CP = Complementary P-ch
NS = N-ch + SBD
PS = P-ch + SBD
[ ] = Under development
PD = P-ch + Driver (load switch)

3 Selection Guide (By Absolute Maximum Ratings)

VDSS (V) / ID (A)	12	20	24	30	40	50	60	100	150	180	200	250	400	450	500	525	550	600	650	700	800	900	1000	VDSS (V) / ID (A)
4.2		△SSM3K123TU (0.028)⑥ ✺SSM6K403TU (0.028)⑥		N♠TPCP8201 (0.05)⑥ CN♠TPCP8402 (0.077)⑥ ⊹SSM3K320T (0.077)⑥																				4.2
4.4		△SSM3J130TU (0.0258)⑥		✺SSM6K406TU (0.0385)⑥																				4.4
4.5		P#♥TPC6107 (0.055)⑥		P♥TPC6108 (0.06)⑥ CP★TPC8405 (0.033)⑥								♩2SK3342 (1.0)② ♫2SK4021 (1.0)②													4.5
4.6		△SSM3J129TU (0.046)⑥																						4.6
4.7		⊹SSM3K309T (0.031)⑥			N♠TPCP8403 (0.040)⑧ N♠TPCP8203 (0.040)⑥																			4.7
4.8					P♠TPCP8103-H (0.040)⑥																			4.8
5	△SSM3J132TU (0.0178)⑥	★TPC8208 (0.05)⑥ ⧗TPCS8209 (0.03)⑥ N#⧗TPCS8210 (0.03)⑥ P#⧗TPCS8303 (0.021)⑥ P⧗TPCS8302 (0.035)⑥ P♠TPCP8301 (0.031)⑥ P♠TPCP8302 (0.033)⑥ ⊹SSM3J307T (0.031)⑥ ⊹SSM3K310T (0.028)⑥		⧗TPCS8209 (0.05)⑥ N♪TPCF8001 (0.032)⑧ P★TPC8104-H (0.065)⑥ N♥TPC6007-H (0.054)⑥ P♥TPC6109-H (0.059)⑥		▲2SK2989 (0.15)④ ▲2SJ537 (0.19)④	♩2SJ668 (0.17)⑥ ♫2SJ681 (0.17)⑥ ☆2SJ378 (0.19)④ ☆2SJ669 (0.17)⑥ ◆2SJ438 (0.19)④ ☆2SK2229 (0.16)④ ♫2SK4017 (0.1)⑥ ♩2SK4033 (0.1)⑥ ★TPC8213-H (0.05)⑥	♩2SK2399 (0.23)④ ☆2SK2400 (0.23)④ ♫2SK4019 (0.23)④	▼2SK3205 (0.52)		◆2SJ407 (1.0)② ◆2SK2381 (0.8)② ☆2SK2835 (0.8)② ♩2SK2920 (0.8)② ♫2SK4020 (0.8)②	◆2SJ512 (1.25)②			○2SK2991 (1.5)② ♣2SK3466 (1.5)② ▽2SK3863 (1.5)③ ♩2SK4103 (1.5)③ ¥○2SK3417 (1.8)② ¥⊗2SK3868 (1.7)③ ⊗TK5A50D (1.5)⑦		⊗TK5A55D (1.88)⑦		⊗TK5A65D (1.45)⑦	◆2SK2274 (1.7)	○2SK2884 (2.2)①	⊗2SK3565 (2.5)⑧ □2SK3700 (2.5)⑧ ⊗2SK3742 (2.5)⑧	□2SK1359 (3.8)	5
5.2		⊹SSM3J321T (0.046)⑥																						5.2
5.5	PD✻♠TPC8401 (0.038)⑥ P♥TPC6103 (0.035)⑥	P✻♥TPC6111 (0.04)⑥		N★TPC8211 (0.036)⑥ N♠TPCP8202 (0.023)⑥							N▶TPCA8010-H (0.45)②		○2SK2838 (1.2)② ◆2SK2679 (1.2)②				⊗TK6A55DA (1.48)⑦							5.5
5.6		P#♠TPCP8101 (0.030)⑥		⊹SSM3J326T (0.0457)⑥																				5.6
6	P✻♪TPCF8101 (0.028)⑥	N◌TPCT4201 (0.031)⑥ N◌TPCT4203 (0.031)⑥ N#♥TPC6004 (0.024)⑥ P✻♪TPCF8102 (0.030)⑥ ★TPC8207 (0.02)⑥ ⧗TPCS8211 (0.024)⑥ ⧗TPCS8204 (0.017)⑥ P#⧗TPCS8102 (0.02)⑥ P#⧗TPCS8302 (0.035)⑥ N#⧗TPCS8212 (0.024)⑥ N#⧗TPCS8208 (0.017)⑥ N⧗TPCS8213 (0.013)⑥ N▦TPCL4201 (0.031)⑥	N▦TPCL4203 (0.036)⑥	N◌TPCT4202 (0.038)⑥ N◌TPCT4204 (0.038)⑥ N♥TPC6011 (0.020)⑥ N#♥TPC6005 (0.028)⑧ PD♠TPCP8J01 (0.035) (-32V)⑥ P♪TPCF8104 (0.028)⑥ N⧗TPCS8214 (0.135)⑥ NS★TPC8A01 (0.025)⑥ ★TPC8212-H (0.021)⑥ CN★TPC8405 (0.026)⑥ ⊹SSM3K315T (0.0415)⑥ N▦TPCL4202 (0.04)⑥ △SSM3K131TU (0.0415)⑥						◆2SJ516 (0.8)②		⊗TK6A50D (1.48)⑦	⊗TK6A53D (1.3)⑦ ▽TK6P53D (1.3)⑦		□2SK2602 (1.25)② ○2SK2777 (1.25)② ♣2SK3312 (1.25)② ⊗TK6A60D (1.25)⑦ ¥⊗2SK3947 (1.4)③	⊗TK6A65D (1.11)⑦		⊗2SK4013 (1.7)⑧	⊗2SK4014 (2.0)⑧		6
6.5				N★TPC8216-H (0.020)⑥																	○2SK3879 (1.7)⑧ ◎2SK3880 (1.7)⑧			6.5
7				N♪TPCF8001 (0.023)⑥ N♪TPCF8002 (0.023)⑥	CNTPC8406-H (0.027)⑥ CPTPC8406-H (0.03)⑥				N▶TPCA8009-H (0.35)②												□2SK3633 (1.7)⑧	□2SK4115 (2.0)⑧	◎2SK1365 (1.8)	7
7.2		P#♠TPCP8102 (0.018)⑥		N♠TPCP8001-H (0.016)⑥																				7.2
7.5					N▶TPCA8020-H (0.027)⑥ N★TPC8022-H (0.027)⑥ P★TPC8116-H (0.03)⑥ P▶TPCA8107-H (0.03)⑥							◆2SK2417 (0.5)② ■2SK2914 (0.5)②					⊗TK8A55DA (1.07)⑦	⊗TK8A60DA (1.0)⑦						7.5
8				N★TPC8210 (0.015)⑥ N★TPC8021-H (0.017)⑥	P★TPC8110 (0.025)⑥										■2SK2542 (0.85)② ○2SK2776 (0.85)② ♣2SK3538 (0.85)② ⊗TK8A50D (0.85)⑦ ¥⊗2SK4042 (0.97)③				⊗TK8A65D (0.84)⑦		◎2SK2606 (1.2)①	◎2SK2847 (1.4)① ⊗2SK3799 (1.3)⑧	□2SK2613 (1.7)①	8
8.3				N♠TPCP8004 (0.009)⑥																				8.3
8.5				NS★TPC8A01 (0.018)⑤													⊗TK9A55DA (0.86)⑦						◎2SK3017 (1.25)①		8.5
9		N♠TPCP8006 (0.01)⑥					N◌TPC8053-H (0.0225)⑥				◆2SK2350 (0.4)②		◆2SK2952 (0.55)②								□2SK2607 (1.2)①	□2SK3473 (1.6)⑧ □2SK3878 (1.3)⑧		9
9.5		✺SSM6J409TU (0.0221)⑥																						9.5
10		P★TPC8115 (0.01)⑥		P★TPC8109 (0.02)⑥ P★TPC8119 (0.012)⑥ NS◌TPC8A05-H (0.012)⑥				♩2SK3669 (0.125)⑦		□2SJ200 (0.83) □2SK1529 (0.83) □2SK3497 (0.15) □2SJ618 (0.37)			■2SK2841 (0.55)② ○2SK2949 (0.55)②	○2SK3309 (0.65)② ◆2SK3310 (0.65)② ⊗2SK3869 (0.68)③	□2SK2601 (1.0)② ⊗TK10A50D (0.72)⑦			■2SK2866 (0.75)② ○2SK2889 (0.75)② ♣2SK3438 (1.0)② ○2SK3437 (1.0)② ○2SK3399 (0.75)② ⊗TK10A60D (0.75)⑦ ¥⊗2SK4015 (0.86)③		◆2SK3265 (1.0)⑧ ◎2SK3453 (1.0)⑧		□2SK2968 (1.25)①		10

Legend

Product series ① : π-MOSIII ② : π-MOSV ③ : π-MOSVI ④ : L²-π-MOSV ⑤ : L²-π-MOSVI ⑥ : U-MOS ⑦ : π-MOSVII ⑧ : π-MOSIV ⑨ : DTMOSI ⑩ : DTMOSII

Package ◇PW-Mini ♪VS-8 ♥VS-6 ♠PS-8 ◌STP ▲TO-92MOD ▼PW-Mold ♩New PW-Mold ⊙TSON Advance ♫New PW-Mold2 ▽DP ☆TPS ◀TSSOP Advance ⧗TSSOP-8 ★SOP-8 ◌SOP-8 Lead Clamp ▶SOP Advance ◆TO-220NIS ⊗TO-220SIS ■TO-220AB ⊞TO-220(W) ♣TFP ○TO-220FL/SM ✣TO-220SM(W) □TO-3P(N) ◎TO-3P(N)IS ●TO-3P(L) ⊞Chip LGA ⁎S-Mini ⁘TSM ⁘USM △UFM ☼SSM ✣VESM ✦CST3 ✧CST3B ✪CST4 ✣SMV ◿US6 ✺UF6 ✚ES6 ✷CST6D ⋀USV ❖UFV ✿ESV

Notes:
( ) = $R_{DS(ON)}$ max
$ = 10-V drive
# = 2.5-V drive
⁎ = 1.8-V drive
¥ = High-speed diode
N = N-ch
P = P-ch
CN = Complementary N-ch
CP = Complementary P-ch
NS = N-ch + SBD
PS = P-ch + SBD
[ ] = Under development
PD = P-ch + Driver (load switch)

3 Selection Guide (By Absolute Maximum Ratings)

V_{DSS} (V) / I_D (A)	20	30	40	50	60	75	80	100	150	200	250	300	450	500	525	550	600	900/1000	V_{DSS} (V) / I_D (A)
11		N★**TPC8025** (0.009)⑥ N★**TPC8021-H** (0.017)⑥ N★**TPC8014** (0.014)⑥ P★**TPC8111** (0.012)⑥ P★**TPC8113** (0.01)⑥ P ⧗ **TPCS8105** (0.0135)⑥ P ⧗ **TPCS8104** (0.012)⑥ N★**TPC8030** (0.0095) N★**TPC8031-H** (0.0133)⑥ N♣**TPCP8005-H** (0.0129)⑥ P★**TPC8121** (0.012)⑥ P◌**TPC8123** (0.0090)⑥			N◌**TPC8050-H** (0.0145)⑥					◆**2SK2965** (0.26)②						⊗**TK11A55D** (0.63)⑦	⊗**TK11A60D** (0.65)⑦		11
12		N◌**TPC8037-H** (0.0114)⑥ N◌**TPC8038-H** (0.0114)⑥ NS◌**TPC8A06-H** (0.0101)⑥	N◌**TPC8052-H** (0.0115)⑥					◆**2SJ380** (0.21)④		●**2SJ201** (0.625) ●**2SK1530** (0.625)				○ **2SK3068** (0.52)② ♣**2SK3398** (0.52)② ⊗ **TK12A50D** (0.52)⑦ ¥◆**2SK3313** (0.62)②	⊗**TK12A53D** (0.58)⑦ ♣**TK12X53D** (0.58)⑦	□**TK12J55D** (0.57)⑦	□**2SK2699** (0.65)② ⊗**TK12A60U** (0.4)⑩ ⊞**TK12D60U** (0.4)⑩ □**TK12J60U** (0.4)⑩ ⊗**TK12A60D** (0.55)⑦	**1000V:** ●**2SK1489** (1.0)	12
12.5														⊗ **TK13A50DA** (0.47)⑦					12.5
13		N★**TPC8041** (0.007)⑥ N★**TPC8026** (0.0066)⑥ P★**TPC8107** (0.007)⑥ P◌**TPC8112** (0.006)⑥ P◌**TPC8118** (0.007) N◉**TPCC8003-H** (0.0169)⑥ N◌**TPC8040-H** (0.0097)⑥			N◌**TPC8049-H** (0.0107)⑥		N◌**TPC8051-H** (0.0097)⑥				◆**2SK2508** (0.25)② ○ **2SK2598** (0.25)②		◆**2SK3743** (0.4)② ○ **2SK3403** (0.4)② ♣**2SK3544** (0.4)② ⊗ **TK13A45D** (0.46)⑦	⊗ **TK13A50D** (0.4)⑦			⊗**TK13A60D** (0.43)⑦ ¥⊗**2SK4016** (0.5)③	**900V:** □**2SK4207** (0.95)	13
14					◆**2SJ304** (0.12) **2SJ312** (0.12)									◎**2SK2916** (0.4)②		⊗**TK14A55D** (0.37)⑦	□**2SK3903** (0.44)③		14
15		N◌**TPC8032-H** (0.0065)⑥ P◉**TPCC8102** (0.0189)⑥			▶ **TPCA8053-H** (0.0223)⑥					◆**2SK2382** (0.18)② ○ **2SK2401** (0.18)②				⊗ **TK15A50D** (0.3)⑦ ¥□**2SK3314** (0.49)② □ **TK15J50D** (0.4)⑦			◎**2SK2953** (0.4)② ⊗**TK15A60U** (0.3)⑩ ⊞**TK15D60U** (0.3)⑩ □**TK15J60U** (0.3)⑩ ⊗**TK15A60D** (0.37)⑦		15
16		NS★**TPC8A02-H** (0.0056)⑥	N◌**TPC8047-H** (0.0076)⑥		N◌**TPC8048-H** (0.0069)⑥			○ **2SJ412** (0.21)④ ♣**2SJ619** (0.21)④								□**TK16J55D** (0.37)⑦			16
17		N◌**TPC8033-H** (0.0053)⑥ NS◌**TPC8A03-H** (0.0056)⑥ N◌**TPC8039-H** (0.006)⑥											⊗**2SK3935** (0.25)③	□ **2SK3905** (0.31)③					17
18		P◌**TPC8114** (0.0045)⑥ N★**TPC8027** (0.0027)⑥ N★**TPC8028** (0.0043)⑥ N★**TPC8029** (0.0038)⑥ N◌**TPC8034-H** (0.0035)⑥ N★**TPC8042** (0.0034)⑥ P◌**TPC8117** (0.0039)⑥ N◌**TPC8036-H** (0.0045)⑥ NS◌**TPC8A04-H** (0.0036)⑥ P◌**TPC8120** (0.0032)⑥ P◉**TPCC8103** (0.012)⑥ N◌**TPC8035-H** (0.0032)⑥ N◌**TPC8060-H** (0.0037)⑥	N◌**TPC8045-H** (0.0039)⑥ N◌**TPC8046-H** (0.0057)⑥					◆**2SJ464** (0.12)④ ♣**2SJ620** (0.09)④ ▶ **TPCA8006-H** (0.067)	◆**2SK2882** (0.12)② ♣**2SK3387** (0.12)④					◎**2SK2917** (0.27)② ⊗**TK18A50D** (0.27)⑦					18
19													□**2SK3904** (0.26)③						19
20		NS◀ **TPCM8A05-H** (0.0129)⑥ NS▶ **TPCA8A05-H** (0.0129)⑥ N◀ **TPCM8001-H** (0.0095)⑥	N▶ **TPCA8052-H** (0.0115)⑥	▽**2SK2614** (0.046)④	◆**2SJ349** (0.045)④ ○ **2SJ401** (0.045)④ ▽**2SK2782** (0.055)④			◆**2SK2391** (0.085)④ ⊗ **TJ20A10M3** (0.090)⑥			○ **2SK2993** (0.105)② ♣**2SK3445** (0.105)② ◆**2SK3994** (0.105)②			□ **TK20J50D** (0.27)⑦			□ **2SK3911** (0.32)③ ⊗ **TK20A60U** (0.19)⑩ ⊞ **TK20D60U** (0.19)⑩ □ **TK20J60U** (0.19)⑩ ¥□ **2SK3906** (0.33)③		20
21		N◀ **TPCM8003-H** (0.0129)⑥ NS◉**TPCC8A01-H** (0.0099)⑥																	21
22		N◉**TPCC8001-H** (0.0083)⑥ N◉**TPCC8002-H** (0.0083)⑥ N◉**TPCC8006-H** (0.008)⑥						▶**TPCA8022-H** (0.026)⑥											22
23		N ▶**TPCA8040-H** (0.0094)⑥												□**2SK3907** (0.23)③ ¥□ **2SK3936** (0.25)③					23

Legend

Product series
① : π-MOSIII ② : π-MOSV ③ : π-MOSVI
④ : L²-π-MOSV ⑤ : L²-π-MOSVI ⑥ : U-MOS ⑦ : π-MOSVII
⑧ : π-MOSIV ⑨ : DTMOSI ⑩ : DTMOSII

Package
◇PW-Mini ♪VS-8 ♥VS-6 ♠PS-8 ✣STP ◢TO-92MOD ▼PW-Mold ♩New PW-Mold ⊙TSON Advance
☼SOP-8 Lead Clamp ▶SOP Advance ◆TO-220NIS ⊗TO-220SIS ■TO-220AB ⊞TO-220(W) ♣TFP ○TO-220FL/SM
⁎S-Mini ✣TSM ⁘USM △UFM ☼SSM ✣VESM ✦CST3 ✧CST3B ✪CST4 ✣SMV ◿US6 ✺UF6
♫New PW-Mold2 ▽DP ☆TPS ◀TSSOP Advance ⧗TSSOP-8 ★SOP-8
❖TO-220SM(W) □TO-3P(N) ◎TO-3P(N)IS ●TO-3P(L) ⊞Chip LGA
✚ES6 ✷CST6D ⋀USV ❉UFV ✿ESV

Notes:
( ) = $R_{DS(ON)}$ max
$ = 10-V drive
# = 2.5-V drive
⁎ = 1.8-V drive
¥ = High-speed diode
N = N-ch
P = P-ch
CN = Complementary N-ch
CP = Complementary P-ch
NS = N-ch + SBD
PS = P-ch + SBD
[ ] = Under development
PD = P-ch + Driver (load switch)

Selection Guide (By Absolute Maximum Ratings)

V_{DSS} (V) / I_D (A)	20	30	40	50	60	75	80	100	150	200	250	300	450	500	525	550	600	900/1000	V_{DSS} (V) / I_D (A)
24		N◀ **TPCM8004-H** (0.011)⑥ N▶ **TPCA8030-H** (0.011)⑥ N▶ **TPCA8031-H** (0.011)⑥			N▶**TPCA8050-H** (0.0142)⑥														24
25		P◀ **TPCM8102** (0.0077)⑥ N◀ **TPCM8006** (0.007)⑥ N⊙ **TPCC8008** (0.0068)⑥		◆**2SK2507** (0.046)④	◆**2SK2232** (0.046)④ ○ **2SK2311** (0.046)④ N▶**TPCA8016-H** (0.021)⑥			⊗**TK25A10K3** (0.040)⑥		♣**2SK3444** (0.082)② ○ **2SK3625** (0.082)②				●**2SK1544** (0.2)					25
26		N⊙ **TPCC8005-H** (0.0064)⑥	◆**2SK3846** (0.016)④																26
27	N⊙ **TPCC8007** (0.0046)⑥							■ **2SK2314** (0.085)④ ○ **2SK2789** (0.085)④											27
28					N▶**TPCA8049-H** (0.0104)⑥		N▶**TPCA8051-H** (0.0094)⑥												28
30		N▶**TPCA8018-H** (0.0062)⑥ N◀**TPCM8002-H** (0.0062)⑥	N▶**TPCA8014-H** (0.009)⑥ N▶**TPCA8027-H** (0.010)⑥		◆**2SJ334** (0.038)④ ○ **2SJ402** (0.038)④ ⊗**TK30A06J3A (0.026)**⑥				♣ **2SK3443** (0.055)②	□ **2SK3176** (0.052)②	□ **2SK2967** (0.068)② ◎ **2SK2995** (0.068)②								30
32			○ **2SK3847** (0.016)⑥ N▶**TPCA8047-H** (0.0073)⑥									● **2SK1486** (0.095)							32
34		NS▶**TPCA8A02-H** (0.0053)⑥ N▶**TPCA8039-H** (0.0057)⑥																	34
35		N▶**TPCA8024** (0.0043)⑥	N▶**TPCA8015-H** (0.0054)⑥		◆**2SK3662** (0.0125)⑥ N▶**TPCA8048-H** (0.0066)⑥														35
36					◆**2SK2385** (0.03)④														36
38		NS▶**TPCA8A08-H** (0.0042)⑥ N▶**TPCA8036-H** (0.0038)⑥	N▶**TPCA8046-H** (0.0054)⑥																38
40	N▶**TPCA8011-H** (0.0035)⑥	P▶**TPCA8102** (0.006)⑥ P▶**TPCA8103** (0.0042)⑥ P▶**TPCA8106** (0.0037)⑥ N▶**TPCA8012-H** (0.0049)⑥ N▶**TPCA8025** (0.0036)⑥ N▷**TK40P03M1** (0.0108)⑥	P▶**TPCA8108** (0.0095)⑥ N▷**TK40P04M1** (0.011)⑥		P▶**TPCA8104** (0.016)⑥	⊗**TK40A08K3** (0.009)⑥		⊞**TK40D10J1** (0.015)⑥ ⊗**TK40A10J1** (0.015)⑥ ⊗**TK40A10K3** (0.015)⑥ ♣ **TK40X10J1** (0.020)⑥								□ **TK40J60T** (0.08)⑨		40
44		NS▶**TPCA8A04-H** (0.0032)⑥																	44
45		$□**2SK3506** (0.02) N▶**TPCA8019-H** (0.0031)⑥ N▶**TPCA8026** (0.0022)⑥ N▶**TPCA8042** (0.0033)⑥ N▶**TPCA8060-H** (0.0034)⑥		$□**2SK2550** (0.03)④ ◆ **2SK2886** (0.02)④ $□**2SK2744** (0.02)④ $○**2SK3051** (0.03)④	□ **2SK2233** (0.03)④ ○ **2SK2266** (0.03)④ ○ **2SK2376** (0.017)④ $□**2SK2398** (0.03)④ ◆**2SK3844** (0.0058)⑥														45
46			N▶**TPCA8045-H** (0.0036)⑥																46
50		N▶**TPCA8028-H** (0.0028)⑥ N▷**TK50P03M1** (0.0075)⑥	N▷**TK50P04M1** (0.0087)⑥	$□**2SK2551** (0.011)④ □ **2SK2745** (0.0095)④	□ **2SK2173** (0.017)④ $□**2SK2445** (0.018)②			□ **2SK1381** (0.032)	♣ **TK50X15J1** (0.03)⑥ ✣ **TK50F15J1** (0.03)⑥					●**2SK3132** (0.09)② ¥●**2SK3131** (0.11)②					50
55								⊞**TK55D10J1** (0.0105)⑥ ⊗**TK55A10J1** (0.0105)⑥											55
60					● **2SK2267** (0.011)④ □ **2SK2313** (0.011)④	⊞**TK60D08J1** (0.0078)⑥ ⊗**TK60A08J1** (0.0078)⑥		● **2SK1382** (0.020)											60
70			□**TK70J04J3** (0.0038)⑥ ♣**TK70X04K3** (0.0056)⑥ ♣**TK70X04K3L** (0.0056)⑥		□ **2SK3845** (0.0058)⑥ ⊞**TK70D06J1** (0.0064)⑥ ⊗ **TK70A06J1** (0.0064)⑥ ⊗ **TJ70A06J3** (0.008)⑥ ♣ **TK70X06K3** (0.008)⑥														70
75			♣**2SK3843** (0.0035)⑥		♣ **2SK4034** (0.0058)⑥ ♣ **2SK3842** (0.0058)⑥														75
80			♣**TK80X04K3**(0.0035)⑥			⊗**TK80A08K3** (0.0045)⑥ ⊞**TK80D08K3** (0.0045)⑥													80
100			✣**TK100F04K3** (0.003)⑥ ✣**TK100F04K3L** (0.003)⑥		✣**TK100F06K3** (0.005)⑥														100
120					✣**TJ120F06J3** (0.008)⑥														120
130					✣**TK130F06K3** (0.0034)⑥														130
150			✣**TK150F04K3** (0.0021)⑥ ✣**TK150F04K3L** (0.0021)⑥																150

Legend

Product series
①：π-MOSIII ②：π-MOSV ③：π-MOSVI
④：L²-π-MOSV ⑤：L²-π-MOSVI ⑥：U-MOS ⑦：π-MOSVII
⑧：π-MOSIV ⑨：DTMOSI ⑩：DTMOSII

Package
◇PW-Mini ♪VS-8 ♥VS-6 ♠PS-8 ✣STP ▲TO-92MOD ▼PW-Mold ♩New PW-Mold ⊙TSON Advance ♫New PW-Mold2 ▽DP ☆TPS ◀TSSOP Advance ⧗TSSOP-8 ★SOP-8
✡SOP-8 Lead Clamp ▶SOP Advance ◆TO-220NIS ⊘TO-220SIS ■TO-220AB ⊞TO-220(W) ♣TFP ○TO-220FL/SM ✣TO-220SM(W) □TO-3P(N) ◎TO-3P(N)IS ●TO-3P(L) ⊞Chip LGA
✳S-Mini ✣TSM ✣USM △UFM ☼SSM ✣VESM ✦CST3 ✧CST3B ✪CST4 ✣SMV ◿US6 ✺UF6 ✚ES6 ✷CST6D ∧USV ❉UFV ✿ESV ▷DPAK

Notes:
( ) = $R_{DS(ON)}$ max
$ = 10-V drive
# = 2.5-V drive
✻ = 1.8-V drive
¥ = High-speed diode
N = N-ch
P = P-ch
CN = Complementary N-ch
CP = Complementary P-ch
NS = N-ch + SBD
PS = P-ch + SBD
[ ] = Under development
PD = P-ch + Driver (load switch)

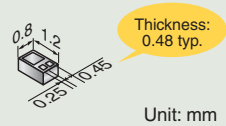
4-1 Packaging Options

SSM Series

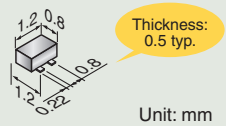
The SSM Series comes in small, thin packages suitable for portable devices. Chip-scale packages (1006 size) help reduce system size.

CST3
Chip-Scale Package, Transfer Molded, 3-Pin
Typical product: SSM3K35CT

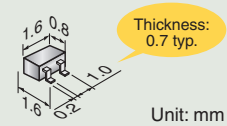
Thickness: 0.38 typ.
Unit: mm

CST3B
Chip-Scale Package, Transfer Molded, 3-Pin, B-Type
Typical product: SSM3J46CTB


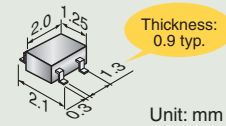
Thickness: 0.48 typ.
Unit: mm

VESM (SOT-723)
Very Extreme Super-Mini
Typical product: SSM3K35MFV


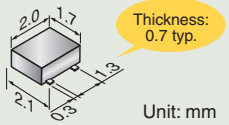
Thickness: 0.5 typ.
Unit: mm

SSM (SOT-416)(SC-75)
Small Super-Mini
Typical product: SSM3K35FS


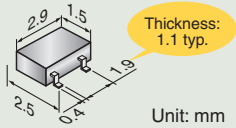
Thickness: 0.7 typ.
Unit: mm

USM (SOT-323)(SC-70)
Ultra-Super-Mini
Typical product: SSM3K15FU


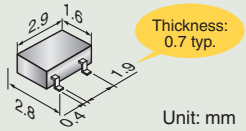
Thickness: 0.9 typ.
Unit: mm

UFM
Ultra-super-Mini Flat lead
Typical product: SSM3J130TU


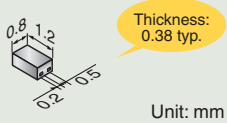
Thickness: 0.7 typ.
Unit: mm

S-Mini (SOT-346)(SC-59)
Super-Mini
Typical product: SSM3K15F


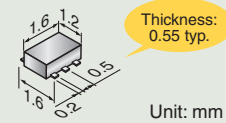
Thickness: 1.1 typ.
Unit: mm

TSM
Thin Super-Mini
Typical product: SSM3J304T


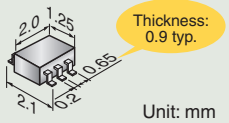
Thickness: 0.7 typ.
Unit: mm

CST4
Chip-Scale Package, Transfer Molded, 4-Pin
Typical product: SSM4K27CT


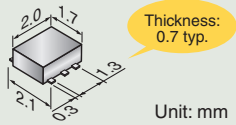
Thickness: 0.38 typ.
Unit: mm

ESV (SOT-553)
Extreme Super-mini, 5-pin
Typical product: SSM5N15FE


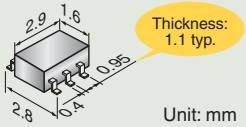
Thickness: 0.55 typ.
Unit: mm

USV (SOT-353)(SC-88A)
Ultra-Super-mini, 5-pin
Typical product: SSM5N15FU


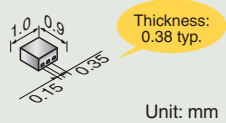
Thickness: 0.9 typ.
Unit: mm

UFV
Ultra-super-mini, Flat lead, 5-pin
Typical product: SSM5H12TU


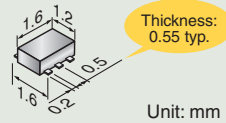
Thickness: 0.7 typ.
Unit: mm

SMV (SOT-25)(SC-74A)
Super-Mini, 5-pin
Typical product: SSM5H14F


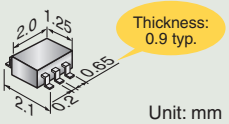
Thickness: 1.1 typ.
Unit: mm

CST6D
Chip-Scale Package, Transfer Molded, 6-Pin, D-Type
Typical product: SSM6N37CTD


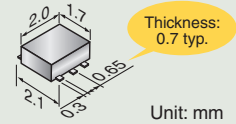
Thickness: 0.38 typ.
Unit: mm

ES6 (SOT-563)
Extreme Super-mini, 6-pin
Typical product: SSM6N36FE


Thickness: 0.55 typ.
Unit: mm

US6 (SOT-353)(SC-88A)
Ultra-Super-mini, 6-pin
Typical product: SSM6N15FU


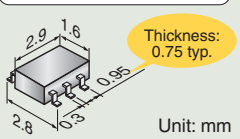
Thickness: 0.9 typ.
Unit: mm

UF6
Ultra Super mini Flat lead 6-pin
Typical product: SSM6J409TU


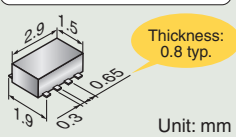
Thickness: 0.7 typ.
Unit: mm

TPC Series

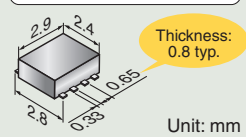
The TPC Series comes in small, thin packages suitable for portable devices. The latest TSON Advance package allows the maximum permissible power dissipation equivalent to SOP-8, but occupies 64% less board space.

VS-6
Very Thin & Small, 6-pin
Typical product: TPC6003


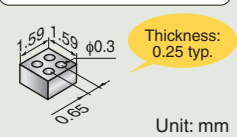
Thickness: 0.75 typ.
Unit: mm

VS-8
Very Thin & Small, 8-pin
Typical product: TPCF8101


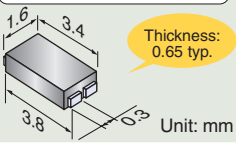
Thickness: 0.8 typ.
Unit: mm

PS-8
Progressive & Small 8-pin Series
Typical product: TPCP8402


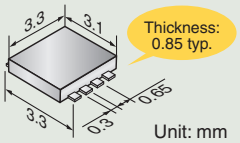
Thickness: 0.8 typ.
Unit: mm

Chip LGA
Land Grid Array
Typical product: TPCL4201


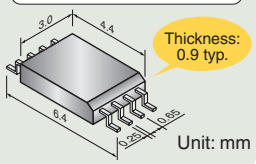
Thickness: 0.25 typ.
Unit: mm

STP2
Small Thin Package
Typical product: TPCT4204


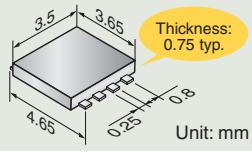
Thickness: 0.65 typ.
Unit: mm

TSON Advance
Typical product: TPCC8005-H


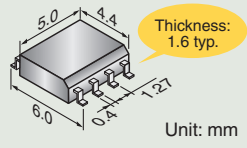
Thickness: 0.85 typ.
Unit: mm

TSSOP-8
Typical product: TPCS8208


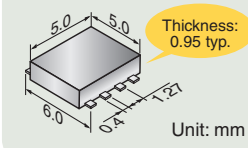
Thickness: 0.9 typ.
Unit: mm

TSSOP Advance
Typical product: TPCM8001-H


Thickness: 0.75 typ.
Unit: mm

SOP-8
Typical product: TPC8035-H


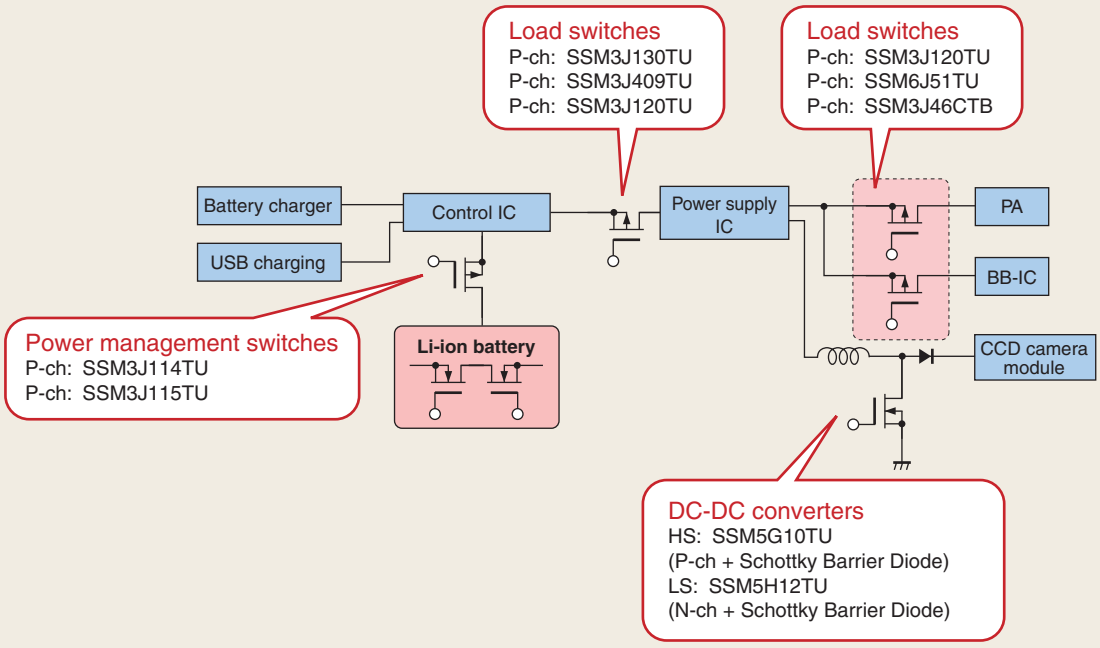
Thickness: 1.6 typ.
Unit: mm

SOP Advance
Typical product: TPCA8028-H


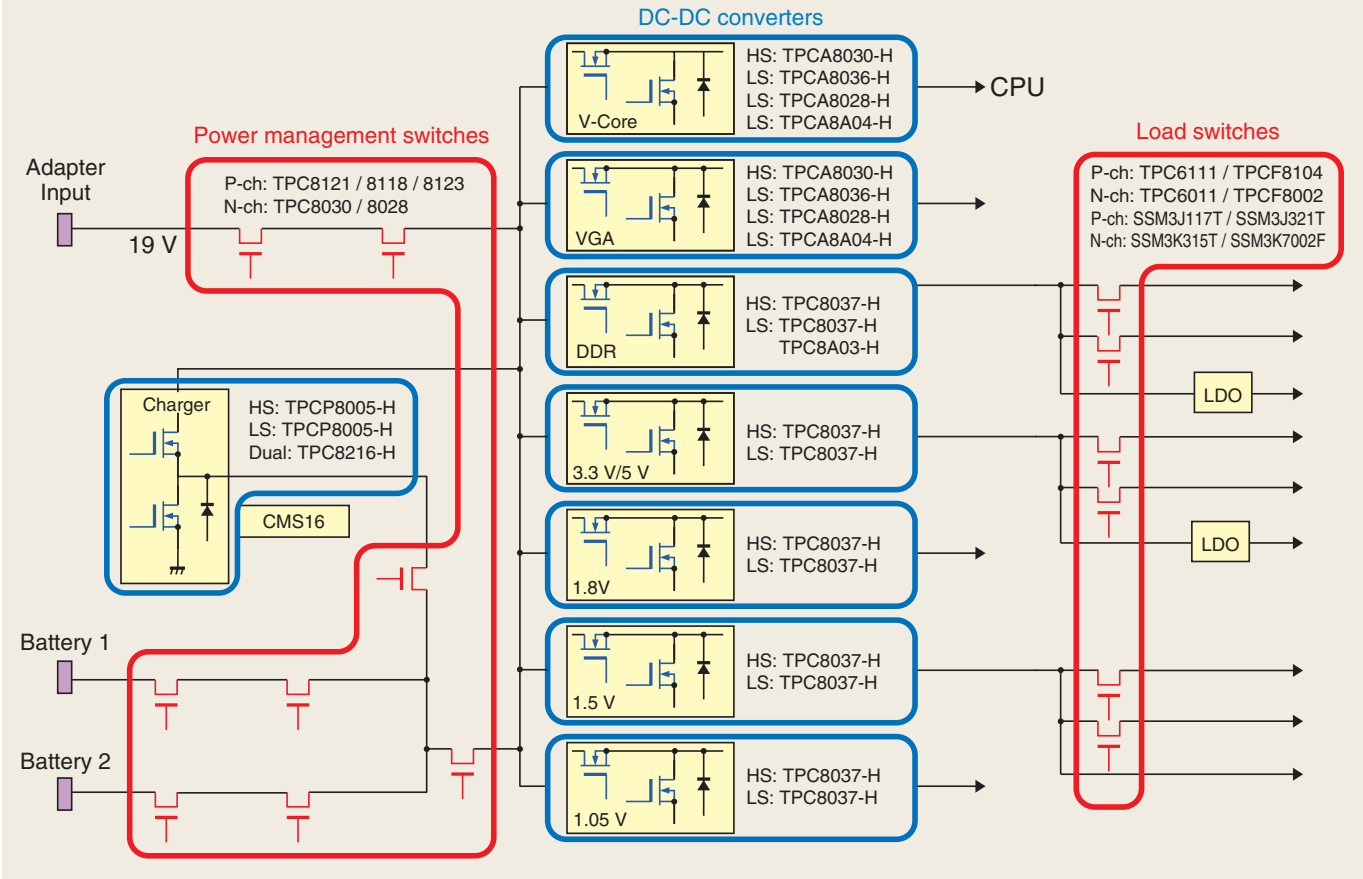
Thickness: 0.95 typ.
Unit: mm

4-2 Application Examples and Block Diagrams

Cell Phone (Power Supply Circuit)

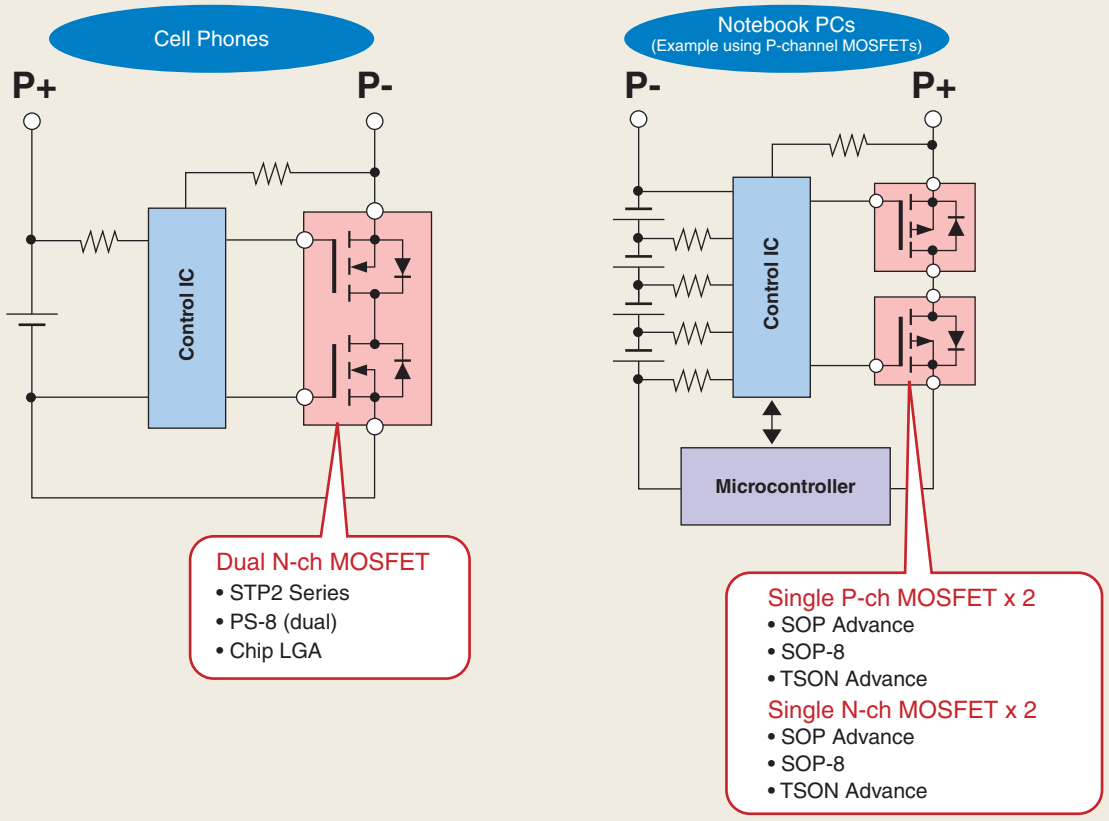


Notebook PC (Power Supply Circuit)

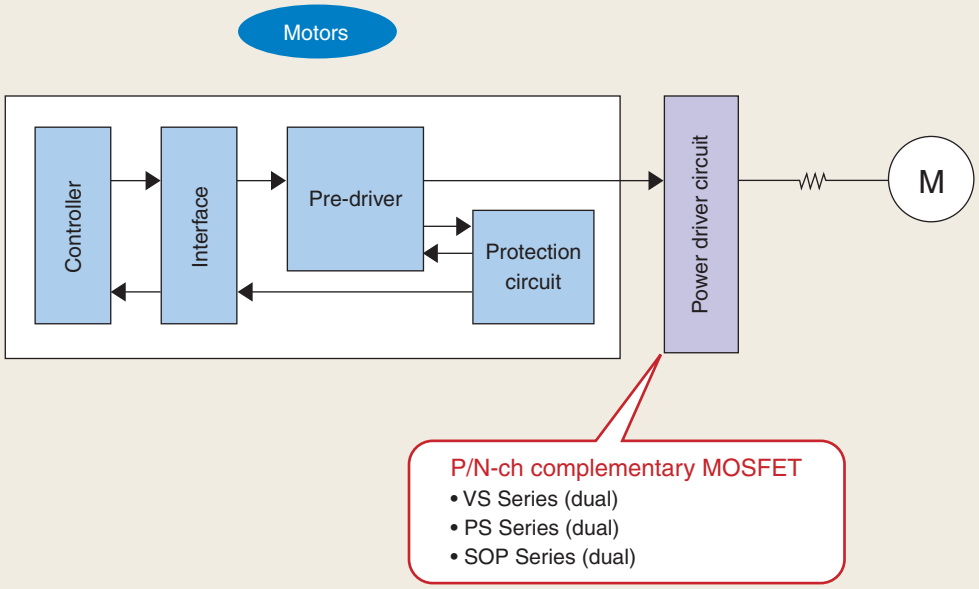


4-2 Application Examples and Block Diagrams

Lithium-Ion Secondary Battery (Battery Protection Circuits)



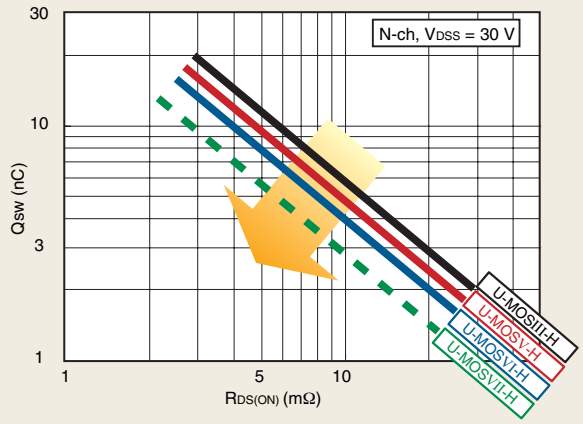
Motor Driver (Power Driver Circuit)



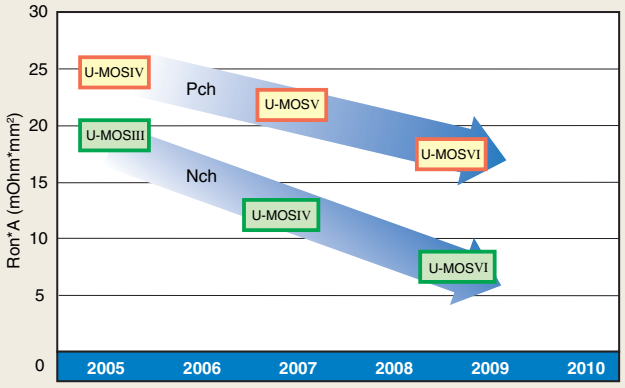
4-3 Low-V_{DSS} MOSFET Roadmaps

Roadmap for Trench MOSFETs

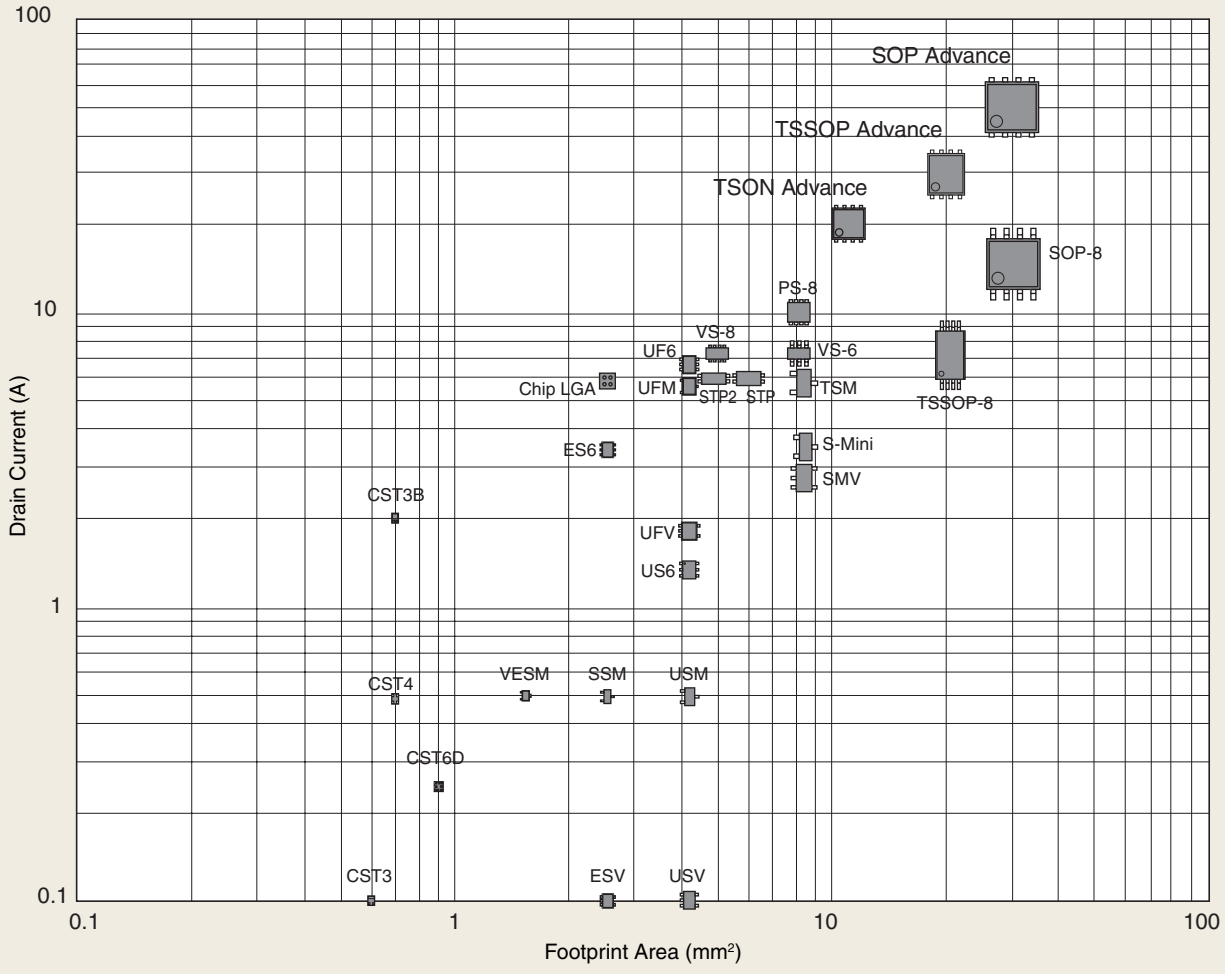
■ High-Speed, Low-V_{DSS} U-MOS



■ Low-Ron Trench MOSFETs

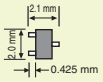
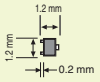
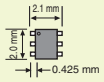
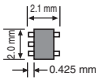
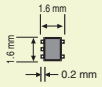


Package Options



4 Low-V_{DSS} MOSFETs (in Small SMD Packages)

■ Ultra-Small Packages

	S-Mini	USM	SSM	VESM	CST3	US6	USV	ESV	CST6D
									
Footprint Area	7.3 mm²	4.2 mm²	2.6 mm²	1.4 mm²	0.6 mm²	4.2 mm²	4.2 mm²	2.6 mm²	0.9 mm²
Permissible Power Dissipation (Note)	0.2 W	0.2 W	0.1 W	0.15 W	0.1 W	0.2 W	0.2 W	0.15 W	0.14 W
Height (MAX)	1.4 mm	1.1 mm	0.9 mm	0.55 mm	0.4 mm	1.1 mm	1.1 mm	0.6 mm	0.4 mm

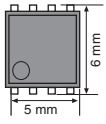
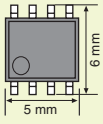
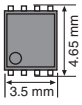
Note: Mounted on FR4 Boad (25.4 x 25.4 mm)

■ Thermally-Enhanced Compact Packages

	TSM	UF6	SMV	UFV	UFM	ES6	CST3B	CST4
Footprint Area	8.1 mm²	4.2 mm²	8.1 mm²	4.2 mm²	4.2 mm²	2.6 mm²	1.0 mm²	1.0 mm²
Permissible Power Dissipation (Note)	0.7 W	0.5 W	0.75 W	0.5 W	0.5 W	0.5 W	1.0 W	0.4 W
Height (MAX)	0.85 mm	0.75 mm	1.4 mm	0.75 mm	0.75 mm	0.6 mm	0.5 mm	0.4 mm

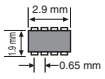
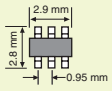
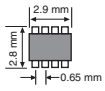
Note: Mounted on FR4 Boad (25.4 x 25.4 mm)

■ Thermally Enhanced Packages

	SOP Adv.	SOP-8	TSSOP Adv.	TSON Adv.
				
Footprint Area	30 mm²	30 mm²	16.3 mm² (–46%)	10.9 mm² (–64%)
Permissible Power Dissipation	2.8 W (+47%)	1.9 W	2.3 W (+21%)	1.9 W
Height	1.0 mm (–47%)	1.9 mm	0.8 mm (–58%)	0.9 mm (–53%)

(Percentage relative to SOP-8)

■ Compact Packages

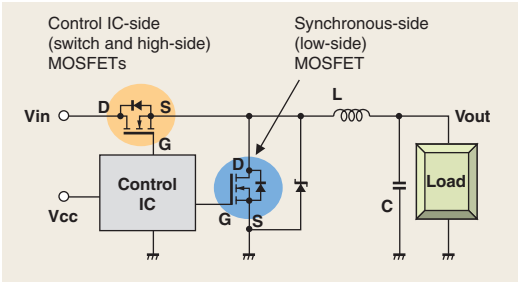
	VS-8	VS-6	PS-8	Chip LGA
				
Footprint Area	5.5 mm² (–32%)	8.1 mm²	8.1 mm²	2.56 mm² (–68%)
Permissible Power Dissipation	2.5 W (+14%)	2.2 W	1.68 W (–24%)	—
Height	0.85 mm	0.85 mm	0.85 mm	0.25 mm (–71%)

(Percentage relative to VS-6)

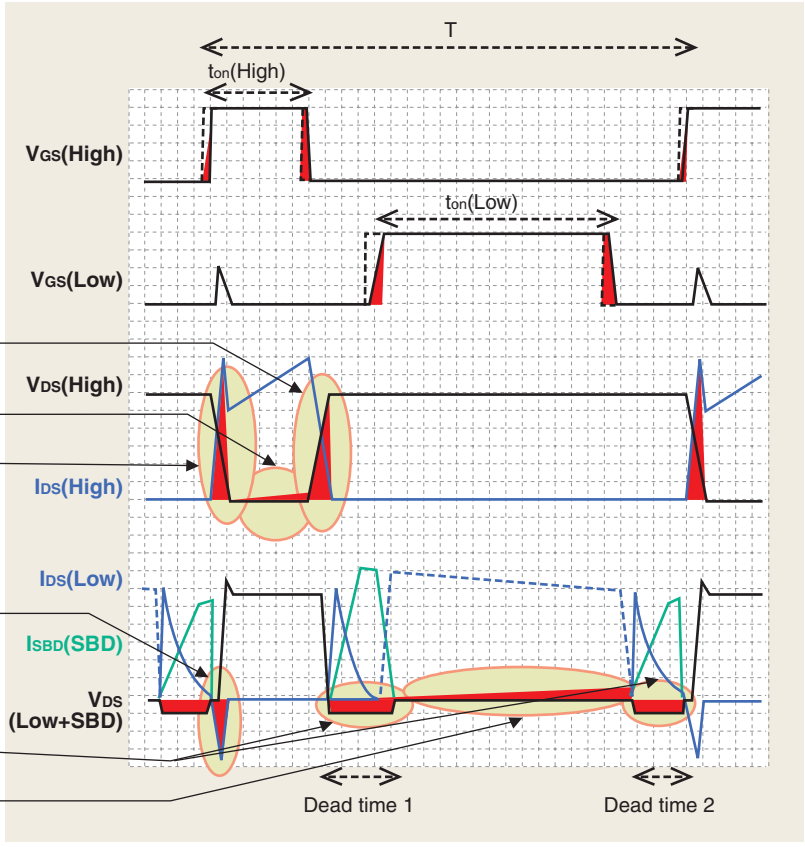
4-4 Low-V_{DSS}, High-Speed MOSFETs

Synchronous Rectification DC-DC Converters – Block Diagram, Timing Chart and Power Loss Factors

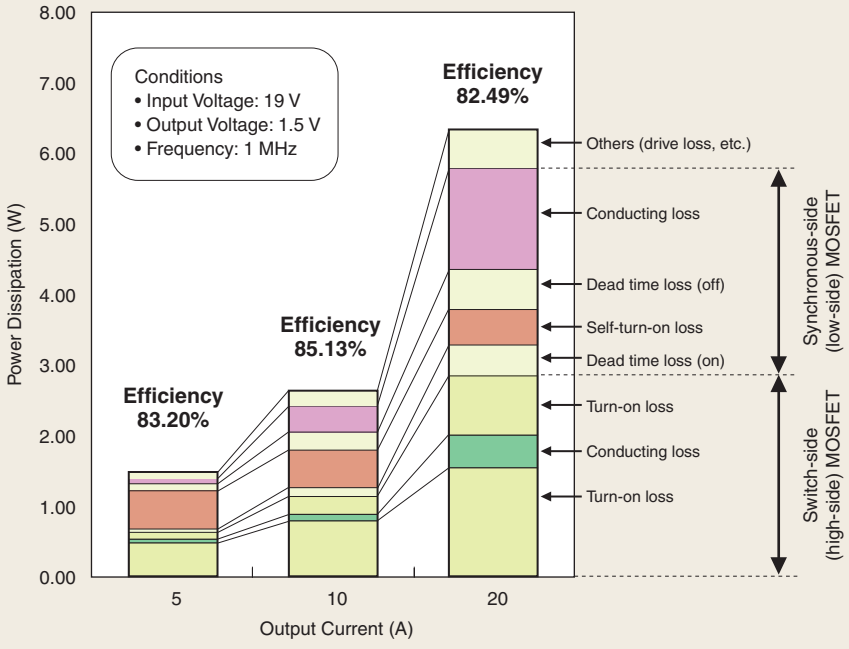
■ Block Diagram



■ Timing Chart



Synchronous Rectification DC-DC Converters – Summary Results of Power Loss Simulation and Key Parameters for MOSFETs



Key Parameters to Improve Efficiency

Synchronous-side MOSFET

- Very low $R_{DS\ (ON)}$
- Reduction of the self-turn-on losses
  - Low Q_{rr}
  - Low C_{gd}, C_{gd}/C_{gs}
  - Low r_g
  - Optimized V_{th}
- Shoot-through current control
  - Low Q_g

Switch-side MOSFET

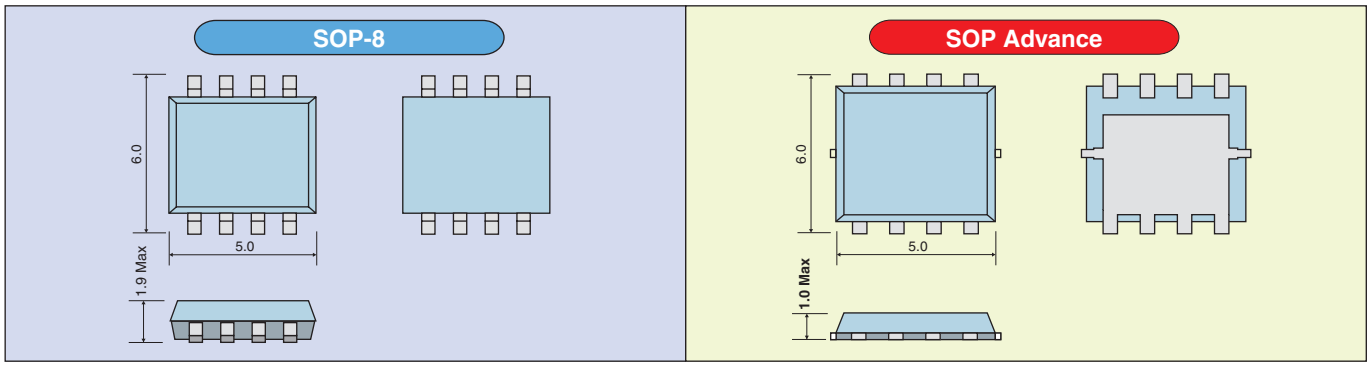
- High-speed switching
  - Low Q_{sw}
  - Low r_g
- Low $R_{DS\ (ON)}$

Synchronous Rectification DC-DC Converters – Efficiency Improvement by Thermally Enhanced Package and New Process Technology

■ Thermally Enhanced Package

Toshiba has developed the SOP Advance package with the same footprint area as the standard SOP-8 package. With an external heatsink on the bottom, the SOP Advance package offers enhanced thermal characteristics, realizing a high power dissipation and thus high-current capability.

Unit: mm



		SOP-8	SOP Advance	Features of the SOP Advance
Footprint Area	(mm^2)	30	**30**	Same footprint area as the SOP-8
Total height (max)	(mm)	1.9	**1.0**	Low profile, Thinner by 0.9 mm
Rth(ch-a) (t = 10 s) (Note 1)	(˚C / W)	65.8	**44.6**	High power dissipation
Current rating	(A)	18	**40**	High current-carrying capacity
Package resistance (Note 2)	(mΩ)	1.6	**0.5**	Low package resistance

Note 1: When mounted on a glass-epoxy board (25.4 mm x 25.4 mm x 0.8 mm) Note 2: Without chip resistance

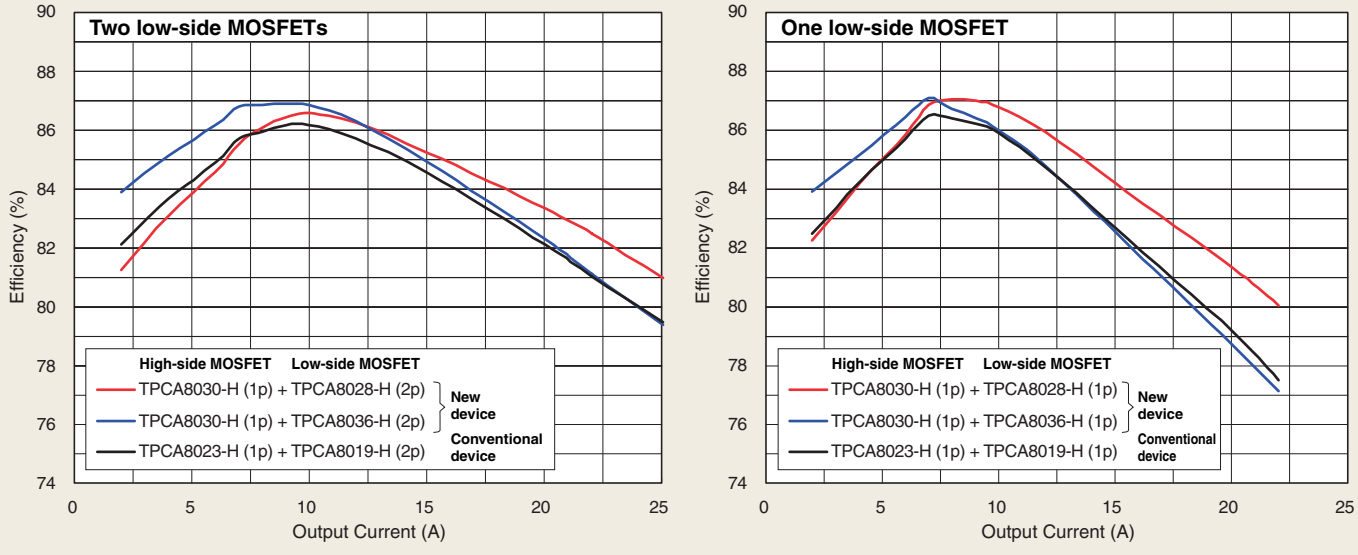
■ New Process Technology

Toshiba has developed a new process technology to further reduce an internal gate resistance (rg) and gate capacitance ratio (Cgd/Cgs) for minimizing the self-turn-on loss while maintaining both the low ON-resistance and low gate charge characteristics.

	$R_{DS(ON)}$ Typ. @4.5 V (mΩ)	rg Typ. (Ω)	Cgd/Cgs Typ. (%)
TPCA8028-H (New generation)	2.3	1.0	6.8
TPCA8019-H (One gen. ago)	3.1	1.0	6.6
TPCA8004-H (Two gen. ago)	4.8	2.4	12.7

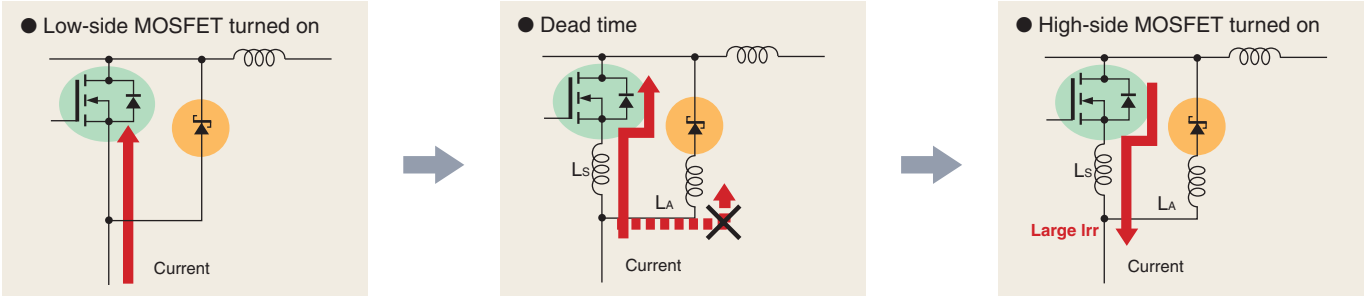
Efficiency Characteristics

f = 300 kHz, V_{IN} = 19.5 V, V_{OUT} = 1.1 V



Synchronous Rectification DC-DC Converters – MOSBD (MOSFET with SBD)

■ External SBD



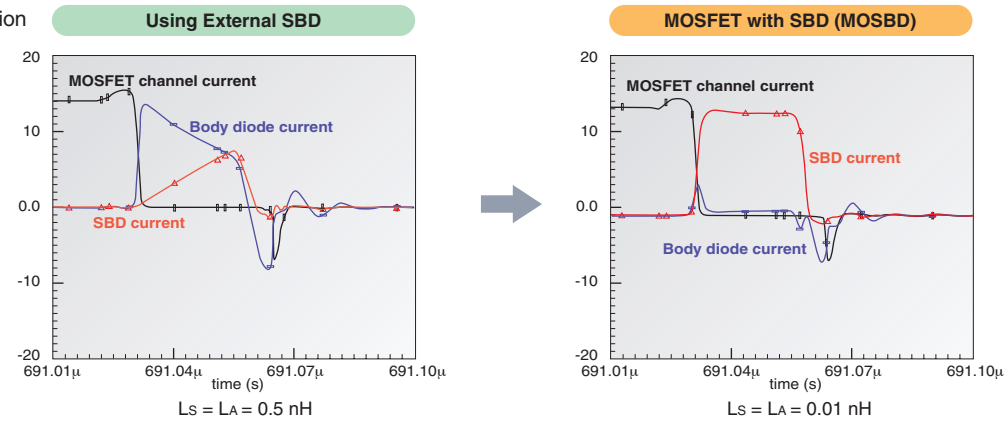
When an SBD is added externally, the SBD can't function fully due to the influence of wire inductances (Ls and LA); thus a body diode current during the dead time becomes larger and causes the following penalties.

1: Increase in the conducting loss of the body diode.
2: Increase in the reverse recovery loss due to high di/dt.
3: Induces a self-turn-on phenomenon.

■ MOSFET with SBD (MOSBD)

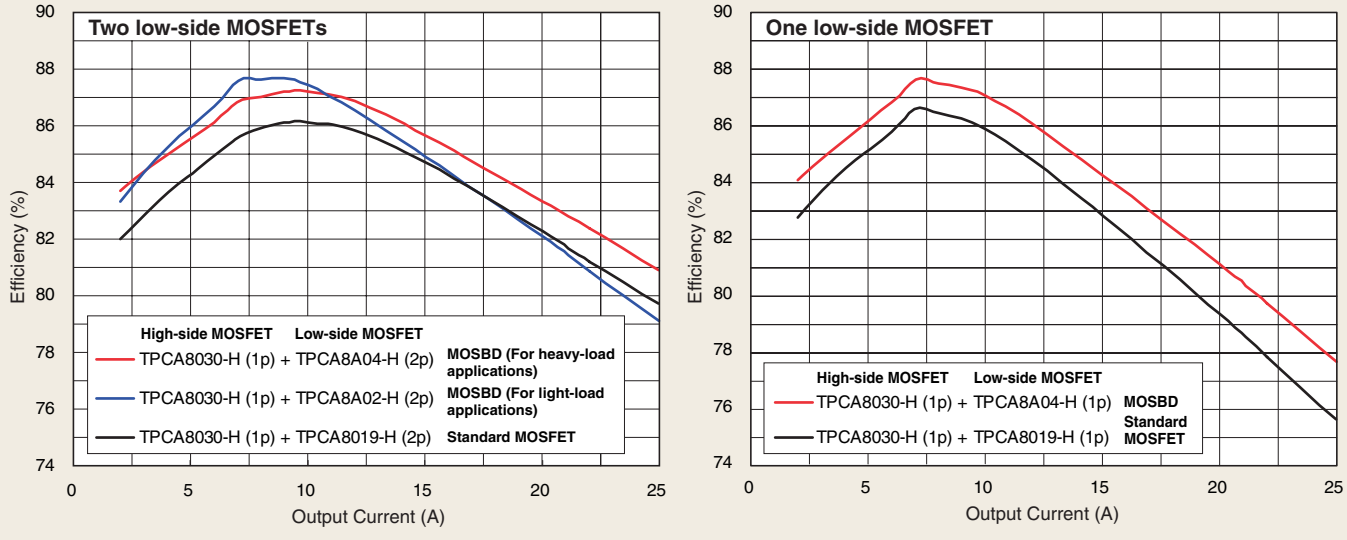
A MOSFET with SBD using a monolithic structure reduces a wire inductance (LA) and a parasitic inductance (Ls). This structure makes it possible for the SBD to function fully and to reduce losses.

● Current Waveform Simulation



Efficiency Characteristics

f = 300 kHz, V_{IN} = 19.5 V, V_{OUT} = 1.1 V



High-Speed MOSFET Offerings

Part Number	Absolute Maximum Ratings			Circuit Configuration	Package	$R_{DS(ON)}$ Max (mΩ)			Qsw Typ.(nC) @V_{DS} = V_{DSS} x 0.8	Series
	V_{DSS} (V)	V_{GSS} (V)	I_D (A)			2.5 V	4.5 V	10 V		
TPCA8011-H	20	±12	40	N-ch Single	SOP Advance	7.5	3.5	—	16	U-MOSⅢ-H
TPC6007-H	30		5		VS-6	—	79	54	1.8	U-MOSⅢ-H
TPC6109-H	–30		–5	P-ch Single		—	83	59	4.8	U-MOSⅢ-H
TPC8216-H ☆			6.4	N-ch Dual	SOP-8	—	23.0	20	3.4	U-MOSVI-H
TPCP8005-H ☆			11		PS-8	—	15.7	12.9	5.0	U-MOSV-H
TPCC8003-H ☆			13		TSON Advance	—	19.3	16.9	4.2	U-MOSVI-H
TPCC8001-H ☆			22			—	10.6	8.3	7.1	U-MOSV-H
TPCC8002-H ☆			22			—	10.6	8.3	7.1	U-MOSV-H
TPCC8006-H ☆			22			—	9.3	8.0	7.4	U-MOSVI-H
TPCC8005-H ☆			26			—	7.4	6.4	9.1	U-MOSVI-H
TPCM8003-H ☆			21		TSSOP Advance	—	15.7	12.9	5.0	U-MOSV-H
TPCM8004-H ☆			24			—	13.4	11	5	U-MOSV-H
TPCM8002-H ☆			30			—	8.2	6.2	9.3	U-MOSV-H
TPC8021-H			11		SOP-8	—	25	17	3.6	U-MOSⅢ-H
TPC8031-H ☆			11			—	16.1	13.3	5.0	U-MOSV-H
TPC8037-H ☆			12			—	13.9	11.4	5	U-MOSV-H
TPC8038-H ☆			12			—	13.9	11.4	5	U-MOSV-H
TPC8040-H ☆			13			—	11.1	9.7	5.1	U-MOSVI-H
TPC8032-H ☆	30		15			—	8.6	6.5	8.4	U-MOSV-H
TPC8033-H ☆			17			—	7.2	5.3	9.6	U-MOSV-H
TPC8039-H ☆			17			—	6.9	6.0	8.5	U-MOSVI-H
TPC8034-H ☆			18			—	4.5	3.5	16	U-MOSV-H
TPC8036-H ☆			18			—	5.1	4.5	13	U-MOSVI-H
TPC8035-H ☆			18			—	3.6	3.2	17	U-MOSVI-H
TPCA8023-H ☆		±20	21		SOP Advance	—	15.7	12.9	5.0	U-MOSV-H
TPCA8040-H ☆			23			—	10.8	9.4	5.7	U-MOSVI-H
TPCA8030-H ☆			24	N-ch Single		—	13.4	11.0	5	U-MOSV-H
TPCA8031-H ☆			24			—	13.4	11.0	5	U-MOSV-H
TPCA8018-H ☆			30			—	8.2	6.2	9.3	U-MOSV-H
TPCA8039-H ☆			34			—	6.6	5.7	8.6	U-MOSVI-H
TPCA8036-H ☆			38			—	4.8	4.2	13	U-MOSVI-H
TPCA8012-H ☆			40			—	6.8	4.9	11.0	U-MOSV-H
TPCA8060-H ☆			45			—	3.9	3.4	17	U-MOSVI-H
TPCA8019-H ☆			45			—	4.1	3.1	15.5	U-MOSV-H
TPCA8028-H ☆			50			—	3.2	2.8	20	U-MOSVI-H
TPC6006-H	40		3.9		VS-6	—	100	75	1.3	U-MOSⅢ-H
TPC8022-H			7.5		SOP-8	—	35	27	3.5	U-MOSⅢ-H
TPC8052-H ☆			12			—	13.3	11.5	6.6	U-MOSVI-H
TPC8047-H ☆			16			—	8.8	7.6	11	U-MOSVI-H
TPC8046-H ☆			18			—	6.6	5.7	15	U-MOSVI-H
TPC8045-H ☆			18			—	4.4	3.9	23	U-MOSVI-H
TPCA8020-H			7.5		SOP Advance	—	35	27	3.5	U-MOSⅢ-H
TPCA8052-H ☆			20			—	13.1	11.3	6.6	U-MOSVI-H
TPCA8014-H			30			—	14	9	7.4	U-MOSⅢ-H
TPCA8027-H			30			—	—	10	8.1	U-MOSⅢ-H
TPCA8047-H ☆			32			—	8.5	7.3	13	U-MOSVI-H
TPCA8015-H			35			—	7.9	5.4	13	U-MOSⅢ-H
TPCA8046-H ☆			38			—	6.3	5.4	15	U-MOSVI-H
TPCA8045-H ☆			46			—	4.1	3.6	23	U-MOSVI-H

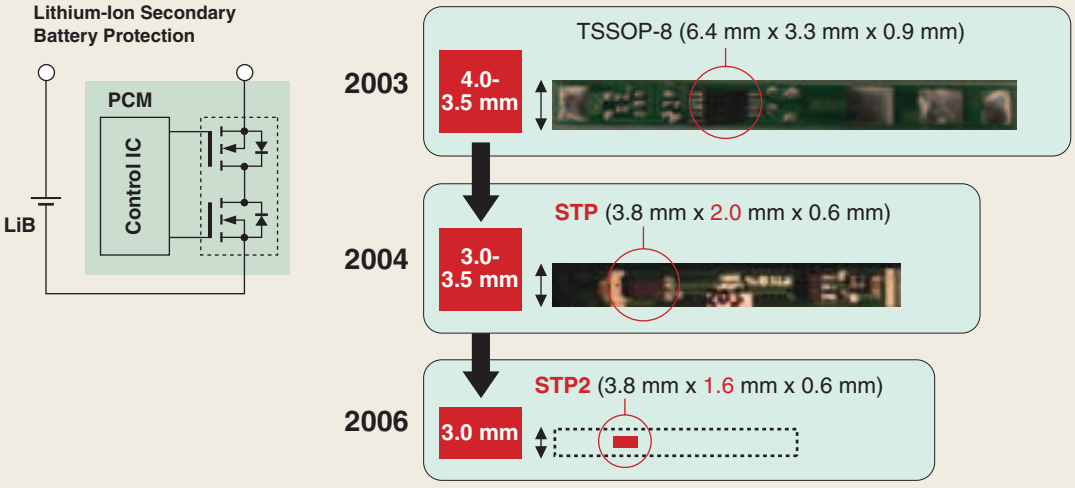
☆: No protection Zener diode between gate and source

Part Number	Absolute Maximum Ratings			Circuit Configuration	Package	$R_{DS(ON)}$ Max (mΩ)		Qsw Typ.(nC) @V_{DS} = V_{DSS} x 0.8	Series
	V_{DSS} (V)	V_{GSS} (V)	I_D (A)			4.5 V	10 V		
TPC8218-H ☆	60	±20	3.8	N-ch Dual	SOP-8	64	57	2.6	U-MOSⅥ-H
TPC8213-H			5			56	50	2.9	U-MOSⅢ-H
TPC8053-H ☆			9	N-ch Single		24.2	22.5	6.7	U-MOSⅥ-H
TPC8050-H ☆			11			15.6	14.5	9.2	U-MOSⅥ-H
TPC8049-H ☆			13			11.5	10.7	13	U-MOSⅥ-H
TPC8048-H ☆			16			7.4	6.9	17	U-MOSⅥ-H
TPCA8053-H ☆			15		SOP Advance	24	22.3	6.9	U-MOSⅥ-H
TPCA8050-H ☆			24			15.3	14.2	10	U-MOSⅥ-H
TPCA8016-H			25			26	21	6.6	U-MOSⅢ-H
TPCA8049-H ☆			28			11.2	10.4	13	U-MOSⅥ-H
TPCA8048-H ☆			35			7.1	6.6	19	U-MOSⅥ-H
TPC8051-H ☆	80		13		SOP-8	10.1	9.7	16	U-MOSⅥ-H
TPCA8051-H ☆			28		SOP Advance	9.8	9.4	18	U-MOSⅥ-H
TPCP8003-H	100		2.2		PS-8	190	180	2.0	U-MOSⅢ-H
TPC8214-H			2.2	N-ch Dual	SOP-8	190	180	2.0	U-MOSⅢ-H
TPCA8022-H			22	N-ch Single	SOP Advance	—	26	14	U-MOSⅢ-H
TPCA8009-H	150		7		SOP Advance	—	350	3.7	π-MOSⅤ
TPCA8010-H	200		5.5		SOP Advance	—	450	3.7	π-MOSⅤ
TPCA8008-H	250		4		SOP Advance	—	580	3.7	π-MOSⅤ
TPCP8A05-H ☆	30		8	MOSBD	PS-8	21.9	17.5	2.7	U-MOSⅤ-H
TPCC8A01-H ☆			21		TSON Advance	12.6	9.9	4.1	U-MOSⅤ-H
TPCM8A05-H ☆			20		TSSOP Advance	17.2	12.9	3.7	U-MOSⅤ-H
TPC8A05-H ☆			10		SOP-8	17.6	13.3	3.7	U-MOSⅤ-H
TPC8A06-H ☆			12			12.9	10.1	4.5	U-MOSⅤ-H
TPC8A03-H ☆			17			7.0	5.6	8.4	U-MOSⅤ-H
TPC8A04-H ☆			18			4.5	3.6	13.4	U-MOSⅤ-H
TPCA8A05-H ☆			20		SOP Advance	17.2	12.9	3.7	U-MOSⅤ-H
TPCA8A02-H ☆			34			6.7	5.3	8.6	U-MOSⅤ-H
TPCA8A08-H ☆			38			5.1	3.9	11	U-MOSⅤ-H
TPCA8A04-H ☆			44			4.1	3.2	13.4	U-MOSⅤ-H
TPCP8103-H	–40		–4.8	P-ch Single	PS-8	54	40	6.5	U-MOSⅢ-H
TPC8116-H			–7.5		SOP-8	37	30	9.7	U-MOSⅢ-H
TPCA8107-H			–7.5		SOP Advance	37	30	9.7	U-MOSⅢ-H
TPC8406-H	40		6.5	N-ch/P-ch Dual	SOP-8	35	27	3.5	U-MOSⅢ-H
	–40		–6.5			37	30	9.7	U-MOSⅢ-H

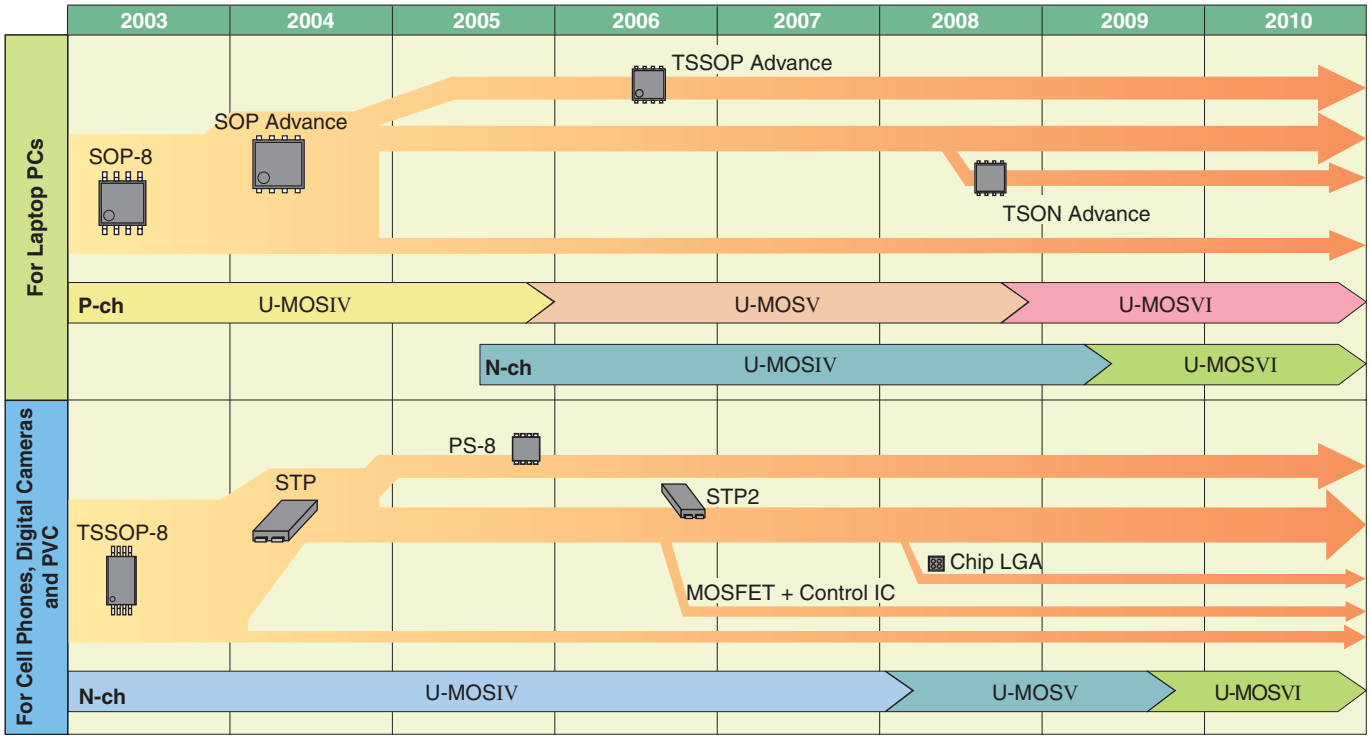
☆: No protection Zener diode between gate and source

4-5 Low-VDSS, Low-RDS(ON) MOSFETs (for Lithium-Ion Battery Protection)

Lithium-Ion Battery Protection Circuit Trend



MOSFET Roadmap



Low-ON-resistance N-Channel Power MOSFETs

Part Number	Absolute Maximum Ratings			Circuit Configuration	Package	$R_{DS(ON)}$ Max (mΩ)				Series
	V_{DSS} (V)	V_{GSS} (V)	I_D (A)			2.5 V	4 V	4.5 V	10 V	
TPCT4203 ☆	20	±12	6	STP2	N-ch Dual	49	32	—	—	U-MOSⅣ
TPCT4204 ☆	30	±12	6			52	39	—	—	U-MOSⅣ
TPCL4201 ☆	20	±12	6	Chip LGA		52	—	31	—	U-MOSV
TPCL4203 ☆✻	24	±12	6			55	—	36	—	U-MOSV
TPCL4202 ☆✻	30	±12	6			64	—	40	—	U-MOSV
TPCP8006 ☆	20	±12	9.1	PS-8	N-ch Single	13.7	—	10	—	U-MOSⅣ
TPCP8004 ☆	30	±20	8.3			—	—	14	8.5	U-MOSⅣ
TPCP8202	30	±12	5.5		N-ch Dual	39	24	23	—	U-MOSⅣ
TPCC8007 ☆✻	20	±12	27	TSON Advance	N-ch Single	(8.7)	—	(4.6)	—	U-MOSⅣ
TPCC8008☆	30	±25	25			—	—	12.8	6.8	U-MOSⅣ
TPC8025 ☆	30	±20	11	SOP-8		—	—	14.5	9	U-MOSⅣ
TPC8030 ☆	30	±25	11			—	—	17	9	U-MOSⅣ
TPC8041 ☆	30	±20	13			—	—	13.5	7	U-MOSⅣ
TPC8026 ☆	30	±20	13			—	—	10	6.6	U-MOSⅣ
TPC8028 ☆	30	±20	18			—	—	8	4.3	U-MOSⅣ
TPC8029 ☆	30	±20	18			—	—	7	3.8	U-MOSⅣ
TPC8042 ☆	30	±20	18			—	—	6.5	3.4	U-MOSⅣ
TPC8027 ☆	30	±20	18			—	—	5.5	2.7	U-MOSⅣ
TPC8208	20	±12	5		N-ch Dual	70	50	—	—	U-MOSⅢ
TPC8207	20	±12	6			30	20	—	—	U-MOSⅢ
TPC8211	30	±20	5.5			—	—	44	36	U-MOSⅢ
TPC8210	30	±20	8			—	—	20	15	U-MOSⅢ
TPCA8024 ☆	30	±20	35	SOP Advance	N-ch Single	—	—	7.8	4.3	U-MOSⅣ
TPCA8025 ☆	30	±20	40			—	—	6.0	3.5	U-MOSⅣ
TPCA8042 ☆	30	±20	45			—	—	5.7	3.3	U-MOSⅣ
TPCA8026 ☆	30	±20	45			—	—	4.5	2.2	U-MOSⅣ

☆: No protection Zener diode between gate and source ✻: Under development

Low-ON-resistance P-Channel Power MOSFETs

Part Number	Absolute Maximum Ratings			Circuit Configuration	Package	$R_{DS(ON)}$ Max (mΩ)				Series
	V_{DSS} (V)	V_{GSS} (V)	I_D (A)			2.5 V	4 V	4.5 V	10 V	
TPCC8102 ☆	−30	±20	−15	TSON Advance	P-ch Single	—	33.2	—	18.9	U-MOSV
TPCC8103 ☆	−30	±20	−18			—	22	—	12	U-MOSV
TPC8115	−20	±8	−10	SOP-8		14	—	10	—	U-MOSⅣ
TPC8119 ☆	−30	±20	−10			—	28	—	13	U-MOSV
TPC8121 ☆	−30	±20	−11			—	24	—	12	U-MOSV
TPC8111	−30	±20	−11			—	18	—	12	U-MOSⅣ
TPC8113	−30	±20	−11			—	18	—	10	U-MOSⅣ
TPC8123 ☆	−30	−25/+20	−11			—	—	12.5	9	U-MOSⅥ
TPC8122 ☆	−30	±20	−12			—	16.5	—	8	U-MOSV
TPC8118 ☆	−30	±20	−13			—	15	—	7	U-MOSV
TPC8114	−30	±20	−18			—	6.8	—	4.5	U-MOSⅣ
TPC8117 ☆	−30	±20	−18			—	7.9	—	3.9	U-MOSV
TPC8120 ☆	−30	−25/+20	−18			—	—	4.2	3.2	U-MOSⅥ
TPC8405	30	±20	6		N-ch/P-ch Dual	—	—	33	26	U-MOSⅢ
	−30	±20	−4.5			—	—	42	33	U-MOSⅣ
TPCM8102 ☆	−30	±20	−25	TSSOP Advance	P-ch Single	—	16	—	7.7	U-MOSV
TPCA8105	−12	±8	−6	SOP Advance		51	33	—	—	U-MOSⅣ
TPCA8103	−30	±20	−40			—	6.8	—	4.2	U-MOSⅣ
TPCA8106 ☆	−30	±20	−40			—	7.8	—	3.7	U-MOSV

☆: No protection Zener diode between gate and source

4-6 Semi-Power MOSFET Offerings

Semi-Power P-Channel Single MOSFETs

Unit: mm

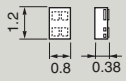
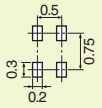
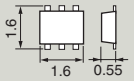
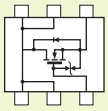
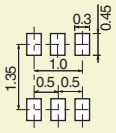
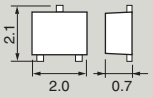
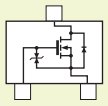
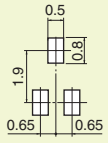
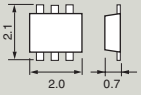
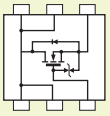
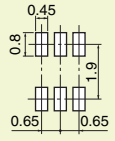
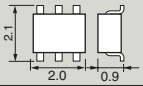
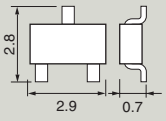
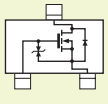
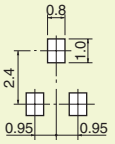
Package	Part Number	VDSS (V)	VGSS (V)	ID (A)	RDS(ON) Max (mΩ) VGS = −1.5 V	VGS = −1.8 V	VGS = −2.5 V	VGS = −4.0 V	Ciss (pF)	Series	*Internal Connections	Land Pattern Example
CST3B	SSM3J46CTB	−20	±8	−2.0	250	178	133	103 (@4.5 V)	290	U-MOSVI	TOP VIEW	
ES6 (SOT-563)	SSM6J212FE*	−20	±8	−3.3	108	73.7	45.6	43.4(@4.5V)	834	U-MOSVI		
	SSM6J53FE	−20	±8	−1.8	364	204	136	—	568	U-MOSIV		
	SSM6J206FE	−20	±8	−2.0	—	320	186	130	335	U-MOSIII		
	SSM6J205FE	−20	±8	−0.8	—	460	306	234	250	U-MOSIII		
	SSM6J26FE	−20	±8	−0.5	—	980	330	230	250	U-MOSIII		
	SSM6J23FE	−12	±8	−1.2	—	—	210	160	420	U-MOSIII		
	SSM6J25FE	−20	±12	−0.5	—	—	430	260	218	U-MOSIII		
	SSM6J207FE	−30	±20	−1.4	—	—	—	491	137	U-MOSII		
UFM	SSM3J132TU*	−12	±5	−5.0	40.4	28.3	21.7	17.8(@4.5V)	2700	U-MOSVI		
	SSM3J130TU	−20	±8	−4.4	63.2	41.1	31	25.8(@4.5V)	1800	U-MOSVI		
	SSM3J120TU	−20	±8	−4.0	140	78	49	38	1484	U-MOSIV		
	SSM3J129TU	−20	±8	−4.6	137	88	62	46(@4.5V)	640	U-MOSV		
	SSM3J115TU	−20	±8	−2.2	353	193	125	98	568	U-MOSIV		
	SSM3J110TU	−12	±8	−2.3	—	240	145	94	550	U-MOSIII		
	SSM3J109TU	−20	±8	−2.0	—	300	172	130	335	U-MOSIII		
	SSM3J114TU	−20	±8	−1.8	526	321	199	149	331	U-MOSIV		
	SSM3J108TU	−20	±8	−1.8	—	363	230	158	250	U-MOSIII		
	SSM3J113TU	−20	±12	−1.7	—	—	249	169	370	U-MOSIII		
	SSM3J111TU	−20	±12	−1.0	—	—	680	480	160	U-MOSIII		
	SSM3J117TU	−30	±20	−2.0	—	—	—	225	280	U-MOSII		
	SSM3J118TU	−30	±20	−1.4	—	—	—	480	137	U-MOSII		
	SSM3J112TU	−30	±20	−1.1	—	—	—	790	86	U-MOSII		
UF6	SSM6J409TU	−20	±8	−9.5	72.3	46.3	30.2	22.1(@4.5V)	1100	U-MOSV		
	SSM6J51TU	−12	±8	−4.0	150	85	54	—	1700	U-MOSIV		
	SSM6J50TU	−20	±10	−2.5	—	205 (@2.0V)	100	64 (@4.5V)	800	U-MOSIV		
	SSM6J21TU	−12	±12	−3.0	—	—	88	50	1300	U-MOSIII		
	SSM6J401TU	−30	±20	−2.5	—	—	—	145	730	U-MOSIII		
	SSM6J402TU	−30	±20	−2.0	—	—	—	225	280	U-MOSIII		
US6(SOT-363)	SSM6J08FU	−20	±12	−1.3	—	460 (@2.0V)	260	180	370	U-MOSII		
	SSM6J06FU	−20	±12	−0.65	—	—	700	500	160	π-MOSVI		
	SSM6J07FU	−30	±20	−0.8	—	—	—	800	130	π-MOSVI		
TSM	SSM3J307T	−20	±8	−5.0	83	56	40	31(@4.5V)	1170	U-MOSV		
	SSM3J321T	−20	±8	−5.2	137	88	62	46(@4.5V)	640	U-MOSV		
	SSM3J326T*	−30	±12	−5.6	—	115	62.5	45.7(@4.5V)	640	U-MOSVI		
	SSM3J13T	−12	±8	−3.0	—	180 (@2.0V)	95	70	890	U-MOSIII		
	SSM3J312T	−12	±8	−2.7	—	237	142	91	550	U-MOSIII		
	SSM3J304T	−20	±8	−2.3	—	297	169	127	335	U-MOSIII		
	SSM3J317T	−20	±8	−3.6	—	306	144	107(@4.5V)	390	U-MOSIII		
	SSM3J313T	−20	±8	−1.6	—	640	396	268	170	U-MOSIII		
	SSM3J01T	−30	±10	−1.7	—	—	600	400	240	π-MOSVI		
	SSM3J02T	−30	±10	−1.5	—	—	700	500	150	π-MOSVI		
	SSM3J314T	−30	±20	−3.5	—	—	—	100	505	U-MOSIII-H		
	SSM3J14T	−30	±20	−2.7	—	—	—	170	413	U-MOSII		
	SSM3J306T	−30	±20	−2.4	—	—	—	225	280	U-MOSII		
	SSM3J305T	−30	±20	−1.7	—	—	—	477	137	U-MOSII		
S-Mini	SSM3J327F*	−20	±8	−3.5	242	170	125	95(@4.5V)	290	U-MOSVI		
	SSM3J325F*	−20	±8	−2.0	362	252	191	155(@4.5V)	226	U-MOSVI		

*: Under development

* The internal connection diagrams only show the general configurations of the circuits.

Semi-Power N-Channel Single MOSFETs

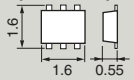
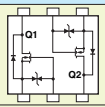
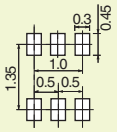
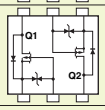
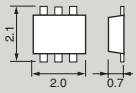
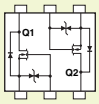
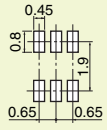
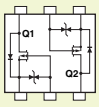
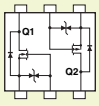
Unit: mm

Package	Part Number	V_{DSS} (V)	V_{GSS} (V)	I_D (A)	$R_{DS(ON)}$ Max (mΩ)				Ciss (pF)	Series	*Internal Connections	Land Pattern Example
					V_{GS} = 1.5 V	V_{GS} = 1.8 V	V_{GS} = 2.5 V	V_{GS} = 4.0 V				
CST4 	**SSM4K27CT**	20	±12	0.5	—	390	260	205	174	U-MOSIII	TOP VIEW	
ES6 (SOT-563) 	**SSM6K211FE**	20	±10	3.2	118	82	59	47(@4.5 V)	510	U-MOSIII		
	SSM6K203FE	20	±10	2.8	153	106	76	61	400	U-MOSIII		
	SSM6K202FE	30	±12	2.3	—	145	101	85	270	U-MOSIII		
	SSM6K204FE	20	±10	2.0	307	214	164	126	195	U-MOSIII		
	SSM6K208FE	30	±12	1.9	—	296	177	133	123	U-MOSIII		
	SSM6K25FE	20	±12	0.5	—	395	190	145	268	U-MOSIII		
	SSM6K24FE	30	±12	0.5	—	—	180	145	245	U-MOSIII		
	SSM6K22FE	20	±12	1.4	—	—	230	170	125	U-MOSIII		
	SSM6K210FE	30	±20	1.4	—	—	—	371	57	U-MOSIII		
	SSM6K30FE	20	±20	1.2	—	—	—	420	60	π-MOSVII		
	SSM6K31FE	20	±20	1.2	—	—	—	540	36	π-MOSVII		
UFM 	**SSM3K123TU**	20	±10	4.2	66	43	32	28	1010	U-MOSIII		
	SSM3K121TU	20	±10	3.2	140	93	63	48	400	U-MOSIII		
	SSM3K104TU	20	±12	3.0	—	110	74	56	320	U-MOSIII		
	SSM3K119TU	30	±12	2.5	—	134	90	74	270	U-MOSIII		
	SSM3K102TU	20	±12	2.6	—	154	99	71	268	U-MOSIII		
	SSM3K122TU	20	±10	2.0	304	211	161	123	195	U-MOSIII		
	SSM3K101TU	20	±12	2.2	—	230	138	103	125	U-MOSIII		
	SSM3K127TU	30	±12	2.0	—	286	167	123	123	U-MOSIII		
	SSM3K116TU	30	±12	2.2	—	—	135	100	245	U-MOSIII		
	SSM3K131TU	30	±20	6.0	—	—	—	41.5(@4.5 V)	450	U-MOSIV		
	SSM3K124TU	30	±20	2.4	—	—	—	120	180	π-MOSVII		
	SSM3K105TU	30	±20	2.1	—	—	—	200	102	π-MOSVI		
	SSM3K128TU	30	±20	1.5	—	—	—	360	57	U-MOSIII		
	SSM3K107TU	20	±20	1.5	—	—	—	410	60	π-MOSVII		
	SSM3K106TU	20	±20	1.2	—	—	—	530	36	π-MOSVII		
UF6 	**SSM6K403TU**	20	±10	4.2	66	43	32	28	1050	U-MOSIII		
	SSM6K404TU	20	±10	3.0	147	100	70	55	400	U-MOSIII		
	SSM6K405TU	20	±10	2.0	307	214	164	126	195	U-MOSIII		
	SSM6K18TU	20	±12	4.0	—	—	54	40	1100	U-MOSIII		
	SSM6K406TU	30	±20	4.4	—	—	—	38.5 (@4.5 V)	490	U-MOSIV		
	SSM6K34TU	30	±20	3.0	—	—	—	77 (@4.5 V)	470	U-MOSIII		
	SSM6K407TU	60	±20	2.0	—	—	—	440	150	π-MOSV		
	SSM6K32TU	60	±20	2.0	—	—	—	440	140	π-MOSV		
US6(SOT-363) 	**SSM6K08FU**	20	±12	1.6	—	210 (@2.0 V)	140	105	306	U-MOSII		
	SSM6K06FU	20	±12	1.1	—	—	210	160	125	π-MOSVI		
	SSM6K07FU	30	±20	1.5	—	—	—	220	102	π-MOSVI		
TSM 	**SSM3K310T**	20	±10	5.0	66	43	32	28	1120	U-MOSIII		
	SSM3K309T	20	±12	4.7	—	47	35	31	1020	U-MOSIII		
	SSM3K301T	20	±12	3.5	—	110	74	56	320	U-MOSIII		
	SSM3K316T	30	±12	4.0	—	131	87	65(@4.5 V)	270	U-MOSIII		
	SSM3K01T	30	±10	3.2	—	—	150	120	152	π-MOSVI		
	SSM3K02T	30	±10	2.5	—	—	250	200	115	π-MOSVI		
	SSM3K315T	30	±20	6.0	—	—	—	41.5(@4.5 V)	450	U-MOSIV		
	SSM3K14T	30	±20	4.0	—	—	—	67	460	U-MOSII		
	SSM3K320T	30	±20	4.2	—	—	—	77(@4.5 V)	190	U-MOSIV		
	SSM3K303T	30	±20	2.9	—	—	—	120	180	π-MOSVII		
	SSM3K12T	30	±20	3.0	—	—	—	175	120	π-MOSVII		
	SSM3K318T	60	±20	2.5	—	—	—	145(@4.5 V)	235	U-MOSIV		

* The internal connection diagrams only show the general configurations of the circuits.

Semi-Power Dual MOSFETs

Unit: mm

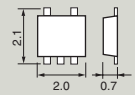
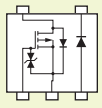
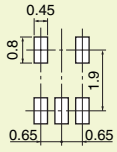
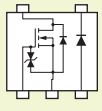
Package	Polarity	Part Number	V_{DSS} (V)	V_{GSS} (V)	I_D (A)	$R_{DS(ON)}$ Max (mΩ) V_{GS} = |1.5 V|	V_{GS} = |1.8 V|	V_{GS} = |2.5 V|	V_{GS} = |4.0 V|	Ciss (pF)	Series	*Internal Connections	Land Pattern Example
ES6 (SOT-563) 	N-ch x 2	**SSM6N42FE***	20	±10	0.77	630	460	340	260 (@4.5 V)	95	U-MOSⅢ		
	P-ch x 2	**SSM6P41FE**	−20	±8	−0.72	1040	670	440	300 (@4.5 V)	110	U-MOSⅤ		
UF6 	N-ch x 2	**SSM6N39TU**	20	±10	1.6	247	190	139	119	260	U-MOSⅢ		
		SSM6N29TU	20	±12	0.8	—	235	178	143	268	U-MOSⅢ		
		SSM6N25TU	20	±12	0.5	—	395	190	145	268	U-MOSⅢ		
		SSM6N24TU	30	±12	0.5	—	—	180	145	245	U-MOSⅢ		
		SSM6N40TU	30	±20	1.6	—	—	—	182	180	U-MOSⅢ		
	P-ch x 2	**SSM6P54TU**	−20	±8	−1.2	555	350	228	—	331	U-MOSⅣ		
		SSM6P39TU	−20	±8	−1.5	—	430	294	213	250	U-MOSⅢ		
		SSM6P28TU	−20	±8	−0.8	—	460	306	234	250	U-MOSⅢ		
		SSM6P26TU	−20	±8	−0.5	—	980	330	230	250	U-MOSⅢ		
		SSM6P25TU	−20	±12	−0.5	—	—	430	260	218	U-MOSⅢ		
		SSM6P40TU	−30	±20	−1.4	—	—	—	403	120	U-MOSⅢ		
	N-ch + P-ch	**SSM6L39TU**	20	±10	1.6	247	190	139	119	260	U-MOSⅢ		
			−20	±8	−1.5	—	430	294	213	250	U-MOSⅢ		
		SSM6L13TU	20	±12	0.8	—	235	178	143	268	U-MOSⅢ		
			−20	±8	−0.8	—	460	306	234	250	U-MOSⅢ		
		SSM6L10TU	20	±12	0.5	—	395	190	145	268	U-MOSⅢ		
			−20	±8	−0.5	—	980	330	230	250	U-MOSⅢ		
		SSM6L11TU	20	±12	0.5	—	395	190	145	268	U-MOSⅢ		
			−20	±12	−0.5	—	—	430	260	218	U-MOSⅢ		
		SSM6L12TU	30	±12	0.5	—	—	180	145	245	U-MOSⅢ		
			−20	±12	−0.5	—	—	430	260	218	U-MOSⅢ		
		SSM6L40TU	30	±20	1.6	—	—	—	182	180	U-MOSⅢ		
			−30	±20	−1.4	—	—	—	403	120	U-MOSⅢ		
	P-ch + N-ch (Load Switch)	**SSM6E01TU**	−12	±12	−1.0	—	—	240	160	310	U-MOSⅢ		
			20	10	0.05	—	—	10 Ω	—	11	π-MOSⅥ		
		SSM6E02TU	−20	±8	−1.8	364	204	136	—	568	U-MOSⅣ		
			20	±10	0.1	15 Ω	—	4 Ω	3 Ω	9.3	π-MOSⅥ		
		SSM6E03TU	−20	±8	−1.8	—	335	180	144	335	U-MOSⅢ		
			20	±10	0.1	15 Ω	—	4 Ω	3 Ω	9.3	π-MOSⅥ		

*: Under development

* The internal connection diagrams only show the general configurations of the circuits.

MOSFET with a Schottky Barrier Diode

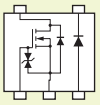
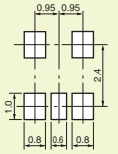
Unit: mm

Package	Polarity	Part Number	MOSFET V_{DSS} (V)	V_{GSS} (V)	I_D (A)	$R_{DS(ON)}$ Max (mΩ) V_{GS} = |1.5 V|	V_{GS} = |1.8 V|	V_{GS} = |2.5 V|	V_{GS} = |4.0 V|	Ciss (pF)	Series	SBD V_R (V)	I_O (A)	V_F Max (V)	@I_F (A)	*Internal Connections	Land Pattern Example
UFV 	P-ch+ SBD	**SSM5G09TU**	−12	±8	−1.5	—	—	200	130	550	U-MOSⅡ	12	0.5	0.43	0.5		
		SSM5G02TU	−12	±12	−1.0	—	—	240	160	310	U-MOSⅡ	12	0.5	0.43	0.5		
		SSM5G10TU	−20	±8	−1.5	—	430	294	213	250	U-MOSⅢ	20	0.7	0.39	0.5		
		SSM5G04TU	−12	±12	−1.0	—	—	420	240	170	U-MOSⅡ	12	0.5	0.43	0.5		
		SSM5G11TU	−30	±20	−1.4	—	—	—	403	120	U-MOSⅢ-H	30	0.7	0.41	0.5		
		SSM5G01TU	−30	±20	−1.0	—	—	—	800	86	U-MOSⅡ	20	0.5	0.45	0.3		
	N-ch+ SBD	**SSM5H10TU**	20	±10	1.6	247	190	139	119	260	U-MOSⅢ	20	0.7	0.39	0.5		
		SSM5H12TU	30	±12	1.9	—	296	177	133	123	U-MOSⅢ	30	0.7	0.41	0.5		
		SSM5H05TU	20	±12	1.5	—	—	220	160	125	U-MOSⅢ	12	0.5	0.43	0.5		
		SSM5H08TU	20	±12	1.5	—	—	220	160	125	U-MOSⅢ	20	0.5	0.45	0.3		
		SSM5H03TU	12	±12	1.4	—	—	—	300	125	U-MOSⅡ	12	0.5	0.43	0.5		
		SSM5H11TU	30	±20	1.6	—	—	—	182	180	U-MOSⅢ	30	0.7	0.41	0.5		
		SSM5H01TU	30	±20	1.4	—	—	—	450	106	U-MOSⅡ	20	0.5	0.45	0.3		
		SSM5H07TU	20	±20	1.2	—	—	—	540	36	π-MOSⅦ	12	0.5	0.43	0.5		

* The internal connection diagrams only show the general configurations of the circuits.

MOSFET with a Schottky Barrier Diode

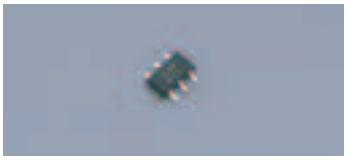
Unit: mm

Package	Polarity	Part Number	MOSFET								SBD				*Internal Connections	Land Pattern Example
			V_{DSS} (V)	V_{GSS} (V)	I_D (A)	$R_{DS(ON)}$ Max (mΩ) V_{GS} = | 1.5 V |	V_{GS} = | 1.8 V |	V_{GS} = | 2.5 V |	V_{GS} = | 4.0 V |	Ciss (pF)	Series	V_R (V)	I_O (A)	V_F Max (V)	@I_F (A)		
SMV	N-ch+ SBD	SSM5H14F	30	±12	3.0	—	138	94	78	270	U-MOSⅢ	45	0.1	0.6	0.1		

* The internal connection diagrams only show the general configurations of the circuits.

VS-6 Series … [Part Number: TPC6xxx]

■ Features



- Zener diode between gate and source for all products
- Thin package, with a board mounting height as low as 0.85 mm (max)

■ Product Offerings

Part Number	Absolute Maximum Ratings			Circuit Configuration	$R_{DS(ON)}$ Max (mΩ)					Q_g Typ. (nC)	C_{iss} Typ. (pF)	Marking	Series
	V_{DSS} (V)	V_{GSS} (V)	I_D (A)		10 V	4.5 V	2.5 V	2.0 V	1.8 V				
TPC6004	20	±12	6	N-ch Single	—	24	32	37	—	17	1400	S2C	U-MOSⅢ
TPC6011 ☆✻	30	±20	6		20	32	—	—	—	14	640	S2L	U-MOSⅣ
TPC6005	30	±12	6		—	28	35	41	—	19	1420	S2E	U-MOSⅢ
TPC6007-H	30	±20	5		54	79	—	—	—	2.8	240	S2G	U-MOSⅢ-H
TPC6006-H	40	±20	3.9		75	100	—	—	—	2.4	251	S2F	U-MOSⅢ-H
TPC6103	–12	±8	–5.5	P-ch Single	—	35	55	—	90	20	1520	S3C	U-MOSⅢ
TPC6105	–20	±8	–2.7		—	110	160	—	300	6	470	S3E	U-MOSⅢ
TPC6107	–20	±12	–4.5		—	55	100	180	—	9.8	680	S3G	U-MOSⅣ
TPC6111	–20	±8	–5.5		—	40	57	—	80	10	700	S3L	U-MOSⅤ
TPC6108	–30	±20	–4.5		60	100	—	—	—	13	570	S3H	U-MOSⅣ
TPC6109-H	–30	±20	–5		59	83	—	—	—	7.2	471	S3J	U-MOSⅢ-H

☆: No protection Zener diode between gate and source ✻: Under development

VS-8 Series … [Part Number: TPCF8xxx]

■ Features

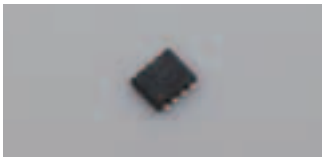
- Ultra-low ON-resistance achieved by employing the U-MOS process
- Thin package, with a board mounting height as low as 0.85 mm (max)
- 32% reduction in mounting area compared with the VS-6 (TSOP-6) Series, due to the use of a high-density flat package
- P_D = 2.5 W @ t = 5 s when the device is mounted on a glass epoxy board

■ Product Offerings

Part Number	Absolute Maximum Ratings			Circuit Configuration	$R_{DS(ON)}$ Max (mΩ)					Q_g Typ. (nC)	C_{iss} Typ. (pF)	Marking	Series
	V_{DSS} (V)	V_{GSS} (V)	I_D (A)		10 V	4.5 V	2.5 V	2.0 V	1.8 V				
TPCF8002 ☆	30	±20	6	N-ch Single	23	31	—	—	—	TBD	TBD	F2B	U-MOSⅣ
TPCF8101	–12	±8	–6	P-ch Single	—	28	40	—	85	18	1600	F3A	U-MOSⅢ
TPCF8103	–20	±8	–2.7		—	110	160	—	300	6	470	F3C	U-MOSⅢ
TPCF8102	–20	±8	–6		—	30	41	—	90	19	1550	F3B	U-MOSⅢ
TPCF8104	–30	±20	–6		28	38	—	—	—	34	1760	F3D	U-MOSⅣ
TPCF8201	20	±12	3	N-ch Dual	—	49	66	100	—	7.5	590	F4A	U-MOSⅢ
TPCF8301	–20	±8	–2.7	P-ch Dual	—	110	160	—	300	6	470	F5A	U-MOSⅢ
TPCF8302	–20	±10	–3		—	59	95	200	—	11	800	F5B	U-MOSⅣ
TPCF8303	–20	±8	–3		—	58	87	—	250	11	860	F5C	U-MOSⅣ
TPCF8304	–30	±20	–3.2		72	105	—	—	—	14	600	F5D	U-MOSⅣ
TPCF8402	30	±20	4	N-ch + P-ch	50	77	—	—	—	10	470	F6B	U-MOSⅢ
	–30	±20	–3.2		72	105	—	—	—	14	600		U-MOSⅣ
TPCF8A01	20	±12	3.0	N-ch + SBD	—	49	66	100	—	7.5	590	F7A	U-MOSⅢ
TPCF8B01	–20	±8	–2.7	P-ch + SBD	—	110	160	—	300	6	470	F8A	U-MOSⅢ

☆: No protection Zener diode between gate and source

PS-8 Series … [Part Number: TPCP8xxx]



■ Features

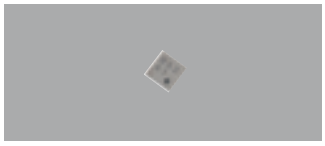
- Same mounting area as for the VS-6 (TSOP-6) Series
- Using flat leads and the latest U-MOS process (U-MOSIV), the PS-8 Series offers a 70% reduction in $R_{DS(ON)}$ compared with the VS-6 Series.

■ Product Offerings

Part Number	Absolute Maximum Ratings			Circuit Configuration	$R_{DS(ON)}$ Max (mΩ)					Q_g Typ. (nC)	C_{iss} Typ. (pF)	Series
	V_{DSS} (V)	V_{GSS} (V)	I_D (A)		10 V	4.5 V	4 V	2.5 V	1.8 V			
TPCP8006 ☆	20	±12	9.1	N-ch Single	—	10	—	13.7	—	22	1480	U-MOSIV
TPCP8001-H	30	±20	7.2		16	25	—	—	—	11	640	U-MOSIII-H
TPCP8004 ☆	30	±20	8.3		8.5	14.5	—	—	—	26	1270	U-MOSIV
TPCP8005-H ☆	30	±20	11		12.9	15.7	—	—	—	20	1433	U-MOSV-H
TPCP8A05-H ☆	30	±20	8	MOSBD	17.5	21.9	—	—	—	16	1300	U-MOSV-H
TPCP8003-H ☆	100	±20	2.2	N-ch Single	180	190	—	—	—	7.5	360	U-MOSIII-H
TPCP8101	–20	±8	–5.6	P-ch Single	—	30	—	41	90	19	1550	U-MOSIII
TPCP8102	–20	±12	–7.2		—	18	—	30	—	33	2560	U-MOSIV
TPCP8103-H	–40	±20	–4.8		40	54	—	—	—	19	800	U-MOSIII-H
TPCP8201	30	±20	4.2	N-ch Dual	50	77	—	—	—	10	470	U-MOSIII
TPCP8202	30	±12	5.5		—	23	—	39	—	28	2150	U-MOSIV
TPCP8203	40	±20	4.7	P-ch Dual	40	60	—	—	—	16	770	U-MOSIII
TPCP8301	–20	±12	–5		—	31	—	60	—	20	1500	U-MOSIV
TPCP8302	–20	±12	–5		—	—	33	45	95	20	1500	U-MOSIV
TPCP8303	–20	±8	–3.8		—	40	—	57	—	10	640	U-MOSV
TPCP8401	20	±10	0.1	N-ch/P-ch Load Switch	—	—	3Ω	4Ω	—	—	—	π-MOSVI
	–12	±8	–5.5		—	38	—	58	103	20	1520	U-MOSIII
TPCP8402	30	±20	4.2	N-ch + P-ch	50	77	—	—	—	10	470	U-MOSIII
	–30	±20	–3.4		72	105	—	—	—	14	600	U-MOSIV
TPCP8404 ☆	30	±20	4	N-ch + P-ch	50	100	—	—	—	4.6	190	U-MOSIV
	–30	±20	–4		50	100	—	—	—	13	510	U-MOSV
TPCP8403	40	±20	4.7	N-ch + P-ch	40	60	—	—	—	16	770	U-MOSIII
	–40	±20	–3.4		70	105	—	—	—	15	680	U-MOSIII
TPCP8BA1	–20	±12	–1.3	MOSBD	—	—	180	260	—	—	—	U-MOSII
TPCP8AA1	20	±12	1.6		—	—	105	140	—	—	—	U-MOSII
TPCP8J01	–32	±20	–5.5	P-ch + NPN	35	—	49	—	—	34	1760	U-MOSIV
	50	—	0.1		—	—	—	—	—	—	—	U-MOSIV + Bip-Tr

☆: No protection Zener diode between gate and source

Chip LGA Series ... [Part Number: TPCL4xxx]



■ Features

- Chip-scale package for high-density board assembly (58% reduction in mounting area compared with the STP2 package)

■ Product Offerings

Part Number	Absolute Maximum Ratings			Circuit Configuration	$R_{DS(ON)}$ Max (mΩ)				Q_g Typ. (nC)	C_{iss} Typ. (pF)	Series
	V_{DSS} (V)	V_{GSS} (V)	I_D (A)		4.5 V	4 V	3.1 V	2.5 V			
TPCL4201 ☆	20	±12	6	N-ch Dual	31	33	44	52	11.5	720	U-MOSV
TPCL4203 ☆✻	24	±12	6		(36)	(38)	(46)	(55)	(10)	(685)	U-MOSV
TPCL4202 ☆✻	30	±12	6		(40)	(42)	(50)	(64)	(10)	(780)	U-MOSV

☆: No protection Zener diode between gate and source ✻: Under development

STP2 Series ... [Part Number: TPCT4xxx]

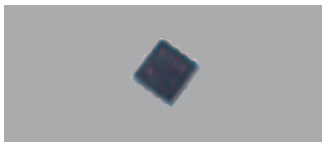
■ Features

- The combination of a new chip design using Toshiba U-MOSIV process technology and a new small pump-structured package, offers low ON-resistance.

■ Product Offerings

Part Number	Absolute Maximum Ratings			Circuit Configuration	$R_{SS(ON)}$ Max (mΩ)			Q_g Typ. (nC)	C_{iss} Typ. (pF)	Series
	V_{SSS} (V)	V_{GSS} (V)	I_S (A)		2.5 V	4 V	4.5 V			
TPCT4203	20	±12	6	N-ch Dual	49	32	31	11	790	U-MOSIV
TPCT4204	30	±12	6		52	39	38	12	780	U-MOSIV

TSON Advance Series … [Part Number: TPCC8xxx]



■ Features

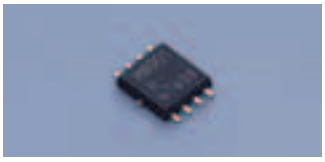
- The small thermally enhanced package gives a 64% reduction in mounting area compared with SOP-8, yet an equivalent maximum permissible power dissipation.

■ Product Offerings

Part Number	Absolute Maximum Ratings			Circuit Configuration	$R_{DS(ON)}$ Max (mΩ)				Q_g Typ. (nC)	C_{iss} Typ. (pF)	Series
	V_{DSS} (V)	V_{GSS} (V)	I_D (A)		10 V	4.5 V	4 V	2.5 V			
TPCC8007 ☆✻	20	±12	27	N-ch Single	—	(4.6)	—	(8.7)	TBD	TBD	U-MOSIV
TPCC8008 ☆	30	±25	25		6.8	12.8	—	—	30	1600	U-MOSIV
TPCC8003-H ☆	30	±20	13		16.9	19.3	—	—	8.6	990	U-MOSVI-H
TPCC8001-H ☆	30	±20	22		8.3	10.6	—	—	14.3	1900	U-MOSV-H
TPCC8002-H ☆	30	±20	22		8.3	10.6	—	—	14.3	1900	U-MOSV-H, rg=3.2Ω(Typ.)
TPCC8A01-H ☆	30	±20	21	MOSBD	9.9	12.6	—	—	10.1	1430	U-MOSV-H
TPCC8006-H ☆	30	±20	22	N-ch Single	8.0	9.3	—	—	15.0	1700	U-MOSVI-H
TPCC8005-H ☆	30	±20	26		6.4	7.4	—	—	19.0	2200	U-MOSVI-H
TPCC8102 ☆	–30	±20	–15	P-ch Single	18.9	—	33.2	—	26	1200	U-MOSV
TPCC8103 ☆	–30	±20	–18		12	—	22	—	38	1600	U-MOSV

☆: No protection Zener diode between gate and source ✻: Under development

TSSOP Advance Series … [Part Number: TPCM8xxx]

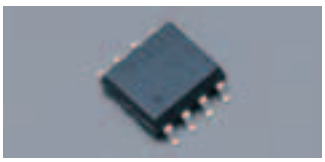


■ Product Offerings

Part Number	Absolute Maximum Ratings			Circuit Configuration	$R_{DS(ON)}$ Max (mΩ)			Q_g Typ. (nC)	C_{iss} Typ. (pF)	Series
	V_{DSS} (V)	V_{GSS} (V)	I_D (A)		10 V	4.5 V	4 V			
TPCM8001-H	30	±20	20	N-ch Single	9.5	14	—	19	1130	U-MOSIII-H
TPCM8003-H ☆	30	±20	21		12.9	15.7	—	11	1433	U-MOSV-H
TPCM8004-H ☆	30	±20	24		11	13.4	—	11	1433	U-MOSV-H
TPCM8006	30	±20	25		7.0	13.5	—	26	1270	U-MOSIV
TPCM8002-H ☆	30	±20	30		6.2	8.2	—	18	2270	U-MOSV-H
TPCM8A05-H ☆	30	±20	20	MOSBD	12.9	17.2	—	7.4	1300	U-MOSV-H
TPCM8102	–30	±20	–25	P-ch Single	7.7	—	16	60	2450	U-MOSV

☆: No protection Zener diode between gate and source

SOP-8 Series … [Part Number: TPC8xxx]



■ Features

- Low ON-resistance and high-speed-switching series are available.
  Low ON-resistance series: UMOSIV/V/VI
  High-speed-switching series: U-MOSIII-H and U-MOSV-H
- ON-resistance reduction through the use of an Al strap structure

■ Product Offerings

Part Number	Absolute Maximum Ratings			Circuit Configuration	$R_{DS(ON)}$ Max (mΩ)				Q_g Typ. (nC)	C_{iss} Typ. (pF)	Series
	V_{DSS} (V)	V_{GSS} (V)	I_D (A)		10 V	4.5 V	4 V	2.5 V			
TPC8021-H	30	±20	11	N-ch Single	17	25	—	—	11	640	U-MOSIII-H
TPC8025 ☆	30	±20	11		9	14.5	—	—	26	1270	U-MOSIV
TPC8030 ☆	30	±25	11		8.5	17	—	—	24	1140	U-MOSIV
TPC8037-H ☆	30	±20	12		11.4	13.9	—	—	11	1433	U-MOSV-H
TPC8038-H ☆	30	±20	12		11.4	13.9	—	—	11	1433	U-MOSV-H
TPC8040-H ☆	30	±20	13		9.7	11.1	—	—	12	1700	U-MOSVI-H
TPC8041 ☆	30	±20	13		7	13.5	—	—	27	1270	U-MOSIV
TPC8026 ☆	30	±20	13		6.6	10	—	—	42	1800	U-MOSIV
TPC8032-H ☆	30	±20	15		6.5	8.6	—	—	17	2270	U-MOSV-H
TPC8039-H ☆	30	±20	17		5.7	6.6	—	—	18	2600	U-MOSVI-H
TPC8033-H ☆	30	±20	17		5.3	7.2	—	—	22	2900	U-MOSV-H

☆: No protection Zener diode between gate and source

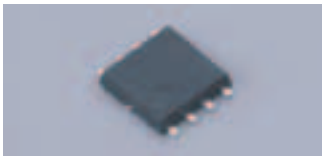
4 Low-V_{DSS} MOSFETs (in Small SMD Packages)

■ Product Offerings

Part Number	Absolute Maximum Ratings			Circuit Configuration	$R_{DS(ON)}$ Max (mΩ)				Q_g Typ. (nC)	C_{iss} Typ. (pF)	Series
	V_{DSS} (V)	V_{GSS} (V)	I_D (A)		10 V	4.5 V	4 V	2.5 V			
TPC8028 ☆	30	±20	18	N-ch Single	4.3	8	—	—	45	1800	U-MOSIV
TPC8029 ☆	30	±20	18		3.8	7	—	—	49	2200	U-MOSIV
TPC8036-H ☆	30	±20	18		4.5	5.1	—	—	26	3500	U-MOSVI-H
TPC8034-H ☆	30	±20	18		3.5	4.5	—	—	35	4614	U-MOSV-H
TPC8035-H ☆	30	±20	18		3.2	3.6	—	—	44	6000	U-MOSVI-H
TPC8042 ☆	30	±20	18		3.4	6.5	—	—	56	2900	U-MOSIV
TPC8027 ☆	30	±20	18		2.7	5.5	—	—	113	4200	U-MOSIV
TPC8022-H	40	±20	7.5		27	35	—	—	11	650	U-MOSIII-H
TPC8052-H ☆	40	±20	12		11.5	13.3	—	—	13	1620	U-MOSVI-H
TPC8047-H ☆	40	±20	16		7.6	8.8	—	—	23	2590	U-MOSVI-H
TPC8046-H ☆	40	±20	18		5.7	6.6	—	—	31	3545	U-MOSVI-H
TPC8045-H ☆	40	±20	18		3.9	4.4	—	—	48	5800	U-MOSVI-H
TPC8053-H ☆	60	±20	9		22.5	24.2	—	—	13	1620	U-MOSVI-H
TPC8050-H ☆	60	±20	11		14.5	15.6	—	—	21	2590	U-MOSVI-H
TPC8049-H ☆	60	±20	13		10.7	11.5	—	—	29	3545	U-MOSVI-H
TPC8048-H ☆	60	±20	16		6.9	7.4	—	—	46	5800	U-MOSVI-H
TPC8051-H ☆	80	±20	13		9.7	10.1	—	—	43	5800	U-MOSVI-H
TPC8012-H	200	±20	1.8		400	—	—	—	11	440	π-MOSV
TPC8208	20	±12	5	N-ch Dual	—	—	50	70	9.5	780	U-MOSIII
TPC8207	20	±12	6		—	—	20	30	22	2010	U-MOSIII
TPC8211	30	±20	5.5		36	44	—	—	25	1250	U-MOSIII
TPC8212-H	30	±20	6		21	27	—	—	16	840	U-MOSIII-H
TPC8216-H ☆	30	±20	6.4		20	23	—	—	7.6	900	U-MOSVI-H
TPC8210	30	±20	8		15	20	—	—	75	3530	U-MOSIII
TPC8218-H☆	60	±20	3.8		57	64	—	—	5.7	640	U-MOSVI-H
TPC8213-H	60	±20	5		50	56	—	—	6	625	U-MOSIII-H
TPC8214-H	100	±20	2.2		180	190	—	—	4.5	360	U-MOSIII-H
TPC8115	–20	±8	–10	P-ch Single	—	10	—	14	115	9130	U-MOSIV
TPC8119 ☆	–30	±20	–10		13	—	28	—	40	1560	U-MOSV
TPC8121 ☆	–30	±20	–11		12	—	24	—	42	1770	U-MOSV
TPC8111	–30	±20	–11		12	—	18	—	107	5710	U-MOSIV
TPC8113	–30	±20	–11		10	—	18	—	107	4500	U-MOSIV
TPC8123 ☆	–30	–25/+20	–11		9	12.5	—	—	68	2940	U-MOSVI
TPC8122 ☆	–30	±20	–12		8	—	16.5	—	62	2450	U-MOSV
TPC8118 ☆	–30	±20	–13		7	—	15	—	65	2700	U-MOSV
TPC8114	–30	±20	–18		4.5	—	6.8	—	180	7480	U-MOSIV
TPC8117 ☆	–30	±20	–18		3.9	—	7.9	—	130	4600	U-MOSV
TPC8120 ☆	–30	–25/+20	–18		3.2	4.2	—	—	180	7420	U-MOSVI
TPC8116-H	–40	±20	–7.5		30	37	—	—	27	1190	U-MOSIII-H
TPC8110	–40	±20	–8		25	—	35	—	48	2180	U-MOSIII
TPC8405	30	±20	6	N-ch/P-ch Dual	26	33	—	—	27	1240	U-MOSIII
	–30	±20	–4.5		33	42	—	—	40	1540	U-MOSIV
TPC8406-H	40	±20	6.5		27	35	—	—	11	650	U-MOSIII-H
	–40	±20	–6.5		30	37	—	—	27	1190	U-MOSIII-H
TPC8404	250	±20	1.1		1.7	—	—	—	10	267	π-MOSV
	–250	±20	–0.9		2.55	—	—	—	12	381	π-MOSV
TPC8A01	30	±20	6	N-ch/ N-ch + SBD	25	30	—	—	17	940	U-MOSIII
	30	±20	8.5/1		18	21	—	—	49	2295	U-MOSIII
TPC8A05-H ☆	30	±20	10/1	MOSBD	13.3	17.6	—	—	7.4	1300	U-MOSV-H
TPC8A06-H ☆	30	±20	12/1		10.1	12.9	—	—	9.6	1400	U-MOSV-H
TPC8A03-H ☆	30	±20	17/1		5.6	7	—	—	19	2640	U-MOSV-H
TPC8A04-H ☆	30	±20	18/1		3.6	4.5	—	—	29	4400	U-MOSV-H

☆: No protection Zener diode between gate and source

SOP Advance Series ... [Part Number: TPCA8xxx]



■ Features

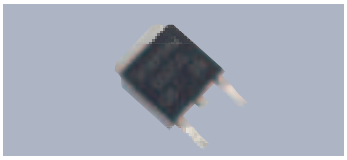
- Low ON-resistance and high-speed-switching series are available.
  Low ON-resistance series: UMOSIV/V
  High-speed-switching series: U-MOSIII-H, U-MOSV-H and U-MOSVI-H
- High-current, thin and thermally enhanced package

■ Product Offerings

Part Number	Absolute Maximum Ratings			Circuit Configuration	$R_{DS(ON)}$ Max (mΩ)					Q_g Typ. (nC)	C_{iss} Typ. (pF)	Series
	V_{DSS} (V)	V_{GSS} (V)	I_D (A)		10 V	4.5 V	4 V	2.5 V	1.8 V			
TPCA8011-H	20	±12	40	N-ch Single	—	3.5	—	7.5	—	32	2900	U-MOSIII-H
TPCA8040-H ☆	30	±20	23		9.4	10.8	—	—	—	11.7	1700	U-MOSVI-H
TPCA8030-H ☆	30	±20	24		11.0	13.4	—	—	—	83	1433	U-MOSV-H
TPCA8031-H ☆	30	±20	24		11.0	13.4	—	—	—	83	1433	U-MOSV-H
TPCA8018-H ☆	30	±20	30		6.2	8.2	—	—	—	18	2270	U-MOSV-H
TPCA8039-H ☆	30	±20	34		5.7	6.6	—	—	—	19	2600	U-MOSVI-H
TPCA8024 ☆	30	±20	35		4.3	7.8	—	—	—	45	1800	U-MOSIV
TPCA8036-H ☆	30	±20	38		4.2	4.8	—	—	—	26	3500	U-MOSVI-H
TPCA8012-H ☆	30	±20	40		4.9	6.8	—	—	—	22	2900	U-MOSV-H
TPCA8025 ☆	30	±20	40		3.5	6.0	—	—	—	49	2200	U-MOSIV
TPCA8060-H ☆	30	±20	45		3.4	3.9	—	—	—	34	4600	U-MOSVI-H
TPCA8042 ☆	30	±20	45		3.3	5.7	—	—	—	56	2900	U-MOSIV
TPCA8019-H ☆	30	±20	45		3.1	4.1	—	—	—	34	4614	U-MOSV-H
TPCA8026 ☆	30	±20	45		2.2	4.5	—	—	—	113	4200	U-MOSIV
TPCA8028-H ☆	30	±20	50		2.8	3.2	—	—	—	46	6000	U-MOSVI-H
TPCA8020-H	40	±20	7.5		27	35	—	—	—	11	650	U-MOSIII-H
TPCA8052-H ☆	40	±20	20		11.3	13.1	—	—	—	13	1620	U-MOSVI-H
TPCA8014-H	40	±20	30		9	14	—	—	—	22	1365	U-MOSIII-H
TPCA8027-H	40	±20	30		10	—	—	—	—	23	1430	U-MOSIII-H
TPCA8047-H ☆	40	±20	32		7.3	8.5	—	—	—	23	2590	U-MOSVI-H
TPCA8015-H	40	±20	35		5.4	7.9	—	—	—	37	2155	U-MOSIII-H
TPCA8046-H ☆	40	±20	38		5.4	6.3	—	—	—	29	3545	U-MOSVI-H
TPCA8045-H ☆	40	±20	46		3.6	4.1	—	—	—	47	5800	U-MOSVI-H
TPCA8053-H ☆	60	±20	15		22.3	24	—	—	—	13	1620	U-MOSVI-H
TPCA8050-H ☆	60	±20	24		14.2	15.3	—	—	—	21	2590	U-MOSVI-H
TPCA8016-H	60	±20	25		21	26	—	—	—	22	1375	U-MOSIII-H
TPCA8049-H ☆	60	±20	28		10.4	11.2	—	—	—	29	3545	U-MOSVI-H
TPCA8048-H ☆	60	±20	35		6.6	7.1	—	—	—	46	5800	U-MOSVI-H
TPCA8051-H ☆	80	±20	28		9.4	9.8	—	—	—	47	5800	U-MOSVI-H
TPCA8006-H	100	±20	18		67	—	—	—	—	12	780	π-MOSVII
TPCA8022-H	100	±20	22		26	—	—	—	—	38	2330	U-MOSIII-H
TPCA8009-H	150	±20	7		350	—	—	—	—	10	600	π-MOSV MACHII
TPCA8010-H	200	±20	5.5		450	—	—	—	—	10	600	π-MOSV MACHII
TPCA8008-H	250	±20	4		580	—	—	—	—	10	600	π-MOSV MACHII
TPCA8105	–12	±8	–6	P-ch Single	—	33	—	51	92	18	1600	U-MOSIV
TPCA8103	–30	±20	–40		4.2	—	6.8	—	—	184	7880	U-MOSIV
TPCA8106 ☆	–30	±20	–40		3.7	—	7.8	—	—	120	4600	U-MOSV
TPCA8107-H	–40	±20	–7.5		30	37	—	—	—	27	1190	U-MOSIII-H
TPCA8108	–40	±20	–40		9.5	—	—	—	—	100	4820	U-MOSIII
TPCA8104	–60	±20	–40		16	—	24	—	—	90	4300	U-MOSIII
TPCA8A05-H ☆	30	±20	10	MOSBD	12.9	17.2	—	—	—	7.4	1300	U-MOSV-H
TPCA8A02-H ☆	30	±20	34		5.3	6.7	—	—	—	19	2640	U-MOSV-H
TPCA8A08-H ☆	30	±20	38		4.2	5.3	—	—	—	24	3500	U-MOSV-H
TPCA8A04-H ✻☆	30	±20	42		3.2	4.1	—	—	—	30	4400	U-MOSV-H

☆: No protection Zener diode between gate and source ✻: Under development

DPAK Series ... [Part Number: TKxxPxxxM1]



■ Features

- High-current, thermally enhanced package

■ Product Offerings

Part Number	Absolute Maximum Ratings			Circuit Configuration	$R_{DS(ON)}$ Max (mΩ)		Q_g Typ. (nC)	C_{iss} Typ. (pF)	Series
	V_{DSS} (V)	V_{GSS} (V)	I_D (A)		10 V	4.5 V			
TK40P03M1☆	30	±20	40	N-ch Single	10.8	14.4	9.4	1150	U-MOSVI-H
TK50P03M1☆	30	±20	50		7.5	9.8	13.3	1700	U-MOSVI-H
TK40P04M1☆	40	±20	40		10.3	13.4	29	1920	U-MOSVI-H
TK50P04M1☆	40	±20	50		8.7	10.2	38	2600	U-MOSVI-H

☆: No protection Zener diode between gate and source

4-7 Standard MOSFET Series (I_D < 500 mA)

Single MOSFETs

Polarity	Absolute Maximum Ratings			Package						V_{th} (V)	$R_{DS(ON)}$ Typ. (Max) (Ω)	V_{GS} (V)
	V_{DSS} (V)	V_{GSS} (V)	I_D (mA)	S-Mini (SOT-346) 2925 size, 3-pin	USM (SOT-323) 2021 size, 3-pin	UFM 2021 size, 3-pin	SSM (SOT-416) 1616 size, 3-pin	VSEM (SOT-723) 1212 size, 3-pin	CST3 1006 size, 3-pin			
N-ch	20	±10	180	—	—	—	SSM3K35FS	SSM3K35MFV	SSM3K35CT	0.4 to 1.0	5 (20)	1.2
	20	±10	100	—	SSM3K16FU	—	SSM3K16FS	SSM3K16FV	SSM3K16CT	0.6 to 1.1	5.2(15)	1.5
	20	±10	500	—	—	SSM3K36TU	SSM3K36FS	SSM3K36MFV	—	0.35 to 1.0	0.95 (1.52)	1.5
	20	±10	500	—	—	—	SSM3K43FS	—	—	0.35 to 1.0	0.95 (1.52)	1.5
	20	10	100	—	—	—	—	SSM3K03FV	—	0.7 to 1.3	4 (12)	2.5
	20	10	100	—	**SSM3K04FU	—	—	**SSM3K04FV	—	0.7 to 1.3	4 (12)	2.5
	20	±12	400	—	SSM3K05FU	—	—	—	—	0.6 to 1.1	0.85 (1.20)	2.5
	30	±20	100	SSM3K15F	SSM3K15FU	—	SSM3K15FS	SSM3K15FV	SSM3K15CT	0.8 to 1.5	4.0 (7.0)	2.5
	30	±20	100	—	—	—	SSM3K44FS	SSM3K44MFV	—	0.8 to 1.5	4.0 (7.0)	2.5
	30	±20	200	2SK2009	—	—	—	—	—	0.5 to 1.5	1.2 (2.0)	2.5
	30	±20	400	—	SSM3K09FU	—	—	—	—	1.1 to 1.8	0.8 (1.2)	4.0
	50	±7	100	—	SSM3K17FU	—	—	—	—	0.9 to 1.5	22 (40)	2.5
	60	±20	200	2SK1062	—	—	—	—	—	2.0 to 3.5	0.6 (1.0)	10
	60	±20	200	SSM3K7002F	SSM3K7002FU	—	—	—	—	1.0 to 2.5	2.2 (3.3)	4.5
	60	±20	200	SSM3K7002AF	SSM3K7002AFU	—	—	—	—	1.0 to 2.5	1.8 (3.3)	4.5
	60	±20	200	SSM3K7002BF	SSM3K7002BFU	—	SSM3K7002BFS	—	—	1.5 to 3.1	2.1 (3.3)	4.5
P-ch	–20	±10	–100	—	—	—	SSM3J35FS	SSM3J35MFV	SSM3J35CT	–0.4 to –1.0	11 (44)	–1.2
	–20	±10	–100	—	SSM3J16FU	—	SSM3J16FS	SSM3J16FV	SSM3J16CT	–0.6 to –1.1	18 (45)	–1.5
	–20	±8	–330	—	—	SSM3J36TU	SSM3J36FS	SSM3J36MFV	—	–0.3 to –1.0	2.23 (3.6)	–1.5
	–20	±12	–200	—	SSM3J05FU	—	—	—	—	–0.6 to –1.1	3.2 (4.0)	–2.5
	–30	±20	–100	SSM3J15F	SSM3J15FU	—	SSM3J15FS	SSM3J15FV	SSM3J15CT	–1.1 to –1.7	14 (32)	–2.5
	–30	±20	–200	2SJ305	—	—	—	—	—	–0.5 to –1.5	2.4 (4.0)	–2.5
	–30	±20	–200	—	SSM3J09FU	—	—	—	—	–1.1 to –1.8	3.3 (4.2)	–4.0
	–50	–7	–50	2SJ343	2SJ344	—	—	—	—	–0.8 to –2.5	20 (50)	–4.0
	–60	±20	–200	2SJ168	—	—	—	—	—	–2.0 to –3.5	1.3 (2.0)	–10

**: Built-in 1-MΩ gate-source resistor

Dual MOSFETs

Polarity	Absolute Maximum Ratings			Package						V_{th} (V)	$R_{DS(ON)}$ Typ. (Max) (Ω)	V_{GS} (V)	Constituent Devices
	V_{DSS} (V)	V_{GSS} (V)	I_D (mA)	US6 (SOT-363) 2021 size, 6-pin	UF6 2021 size, 6-pin	USV (SOT-353) 2021 size, 5-pin	ES6 (SOT-563) 1616 size, 6-pin	ESV (SOT-553) 1616 size, 5-pin	CST6D 1009 size, 6-pin				
N-ch×2	20	±10	180	SSM6N35FU	—	—	SSM6N35FE	—	—	0.4 to 1.0	5 (20)	1.2	SSM3K35FS×2
	20	±10	100	SSM6N16FU	—	SSM5N16FU	SSM6N16FE	SSM5N16FE	—	0.6 to 1.1	5.2 (15)	1.5	SSM3K16FU×2
	20	±10	250	—	—	—	—	—	SSM6N37CTD	0.35 to 1.0	3.07 (5.6)	1.5	—
	20	±10	500	—	SSM6N36TU	—	SSM6N36FE	—	—	0.35 to 1.0	0.95 (1.52)	1.5	SSM3K36FS×2
	20	±10	500	SSM6N43FU	—	—	—	—	—	0.35 to 1.0	0.95 (1.52)	1.5	SSM3K43FS×2
	20	10	100	—	—	—	SSM6N03FE	SSM5N03FE	—	0.7 to 1.3	4 (12)	2.5	SSM3K03FE×2
	20	10	100	**SSM6N04FU	—	—	—	—	—	0.7 to 1.3	4 (12)	2.5	SSM3K04FU×2
	20	±12	400	SSM6N05FU	—	SSM5N05FU	—	—	—	0.6 to 1.1	0.85 (1.2)	2.5	SSM3K05FU×2
	30	±20	100	SSM6N15FU	—	SSM5N15FU	SSM6N15FE	SSM5N15FE	—	0.8 to 1.5	4.0 (7.0)	2.5	SSM3K15FU×2
	30	±20	100	SSM6N44FU	—	—	SSM6N44FE	—	—	0.8 to 1.5	4.0 (7.0)	2.5	SSM3K44FS×2
	30	±20	400	SSM6N09FU	—	—	—	—	—	1.1 to 1.8	0.8 (1.2)	4.0	SSM3K09FU×2
	50	±7	100	SSM6N17FU	—	—	—	—	—	0.9 to 1.5	22 (40)	2.5	SSM3K17FU×2
	60	±20	200	SSM6N7002FU	—	—	—	—	—	1.0 to 2.5	2.2 (3.3)	4.5	SSM3K7002FU×2
	60	±20	200	SSM6N7002AFU	—	—	—	—	—	1.0 to 2.5	1.8 (3.3)	4.5	SSM3K7002AFU×2
	60	±20	200	SSM6N7002BFU	—	—	SSM6N7002BFE	—	—	1.5 to 3.1	2.1 (3.3)	4.5	SSM3K7002BFU×2
P-ch×2	–20	±10	–100	SSM6P35FU	—	—	SSM6P35FE	—	—	–0.4 to –1.0	11 (44)	–1.2	SSM3J35FS×2
	–20	±10	–100	SSM6P16FU	—	SSM5P16FU	SSM6P16FE	SSM5P16FE	—	–0.6 to –1.1	18 (45)	–1.5	SSM3J16FU×2
	–20	±8	–330	—	SSM6P36TU	—	SSM6P36FE	—	—	–0.3 to –1.0	2.23 (3.6)	–1.5	SSM3J36FS×2
	–20	±12	–200	SSM6P05FU	—	SSM5P05FU	—	—	—	–0.6 to –1.1	3.2 (4.0)	–2.5	SSM3J05FU×2
	–30	±20	–100	SSM6P15FU	—	SSM5P15FU	SSM6P15FE	SSM5P15FE	—	–1.1 to –1.7	14 (32)	–2.5	SSM3J15FU×2
	–30	±20	–200	SSM6P09FU	—	—	—	—	—	–1.1 to –1.8	3.3 (4.2)	–4.0	SSM3J09FU×2
N-ch+ P-ch	20	±10	180	SSM6L35FU	—	—	SSM6L35FE	—	—	0.4 to 1.0	5 (20)	1.2	SSM3K35FS
	–20	±10	–100							–0.4 to –1.0	11 (44)	–1.2	+SSM3J35FS
	20	±10	100	—	—	—	SSM6L16FE	—	—	0.6 to 1.1	5.2 (15)	1.5	SSM3K16FS
	–20	±10	–100							–0.6 to –1.1	18 (45)	–1.5	+SSM3J16FS
	20	±10	500	—	SSM6L36TU	—	SSM6L36FE	—	—	0.35 to 1.0	0.95 (1.52)	1.5	SSM3K36FS
	–20	±8	–330							–0.3 to –1.0	2.23 (3.6)	–1.5	+SSM3J36FS
	20	±12	400	SSM6L05FU	—	—	—	—	—	0.6 to 1.1	0.85 (1.2)	2.5	SSM3K05FU
	–20	±12	–200							–0.6 to –1.1	3.2 (4.0)	–2.5	+SSM3J05FU
	30	±20	400	SSM6L09FU	—	—	—	—	—	1.1 to 1.8	0.8 (1.2)	4.0	SSM3K09FU
	–30	±20	–200							–1.1 to –1.8	3.3 (4.2)	–4.0	+SSM3J09FU

**: Built-in 1-MΩ gate-source resistor

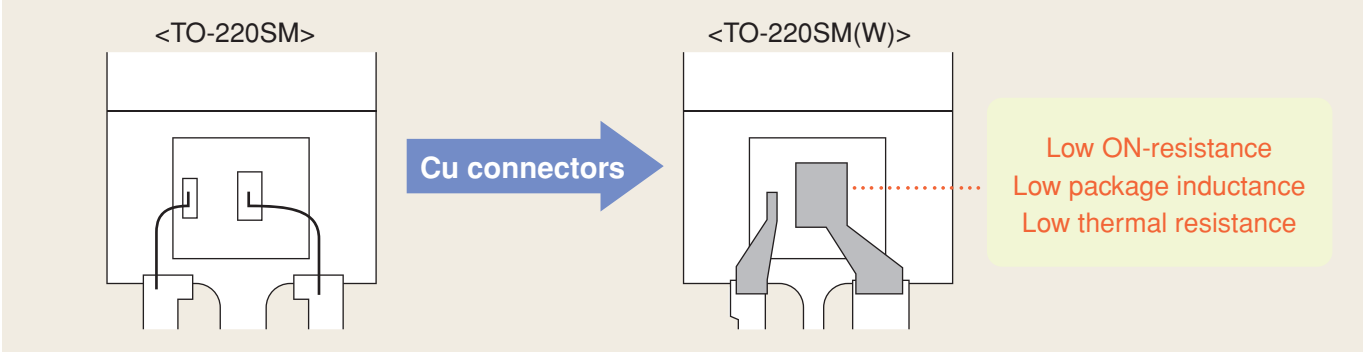
5-1 TO-220SM(W) Series

The TO-220SM(W) package, which uses Cu connectors and a wide source terminal, realizes low ON-resistance and a high current-carrying capability.

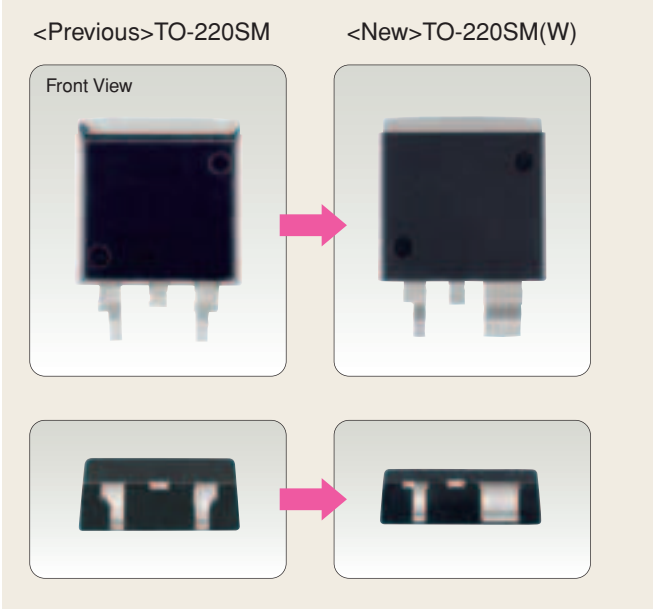
■ Features

- Achieves low ON-resistance, low package inductance and low thermal resistance due to the use of Cu connectors.
- Achieves a high current-carrying capability due to the use of a wide source terminal (I_D (DC) = 150 A max)
- AEC-Q101-qualified at a channel temperature (Tch) of 175˚C
- Thin package: 3.7-mm (max) thick, much thinner than the previous TO-220SM package with a thickness of 4.7 mm (max)

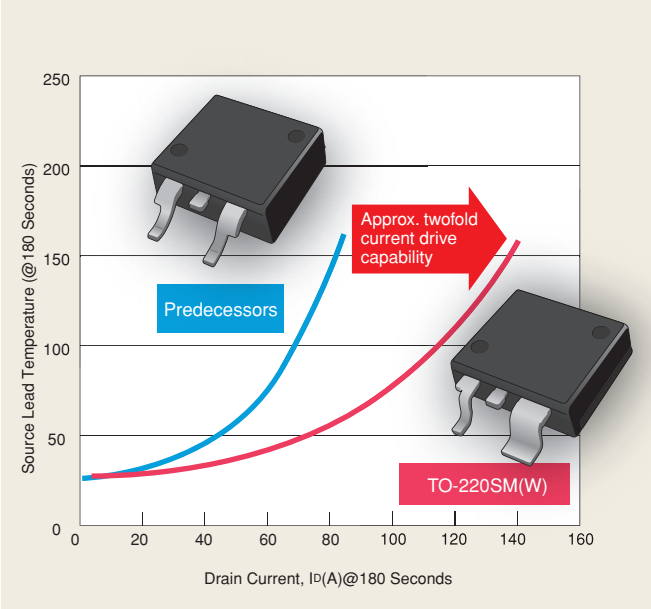
■ Characteristics of the WARP Series



■ Package



■ Comparison of the Source Lead Temperature



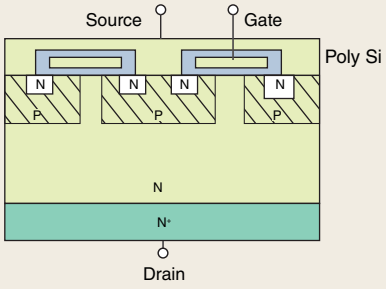
■ Product Offerings

Part Number	Absolute Maximum Ratings			$R_{DS(ON)}$ Max (mΩ)		C_{iss} Typ. (pF)	Q_g Typ. (nC)	Series
	V_{DSS} (V)	V_{GSS} (V)	I_D (A)	V_{GS} = 10 V	V_{GS} = 6 V			
TJ120F06J3	–60	±20	–120	8	—	11500	258	U-MOSⅢ
TK100F04K3	40	±20	100	3	—	4500	102	U-MOSⅣ
TK100F04K3L	40	±20	100	3	4.5	4980	105	U-MOSⅣ
TK150F04K3	40	±20	150	2.1	—	7500	166	U-MOSⅣ
TK150F04K3L	40	±20	150	2.1	3.2	9400	190	U-MOSⅣ
TK100F06K3	60	±20	100	5	—	4500	98	U-MOSⅣ
TK130F06K3	60	±20	130	3.4	—	8400	170	U-MOSⅣ
TK50F15J1	150	±20	50	30	—	4300	75	U-MOSⅢ

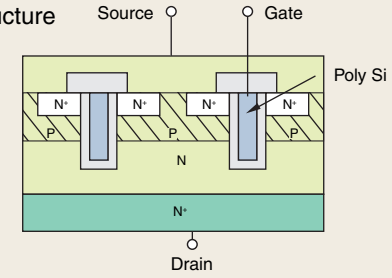
5-2 U-MOS (Trench Type) Series

Fabricated using a trench structure, the U-MOS Series ultra-high integration density and thus

Planar Structure



Trench (U-MOS) Structure



■ Features

- High density through the use of submicron technology
- 60% reduction in $R_{DS\ (ON)}$ by per unit area (as compared with the maximum $R_{DS\ (ON)}$ of L^2-π-MOSV)
- Guaranteed avalanche capability and improved di/dt rate

■ Product Offerings

Applications	Part Number	Absolute Maximum Ratings				Package	$R_{DS(ON)}$ Max (mΩ)				Q_g Typ. (nC)	Series
		V_{DSS} (V)	V_{GSS} (V)	I_D (A)	P_D (W)		10 V	6 V	4.5 V	4 V		
motor drive Solenoids Lamp drivers DC-DC converters	**2SJ668**	–60	±20	–5	20	PW-Mold	170	—	—	250	15	
	2SJ681	–60	±20	–5	20	New PW-Mold2	170	—	—	250	15	
	2SJ669	–60	±20	–5	1.2	TPS	170	—	—	250	15	U-MOSⅢ
	TPCA8104	–60	±20	–40	45	SOP Advance	16	—	—	24	90	
	TJ70A06J3	–60	±20	–70	54	TO-220SIS	8.0	—	10	—	246	
	TJ120F06J3	–60	±20	–120	300	TO-220SM(W)	8.0	—	—	—	258	
LCD backlight inverter	**TJ20A10M3** ☆	–100	±20	–20	35	TO-220SIS	90	—	—	—	120	U-MOSⅥ
motor drive Solenoids Lamp drivers DC-DC converters	**2SK3754**	30	±20	5	25	TO-220NIS	89	—	99	—	2.5	
	2SK3846	40	±20	26	25	TO-220NIS	16	—	28	—	40	U-MOSⅢ
	2SK3847	40	±20	32	30	TO-220SM	16	—	28	—	40	
	TK70J04J3	40	±20	70	150	TO-3P(N)	3.8	—	8.3	—	210	
	TK70X04K3 ☆	40	±20	70	80	TFP	5.6	—	—	—	62	U-MOSⅣ
	TK70X04K3Z	40	±20	70	80	TFP	5.6	—	—	—	62	
	2SK3843	40	±20	75	125	TFP	3.5	—	8.0	—	210	U-MOSⅢ
	TK80X04K3 ☆	40	±20	80	125	TFP	3.5	—	—	—	100	
	TK100F04K3 ☆	40	±20	100	200	TO-220SM(W)	3.0	—	—	—	102	
	TK100F04K3L	40	±20	100	200	TO-220SM(W)	3.0	4.5	—	—	105	U-MOSⅣ
	TK150F04K3 ☆	40	±20	150	300	TO-220SM(W)	2.1	—	—	—	166	
	TK150F04K3L	40	±20	150	300	TO-220SM(W)	2.1	3.2	—	—	190	
	2SK4017	60	±20	5	20	New PW-Mold2	100	—	—	150	15	
	2SK4033	60	±20	5	20	New PW-Mold	100	—	—	150	15	
	TK30A06J3A	60	±20	30	25	TO-220SIS	26	—	35	—	36	U-MOSⅢ
	2SK3662	60	±20	35	35	TO-220NIS	12.5	—	—	19	91	
	2SK3844	60	±20	45	45	TO-220NIS	5.8	—	—	—	196	
	TK70X06K3 ☆	60	±20	70	80	TFP	8.0	—	—	—	62	U-MOSⅣ
	2SK3845	60	±20	70	125	TO-3P(N)	5.8	—	—	—	196	
	2SK3842	60	±20	75	125	TFP	5.8	—	—	—	196	U-MOSⅢ
	2SK4034	60	±20	75	125	TFP	5.8	—	10	—	196	
	2SK3940	75	±20	70	150	TO-3P(N)	7.0	—	—	—	200	U-MOSⅢ
LCD backlight inverter	**TK25A10K3** ☆	100	±20	25	25	TO-220SIS	40	—	—	—	34	U-MOSⅣ
	TK40X10J1	100	±20	40	125	TFP	20	—	—	—	59	U-MOSⅢ
	TK50F15J1	150	±20	50	300	TO-220SM(W)	30	—	—	—	75	

☆: No protection Zener diode between gate and source

5-3 U-MOS Series for Synchronous Rectification (V_{DSS} = 60 V to 150 V)

■ Features

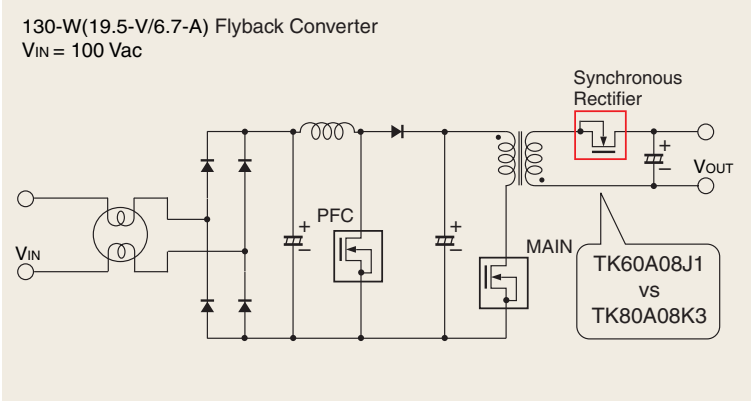
- Low ON-resistance achieved by high density through the use of submicron technology
- Guaranteed avalanche capability
- High power dissipation achieved by having the series housed in the TO-220(W) package with an exposed heatsink on the bottom of the package

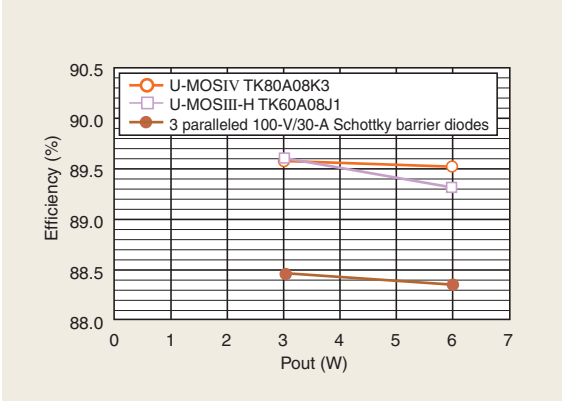
■ Comparisons Between Synchronous Rectification MOSFETs

			TK80A08K3			TK60A08J1			
Characteristic	Symbol	Test Conditions	Min	Typ.	Max	Min	Typ.	Max	Unit
Gate leakage current	+I_{GSS}	V_{GS} condition*, V_{DS} = 0 V	—	—	1	—	—	10	μA
	-I_{GSS}	V_{GS} condition*, V_{DS} = 0 V	—	—	−1	—	—	−10	μA
Drain cut-off current	I_{DSS}	V_{DS} = 75 V, V_{GS} = 0 V	—	—	10	—	—	10	μA
Drain-source breakdown voltage	$V_{(BR)\ DSS}$	I_D = 10 mA, V_{GS} = 0 V	75	—	—	75	—	—	V
	$V_{(BR)\ DSX}$	I_D = 10 mA, V_{GS} = −20 V	50	—	—	60	—	—	V
Gate threshold voltage	V_{th}	V_{DS} = 10 V, I_D = 1 mA	2.0	—	4.0	1.1	—	2.3	V
Drain-source ON-resistance	$R_{DS\ (ON)}$	V_{GS} = 10 V, I_D = 40 A	—	3.6	4.5	—	6.2	7.8	mΩ
Input capacitance	Ciss	V_{DS} = 10 V, V_{GS} = 0 V f = 1 MHz	—	8200	—	—	5450	—	pF
Reverse transfer capacitance	Crss		—	770	—	—	320	—	pF
Forward voltage	V_{DSF}	I_{DR} = 80 A, V_{GS} = 0 V	—	−0.9	−1.2	—	−0.9	−1.2	V

*: Test conditions: TK80A08K3: V_{GS} = ± 20 V, TK60A08J1: V_{GS} = ±16 V

■ Efficiency Test Circuit





Efficiency approx. 1% higher than Schottky barrier diodes

■ Product Offerings

Part Number	Absolute Maximum Ratings				$R_{DS(ON)}$ (mΩ) @ V_{GS} = 10 V		Q_g (nC) Typ.	Q_{sw} (nC) Typ.	Package	Series
	V_{DSS} (V)	V_{GSS} (V)	I_D (A)	P_D (W)	Typ.	Max	V_{DS} = V_{DSS} x 0.8, I_D = $I_{D\ (DC)}$			
TK70D06J1	60	±20	70	140	5.1	6.4	87	30	TO-220(W)	U-MOSIII-H
TK70A06J1	60	±20	70	45	5.1	6.4	87	30	TO-220SIS	U-MOSIII-H
TK60D08J1	75	±20	60	140	6.2	7.8	86	27	TO-220(W)	U-MOSIII-H
TK60A08J1	75	±20	60	45	6.2	7.8	86	27	TO-220SIS	U-MOSIII-H
TK40A08K3	75	±20	40	42	7.0	9.0	80	—	TO-220SIS	U-MOSIV
TK80D08K3	75	±20	80	100	3.6	4.5	175	80	TO-220(W)	U-MOSIV
TK80A08K3	75	±20	80	40	3.6	4.5	175	80	TO-220SIS	U-MOSIV
TK40A10K3	100	±20	40	40	11.5	15	85	40	TO-220SIS	U-MOSIV
TK40D10J1	100	±20	40	100	11.5	15	76	25	TO-220(W)	U-MOSIII-H
TK40A10J1	100	±20	40	40	11.5	15	76	25	TO-220SIS	U-MOSIII-H
TK40X10J1	100	±20	40	125	15	20	59	25	TFP	U-MOSIII-H
TK55D10J1	100	±20	55	140	8.4	10.5	110	33	TO-220(W)	U-MOSIII-H
TK55A10J1	100	±20	55	45	8.4	10.5	110	33	TO-220SIS	U-MOSIII-H
TK50X15J1	150	±20	50	125	22	30	75	33	TFP	U-MOSIII-H

6-1 π-MOSVII Series (V_{DSS} = 450 V to 650 V)

The latest addition to the π-MOS portfolio, the π-MOSVII Series offers reduced capacitances due to optimized chip design and is available with a greatly wider range of electrical characteristics.

■ Features

- 40% reduction in Q_g from π-MOSVI due to optimized chip design
- Available in 50-V steps of V_{DSS} and in finer steps of $R_{DS(ON)}$.
- Rated avalanche and reverse recovery current capabilities

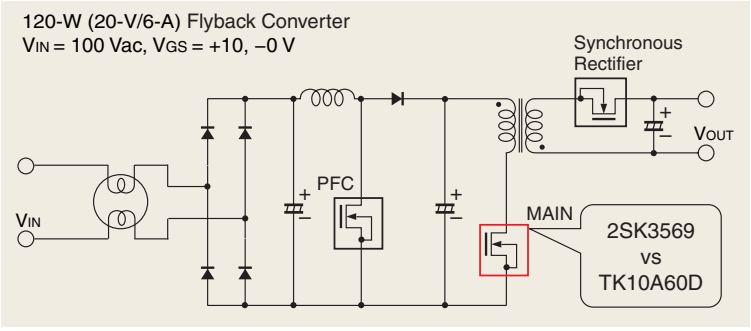
■ Performance Comparisons Between π-MOSVII and π-MOSVI Devices (600 V/10 A)

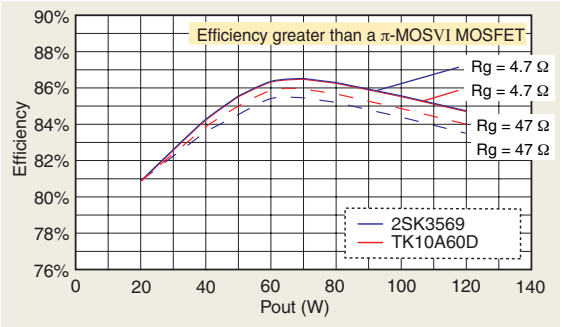
Series	π-MOSVII			π-MOSVI			
Part Number	TK10A60D			2SK3569			
Ratings	600 V/10 A			600 V/10 A			
Package	TO-220SIS			TO-220SIS			

Characteristic	Symbol	Test Conditions	Min	Typ.	Max	Min	Typ.	Max	Unit
Gate leakage current	± I_{GSS}	V_{GS} condition*, V_{DS} = 0 V	—	—	± 1	—	—	± 10	μA
Drain cut-off current	I_{DSS}	V_{DS} = 600 V, V_{GS} = 0 V	—	—	100	—	—	100	μA
Drain-source breakdown voltage	$V_{(BR)DSS}$	I_D = +10 mA, V_{GS} = 0 V	600	—	—	600	—	—	V
Gate threshold voltage	V_{th}	V_{DS} = 10 V, I_D = 1 mA	2.0	—	4.0	2.0		4.0	V
Drain-source ON-resistance	$R_{DS(ON)}$	V_{GS} = 10 V, I_D = 5 A	—	—	0.75	—	—	0.75	Ω
Total gate charge	Q_g	V_{DD} = 400 V, V_{GS} = 10 V, I_D = 10 A	—	25	—	—	42	—	nC
Diode forward voltage	V_{DSF}	I_{DR} =10 A, V_{GS} = 0 V	—	—	–1.7	—	—	–1.7	V

*: Test conditions: TK10A60D: V_{GS} = ± 30 V, 2SK3569: V_{GS} = ± 25 V

■ Efficiency Test Circuit





■ Product Offerings

Part Number	Absolute Maximum Ratings		$R_{DS(ON)}$ (Ω)	Equivalent π-MOSVI Part	Package
	V_{DSS} (V)	I_D (A)	V_{GS} = 10 V		
TK13A45D	450	13	0.46	2SK3743	TO-220SIS
TK4A50D	500	4	2.0	—	TO-220SIS
TK5A50D		5	1.5	2SK3563	TO-220SIS
TK6A50D		6	1.4	—	TO-220SIS
TK7A50D		7	1.2	—	TO-220SIS
TK8A50DA		7.5	1.0	—	TO-220SIS
TK8A50D		8	0.85	2SK3561	TO-220SIS
TK10A50D		10	0.72	—	TO-220SIS
TK11A50D		11	0.6	—	TO-220SIS
TK12A50D		12	0.52	2SK3568	TO-220SIS
TK13A50DA		12.5	0.47	—	TO-220SIS
TK13A50D		13	0.4	2SK4012	TO-220SIS
TK15J50D		15	0.4	2SK4107	TO-3P(N)
TK15A50D		15	0.3	2SK3934	TO-220SIS
TK18A50D		18	0.27	—	TO-220SIS
TK20J50D		20	0.27	2SK4108	TO-3P(N)
TK4A53D	525	4	1.7	—	TO-220SIS
TK5A53D		5	1.5	2SK3563	TO-220SIS
TK6A53D		6	1.3	—	TO-220SIS
TK6P53D		6	1.3	—	D-PAK
TK12A53D		12	0.58	—	TO-220SIS
TK12X53D		12	0.58	2SK3398	TFP
TK4A55DA	550	3.5	2.45	—	TO-220SIS
TK4A55D		4	1.9	—	TO-220SIS
TK5A55D		5	1.7	—	TO-220SIS
TK6A55DA		5.5	1.48	—	TO-220SIS

Part Number	Absolute Maximum Ratings		$R_{DS(ON)}$ (Ω)	Equivalent π-MOSVI Part	Package
	V_{DSS} (V)	I_D (A)	V_{GS} = 10 V		
TK8A55DA	550	7.5	1.07	—	TO-220SIS
TK9A55DA		8.5	0.86	—	TO-220SIS
TK11A55D		11	0.63	—	TO-220SIS
TK12A55D		12	0.57	—	TO-220SIS
TK12J55D		12	0.57	—	TO-3P(N)
TK13A55DA		12.5	0.48	—	TO-220SIS
TK14A55D		14	0.37	—	TO-220SIS
TK16A55D ✻		16	0.33	—	TO-220SIS
TK16J55D		16	0.37	—	TO-3P(N)
TK2Q60D	600	2	5.0	2SK4002	New PW-Mold 2
TK3A60DA		2.5	2.8	—	TO-220SIS
TK4A60DA		3.5	2.2	2SK3567	TO-220SIS
TK4A60DB		3.7	2	—	TO-220SIS
TK4A60D		4	1.7	—	TO-220SIS
TK6A60D		6	1.25	2SK3562	TO-220SIS
TK8A60DA		7.5	1	2SK3667	TO-220SIS
TK10A60D		10	0.75	2SK3569	TO-220SIS
TK11A60D		11	0.65	—	TO-220SIS
TK12A60D		12	0.55	—	TO-220SIS
TK13A60D		13	0.43	2SK3797	TO-220SIS
TK15A60D		15	0.37	—	TO-220SIS
TK5A65D	650	5	1.43	—	TO-220SIS
TK6A65D		6	1.11	—	TO-220SIS
TK8A65D		8	0.84	—	TO-220SIS
TK12A65D ✻		12	0.50	—	TO-220SIS

✻: Under development

6-2 Super-Junction DTMOS Series (V_{DSS} = 600 V, 650 V)

The DTMOS devices employ a new super-junction structure that enables an ultra-low ON-resistance with the maximum V_{DSS} rating of 600 V. The DTMOS Series helps reduce the power consumption and size of electronic equipment.

■ Features

- Low ON-resistance TK40J60T: 80 mΩ (max) @V_{GS} = 10 V, I_D = 20 A
- Low gate charge TK20A60U: Q_g = 27 nC typ., 600 V / 20 A
- The rugged internal drain-source diode is not damaged at di/dt = 500 A/μs (@V_{DS} = 400 V, 150˚C).

■ Product Offerings

Part Number	Absolute Maximum Ratings		$R_{DS(ON)}$ Max (Ω)	Q_g Typ. (nC)	C_{iss} Typ. (pF)	Package	Series
	V_{DSS} (V)	I_D (A)	V_{GS} = 10 V				
TK12A60U	600	12	0.4	14	720	TO-220SIS	DTMOSII
TK12D60U						TO-220(W)	
TK12J60U						TO-3P(N)	
TK15J60T		15	0.3	21	1200	TO-3P(N)	DTMOSI
TK15A60U		15	0.3	17	950	TO-220SIS	DTMOSII
TK15D60U						TO-220(W)	
TK15J60U						TO-3P(N)	
TK20A60T		20	0.19	30	1580	TO-220SIS	DTMOSI
TK20D60T						TO-220(W)	
TK20J60T						TO-3P(N)	
TK20A60U		20	0.19	27	1470	TO-220SIS	DTMOSII
TK20D60U						TO-220(W)	
TK20J60U						TO-3P(N)	
TK40J60T		40	0.08	67	3900	TO-3P(N)	DTMOSI
TK50J60U ✻		50	0.065	70	4300	TO-3P(N)	DTMOSII
TK13A65U	650	13	0.38	17	950	TO-220SIS	DTMOSII

✻: Under development

■ Performance Comparisons Between the New DTMOS and Conventional MOSFET (π-MOSVI) Devices (600 V/20 A)

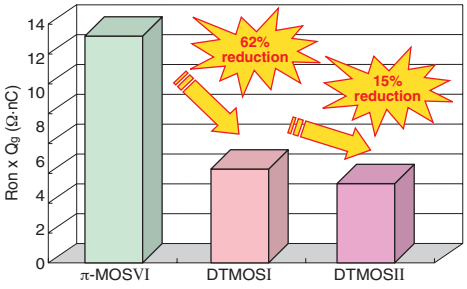
		Series	DTMOSII			π-MOSVI			
		Part Number	TK20J60U			2SK3911			
		Ratings	600 V/20 A			600 V/20 A			
Characteristic	Symbol	Test Conditions	Min	Typ.	Max	Min	Typ.	Max	Unit
Gate leakage current	± I_{GSS}	V_{GS} condition*, V_{DS} = 0 V	—	—	± 1	—	—	± 10	μA
Drain cut-off current	I_{DSS}	V_{DS} = 600 V, V_{GS} = 0 V	—	—	100	—	—	100	μA
Drain-source breakdown voltage	$V_{(BR)DSS}$	I_D = 10 mA, V_{GS} = 0 V	600	—	—	600	—	—	V
Gate threshold voltage	V_{th}	V_{DS} = 10 V, I_D = 1 mA	3.0	—	5.0	2.0	—	4.0	V
Drain-source ON-resistance	$R_{DS(ON)}$	V_{GS} = 10 V, I_D = 10 A	—	0.165	0.19	—	0.22	0.32	Ω
Total gate charge	Q_g	V_{DD} = 400 V, V_{GS} = 10 V, I_D = 20 A	—	27	—	—	60	—	nC
Diode forward voltage	V_{DSF}	I_{DR} = 20 A, V_{GS} = 0 V	—	—	−1.7	—	—	−1.7	V

*: Test conditions: TK20J60U: V_{GS} = ± 30 V, 2SK3911: V_{GS} = ± 25 V

■ Figure-of-Merit (FOM) Comparison

Ron x Q_g, the product of ON-resistance and total gate charge, is reduced by 62%, compared with the conventional MOSFETs with the same chip size.

*Ron x Q_g is a figure-of-merit index for the switching speed of MOSFETs.

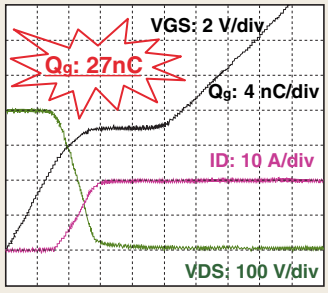


■ Performance Characteristics of the New DTMOS Series

TK20A60U Electrical Characteristics

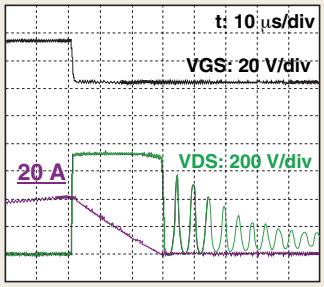
Qg

V_{DD}: 400 V, I_D = 20 A, 25˚C



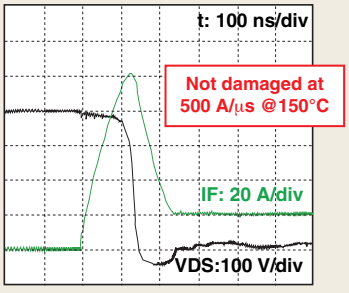
Avalanche Breakdown

V_{DD} = 90 V, L = 1 mH
V_{GS} = ±15 V, Rg = 25 Ω, 25˚C



Internal Diode Reverse Recovery

V_{DD} = 400 V, di/dt = 500 A/μs
I_{DR} = 20 A, V_{GS} = 0 V, 150˚C



6-3 High-speed π-MOS Series (V_{DSS} = 450 V to 600 V)

To support the development of high-efficiency equipment, Toshiba has developed two series of high-speed power MOSFETs: a high-speed switching series for AC adapters and switching power supplies; and a high-speed diode series for motor controllers and inverter circuits.

- MACH Series: Achieves a higher switching speed than the existing π-MOS Series, which is currently well established in the market.
- High-Speed Diode Series: Achieves a higher internal diode speed by using lifetime control.

■ Product Offerings

- MACH Series

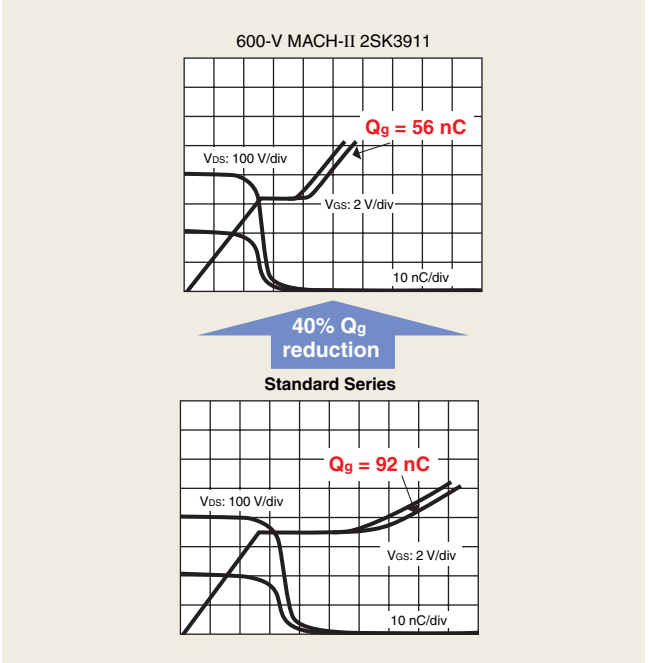
Applications	Part Number	Absolute Maximum Ratings			Package	$R_{DS(ON)}$ Max (Ω)	V_{GS} (V)	I_D (A)	Qg Typ. (nC)	Standard Type	Series
		V_{DSS} (V)	I_D (A)	P_D (W)							
AC adapters Switching power supplies	**2SK3310**	450	10	40	TO-220NIS	0.65	10	5	23	2SK3126	MACH-I
	2SK3309	450	10	65	TO-220FL/SM	0.65	10	5	23	—	
	2SK3743	450	13	40	TO-220NIS	0.4	10	6	34	—	
	2SK3403	450	13	100	TO-220FL/SM	0.4	10	6	34	—	
	2SK3312	600	6	65	TO-220FL/SM	1.25	10	3	25	2SK2777	
	2SK3437	600	10	80	TO-220FL/SM	1	10	5	28	2SK2996	
	2SK3399	600	10	100	TO-220FL/SM	0.75	10	5	35	2SK2866	
	2SK3907	500	23	150	TO-3P(N)	0.23	10	11.5	60	—	MACH-II
	2SK3911	600	20	150	TO-3P(N)	0.32	10	10	60	—	

- High-Speed Diode Series (HSD Series)

Applications	Part Number	Absolute Maximum Ratings			Package	$R_{DS(ON)}$ Max (Ω)	V_{GS} (V)	I_D (A)	trr Typ. (ns)	Standard Type
		V_{DSS} (V)	I_D (A)	P_D (W)						
Motor control Inverters Switching power supplies	**2SK3868**	500	5	35	TO-220SIS	1.7	10	2.5	150	2SK3563
	2SK3417	500	5	50	TO-220FL/SM	1.8	10	2.5	60	2SK2991
	2SK4042	500	8	40	TO-220SIS	0.97	10	4	185	2SK3561
	2SK3313	500	12	40	TO-220NIS	0.62	10	6	90	2SK2842
	2SK3314	500	15	150	TO-3P(N)	0.49	10	7	105	2SK2698
	2SK3131	500	50	250	TO-3P(L)	0.11	10	25	105	2SK3132
	2SK3936	500	23	150	TO-3P(N)	0.25	10	11.5	380	2SK3907
	2SK3947	600	6	40	TO-220SIS	1.4	10	3	150	2SK3562
	2SK4015	600	10	45	TO-220SIS	0.86	10	5	170	2SK3569
	2SK4016	600	13	50	TO-220SIS	0.50	10	6.5	160	2SK3911
	2SK3906	600	20	150	TO-3P(N)	0.33	10	10	400	2SK3797

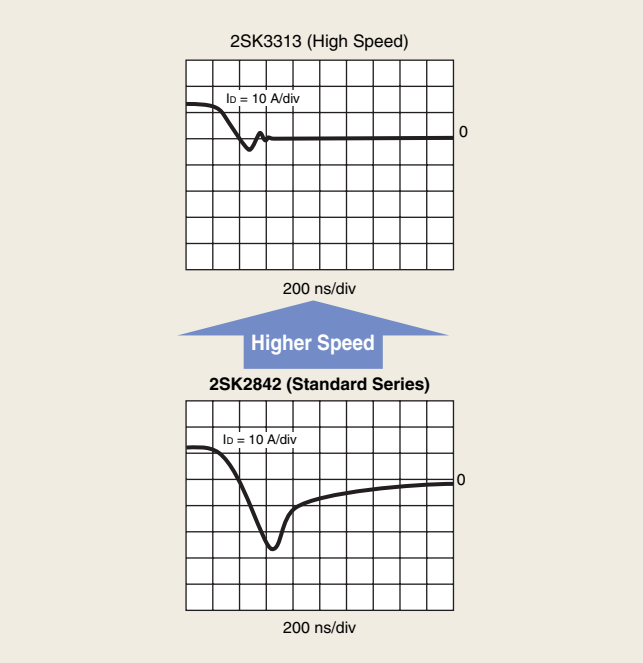
■ Characteristics of the MACHII Series

40% reduction in Q_g losses



■ Characteristics of the High-Speed Diode Series

Faster internal diode



6-4 π-MOS Series

■ π-MOSVI Series (V_{DSS} = 450 V to 600 V)

Series	Part Number	Absolute Maximum Ratings		$R_{DS(ON)}$ Max (Ω)	Q_g Typ. (nC)	C_{iss} Typ. (pF)	Equivalent Predecessor Part	Package
		V_{DSS} (V)	I_D (A)	V_{GS} = 10 V				
π-MOSVI	**2SK3757**	450	2	2.45	9	330	2SK3543	TO-220SIS
	2SK3766		2	2.45	8	270	2SK3543	TO-220SIS
	2SK3869		10	0.68	28	1050	2SK3407	TO-220SIS
	2SK3935		17	0.25	62	3100	—	TO-220SIS
	2SK3904		19	0.26	62	3100	—	TO-3P(N)
	2SK3563	500	5	1.5	16	550	2SK2662	TO-220SIS
	2SK3863		5	1.5	16	550	—	DP
	2SK4103		5	1.5	16	550	2SK3863	New Pw-Mold
	2SK3561		8	0.85	28	1050	2SK2543	TO-220SIS
	2SK3568		12	0.52	42	1500	2SK2842	TO-220SIS
	2SK4012		13	0.4	50	2400	—	TO-220SIS
	2SK3934		15	0.3	62	3100	—	TO-220SIS
	2SK4107		15	0.4	48	2450	2SK2698	TO-3P(N)
	2SK3905		17	0.31	62	3100	—	TO-3P(N)
	2SK4108		20	0.27	70	3400	2SK2837	TO-3P(N)
	2SK3767	600	2	4.5	9	320	2SK3067	TO-220SIS
	2SK3567		3.5	2.2	17	550	2SK2750	TO-220SIS
	2SK3562		6	1.25	28	1050	2SK2545	TO-220SIS
	2SK3667		7.5	1.0	33	1300	2SK2996	TO-220SIS
	2SK3569		10	0.75	42	1500	2SK2843	TO-220SIS
	2SK3797		13	0.43	62	3150	—	TO-220SIS
	2SK3903		14	0.44	62	3100	—	TO-3P(N)

■ π-MOSIV Series (V_{DSS} = 800 V to 900 V)

Series	Part Number	Absolute Maximum Ratings		$R_{DS(ON)}$ Max (Ω)	Q_g Typ. (nC)	C_{iss} Typ. (pF)	Equivalent Predecessor Part	Package
		V_{DSS} (V)	I_D (A)	V_{GS} = 10 V				
π-MOSIV	**2SK3633**	800	7	1.7	35	1500	2SK2746	TO-3P(N)
	2SK3879		6.5	1.7	35	1500	—	TO-220FL/SM
	2SK3880		6.5	1.7	35	1500	—	TO-3P(N)IS
	2SK4013		6	1.7	45	1400	—	TO-220SIS
	2SK3566	900	2.5	6.4	12	470	2SK2718	TO-220SIS
	2SK3564		3	4.3	17	700	2SK2700	TO-220SIS
	2SK3798		4	3.5	26	800	—	TO-220SIS
	2SK3565		5	2.5	28	1150	2SK2717	TO-220SIS
	2SK3742		5	2.5	25	1150	2SK2717	TO-220SIS
	2SK3700		5	2.5	28	1150	2SK2610	TO-3P(N)
	2SK4014		6	2.0	45	1400	—	TO-220SIS
	2SK4115		7	2.0	45	1650	2SK2749	TO-3P(N)
	2SK3799		8	1.3	60	2200	—	TO-220SIS
	2SK3473		9	1.6	38	1450	—	TO-3P(N)
	2SK3878		9	1.3	60	2200	2SK2611	TO-3P(N)
	2SK4207		13	0.95	45	2790	—	TO-3P(N)

■ L^2-π-MOSV and VI Series (V_{DSS} = 30 V to 100 V)

Part Number	V_{DSS} (V)	I_D (A)	P_D (W)	Package	$R_{DS(ON)}$ (Ω)				$R_{DS(ON)}$ (Ω)				Qg Typ. (nC)
					Typ.	Max	V_{GS} (V)	I_D (A)	Typ.	Max	V_{GS} (V)	I_D (A)	
2SJ537	–50	–5	0.9	LSTM	0.16	0.19	–10	–2.5	0.27	0.34	–4	–1.3	18
2SJ360	–60	–1	0.5	PW-Mini	0.55	0.73	–10	–0.5	0.86	1.2	–4	–0.5	6.5
2SJ507	–60	–1	0.9	LSTM	0.5	0.7	–10	–0.5	0.72	1.0	–4	–0.5	5.6
2SJ438	–60	–5	25	TO-220NIS	0.16	0.19	–10	–2.5	0.24	0.28	–4	–2.5	22
2SJ378	–60	–5	1.2	TPS	0.16	0.19	–10	–2.5	0.24	0.28	–4	–2.5	22
2SJ349	–60	–20	45	TO-220NIS	0.033	0.045	–10	–10	0.05	0.09	–4	–10	90
2SJ401	–60	–20	100	TO-220FL/SM	0.033	0.045	–10	–10	0.05	0.09	–4	–10	90
2SJ334	–60	–30	45	TO-220NIS	0.029	0.038	–10	–15	0.046	0.06	–4	–15	110
2SJ402	–60	–30	100	TO-220FL/SM	0.029	0.038	–10	–15	0.046	0.06	–4	–15	110
2SJ508	–100	–1	1.5	PW-Mini	1.34	1.9	–10	–0.5	1.68	2.5	–4	–0.5	6.3
2SJ509	–100	–1	0.9	LSTM	1.34	1.9	–10	–0.5	1.68	2.5	–4	–0.5	6.3
2SJ380	–100	–12	35	TO-220NIS	0.15	0.21	–10	–6	0.25	0.32	–4	–6	48
2SJ412	–100	–16	60	TO-220FL/SM	0.15	0.21	–10	–6	0.25	0.32	–4	–6	48
2SJ619	–100	–16	75	TFP	0.15	0.21	–10	–6	0.25	0.32	–4	–6	48
2SJ620	–100	–18	25	TFP	0.063	0.09	–10	–9	0.085	0.12	–4	–9	140
2SJ464	–100	–18	45	TO-220NIS	0.064	0.09	–10	–9	0.085	0.12	–4	–9	140
2SK3506	30	45	100	TO-3P(N)	0.016	0.02	10	25	—	—	—	—	39
2SK2989	50	5	0.9	LSTM	0.12	0.15	10	2.5	0.24	0.33	4	1.3	6.5
2SK2614	50	20	40	DP	0.032	0.046	10	10	0.055	0.08	4	5	25
2SK2507	50	25	30	TO-220NIS	0.034	0.046	10	12	0.058	0.08	4	6	25
2SK2886	50	45	40	TO-220NIS	0.014	0.02	10	25	0.027	0.036	4	25	66
2SK3051	50	45	40	TO-220FL/SM	0.024	0.03	10	25	—	—	—	—	36
2SK2744	50	45	125	TO-3P(N)	0.015	0.02	10	25	—	—	—	—	68
2SK2550	50	45	100	TO-3P(N)	0.024	0.030	10	25	—	—	—	—	36
2SK2551	50	50	150	TO-3P(N)	0.0072	0.011	10	25	—	—	—	—	130
2SK2745	50	50	150	TO-3P(N)	0.007	0.0095	10	25	0.011	0.016	4	25	130

Part Number	V_{DSS} (V)	I_D (A)	P_D (W)	Package	$R_{DS(ON)}$ (Ω)				$R_{DS(ON)}$ (Ω)				Qg Typ. (nC)
					Typ.	Max	V_{GS} (V)	I_D (A)	Typ.	Max	V_{GS} (V)	I_D (A)	
2SK2615	60	2	0.5	PW-Mini	0.23	0.3	10	1	0.33	0.44	4	1	6
2SK2961	60	2	0.9	LSTM	0.2	0.27	10	1	0.26	0.38	4	1	5.8
2SK2229	60	5	1.2	TPS	0.12	0.16	10	2.5	0.2	0.3	4	1.3	12
2SK2782	60	20	40	DP	0.039	0.055	10	10	0.06	0.090	4	5	25
2SK2232	60	25	35	TO-220NIS	0.036	0.046	10	12	0.057	0.08	4	12	38
2SK2311	60	25	40	TO-220FL/SM	0.036	0.046	10	12	0.057	0.08	4	12	38
2SK2385	60	36	40	TO-220NIS	0.022	0.03	10	18	0.04	0.055	4	15	60
2SK2233	60	45	100	TO-3P(N)	0.022	0.03	10	25	0.04	0.055	4	15	60
2SK2266	60	45	65	TO-220FL/SM	0.022	0.03	10	25	0.04	0.055	4	15	60
2SK2376	60	45	100	TO-220FL/SM	0.013	0.017	10	25	0.019	0.025	4	25	110
2SK2398	60	45	100	TO-3P(N)	0.022	0.03	10	25	—	—	—	—	60
2SK2173	60	50	125	TO-3P(N)	0.013	0.017	10	25	0.019	0.025	4	25	110
2SK2445	60	50	125	TO-3P(N)	0.014	0.018	10	25	—	—	—	—	110
2SK2267	60	60	150	TO-3P(L)	0.008	0.011	10	30	0.012	0.015	4	30	170
2SK2313	60	60	150	TO-3P(N)	0.008	0.011	10	30	0.012	0.015	4	30	170
2SK2962	100	1	0.9	LSTM	0.5	0.7	10	0.5	0.65	0.95	4	0.5	6.3
2SK2963	100	1	0.5	PW-Mini	0.5	0.7	10	0.5	0.65	0.95	4	0.5	6.3
2SK2200	100	3	1.3	TPS	0.28	0.35	10	2	0.36	0.45	4	2	13.5
2SK2201	100	3	20	New PW-Mold	0.28	0.35	10	2	0.36	0.45	4	2	13.5
2SK4018	100	3	20	New PW-Mold2	0.28	0.35	10	2	0.35	0.45	4	2	13.5
2SK2399	100	5	20	New PW-Mold	0.17	0.23	10	2.5	0.22	0.3	4	2.5	22
2SK2400	100	5	1.2	TPS	0.17	0.23	10	2.5	0.22	0.3	4	2.5	22
2SK4019	100	5	20	New PW-Mold2	0.17	0.23	10	2.5	0.22	0.3	4	2.5	22
2SK2391	100	20	35	TO-220NIS	0.068	0.085	10	10	0.09	0.13	4	10	50
2SK2314	100	27	75	TO-220AB	0.066	0.085	10	15	0.09	0.13	4	15	50
2SK2789	100	27	60	TO-220FL/SM	0.066	0.085	10	15	0.09	0.13	4	15	50
2SK3387	150	18	100	TFP	0.08	0.12	10	9	0.09	0.18	4	9	57

■ π-MOSV Series (V_{DSS} = 150 V to 250 V)

Applications	Part Number	Absolute Maximum Ratings			Package	$R_{DS(ON)}$ (Ω)		V_{GS} (V)	I_D (A)	Qg Typ. (nC)
		V_{DSS} (V)	I_D (A)	P_D (W)		Typ.	Max			
DC-DC converters Monitors Motor controllers	**2SJ618**	–180	–10	130	TO-3P(N)	–	0.37	–10	–5	18
	2SJ407	–200	–5	30	TO-220NIS	0.8	1.0	–10	–2.5	20
	2SJ567	–200	–2.5	20	New PW-Mold	1.6	2.0	–10	–1.5	10
	2SJ676	–200	–2.5	1.3	TPS	1.6	2.0	–10	–1.5	10
	2SJ680	–200	–2.5	20	New PW-Mold2	1.6	2.0	–10	–1.5	10
	2SJ610	–250	–2	20	PW-Mold	1.85	2.55	–10	–1.0	24
	2SJ512	–250	–5	30	TO-220NIS	1.0	1.25	–10	–2.5	22
	2SJ516	–250	–6.5	35	TO-220NIS	0.6	0.8	–10	–3	29
	2SK3670	150	0.67	0.9	LSTM	1.0	1.7	4	0.5	4.6
	2SK3205	150	5	20	PW-Mold	0.36	0.5	10	2.5	12
	2SK2882	150	18	45	TO-220NIS	0.08	0.12	10	9	57
	2SK3497	180	10	130	TO-3P(N)	—	0.15	10	5	—
	2SK2992	200	1	1.5	PW-Mini	2.2	3.5	10	0.5	3
	2SK2835	200	5	1.3	TPS	0.56	0.8	10	2.5	10
	2SK2381	200	5	25	TO-220NIS	0.56	0.8	10	2.5	10
	2SK2920	200	5	20	New PW-Mold	0.56	0.8	10	2.5	10
	2SK4020	200	5	20	New PW-Mold2	0.52	0.8	10	2.5	10
	2SK2350	200	8.5	30	TO-220NIS	0.26	0.4	10	5	17
	2SK2965	200	11	35	TO-220NIS	0.15	0.26	10	5.5	30
	2SK2382	200	15	45	TO-220NIS	0.13	0.18	10	10	40
	2SK2401	200	15	75	TO-220FL/SM	0.13	0.18	10	10	40
	2SK3625	200	25	100	TO-220FL/SM	0.065	0.082	10	12.5	44
	2SK3444	200	25	125	TFP	0.067	0.082	10	12.5	44
	2SK3176	250	30	150	TO-3P(N)	0.038	0.052	10	15	125
	2SK3462	250	3	20	New PW-Mold	1.2	1.7	10	1.5	12
	2SK4022	250	3	20	New PW-Mold2	1.2	1.7	10	1.5	12
	2SK3342	250	4.5	20	New PW-Mold	0.8	1.0	10	2.5	10
	2SK4021	250	4.5	20	New PW-Mold2	0.8	1.0	10	2.5	10
	2SK2417	250	7.5	30	TO-220NIS	0.42	0.5	10	3.5	20
	2SK2914	250	7.5	20	TO-220AB	0.42	0.5	10	3.5	20
	2SK2508	250	13	45	TO-220NIS	0.18	0.25	10	6.5	40
	2SK2598	250	13	60	TO-220FL/SM	0.18	0.25	10	6.5	40
	2SK2993	250	20	100	TO-220FL/SM	0.082	0.105	10	10	100
	2SK3994	250	20	45	TO-220NIS	0.090	0.105	10	10	45
	2SK3388	250	20	125	TFP	0.082	0.105	10	10	100
	2SK3445	250	20	125	TFP	0.09	0.105	10	10	45
	2SK2967	250	30	150	TO-3P(N)	0.048	0.068	10	15	132
	2SK2995	250	30	90	TO-3P(N)IS	0.048	0.068	10	15	132

■ π-MOSV Series (V_{DSS} = 400 V to 700 V)

Applications	Part Number	Absolute Maximum Ratings			Package	$R_{DS(ON)}$ (Ω)		V_{GS}	I_D	Qg Typ. (nC)
		V_{DSS} (V)	I_D (A)	P_D (W)		Typ.	Max	(V)	(A)	
115-Vac switching power supplies Ballast inverters Motor controllers	**2SK3498**	400	1	20	PW-Mold	4.2	5.5	10	0.5	5.7
	2SK2838	400	5.5	40	TO-220FL/SM	0.84	1.2	10	3	17
	2SK2679	400	5.5	35	TO-220NIS	0.84	1.2	10	3	17
	2SK2952	400	8.5	40	TO-220NIS	0.4	0.55	10	5	34
	2SK2841	400	10	80	TO-220AB	0.4	0.55	10	5	34
	2SK2949	400	10	80	TO-220FL/SM	0.4	0.55	10	5	34
	2SK3499	400	10	80	TFP	0.4	0.55	10	5	34
	2SK3472	450	1	20	New PW-Mold	4.0	4.6	10	0.5	5
	2SK3374	450	1	20	TPS	3.7	4.6	10	5	5
	2SK4023	450	1	20	New PW-Mold2	4.0	4.6	10	0.5	5
	2SK3544	450	13	100	TFP	0.29	0.4	10	6	34
	2SK2998	500	0.5	0.9	LSTM	10	18	10	0.25	3.8
	2SK3302	500	0.5	1.3	TPS	10	18	10	0.25	3.8
	2SK3471	500	0.5	0.5	PW-Mini	10	18	10	0.25	3.8
	2SK2599	500	2	1.3	TPS	2.9	3.2	10	1	9
	2SK3373	500	2	20	New PW-Mold	2.9	3.2	10	1	9
	2SK2862	500	3	25	TO-220NIS	2.9	3.2	10	1	9
	2SK2991	500	5	50	TO-220FL/SM	1.35	1.5	10	2.5	17
	2SK3466	500	5	50	TO-220FL/SM	1.35	1.5	10	2.5	17
	2SK2542	500	8	80	TO-220AB	0.75	0.85	10	4	30
	2SK2776	500	8	65	TO-220FL/SM	0.75	0.85	10	4	30
	2SK3538	500	8	65	TFP	0.75	0.85	10	4	30
	2SK2601	500	10	125	TO-3P(N)	0.56	1.0	10	5	30
	2SK3068	500	12	100	TO-220FL/SM	0.4	0.52	10	6	45
	2SK3398	500	12	100	TFP	0.4	0.52	10	6	45
	2SK2916	500	14	80	TO-3P(N)IS	0.35	0.4	10	7	58
	2SK2917	500	18	90	TO-3P(N)IS	0.21	0.27	10	10	80
	2SK3132	500	50	250	TO-3P(L)	0.07	0.095	10	25	280
	2SK3371	600	1	20	New PW-Mold	6.4	9.0	10	0.5	9
	2SK4026	600	1	20	New PW-Mold2	6.4	9	10	0.5	9
	2SK2846	600	2	1.3	TPS	4.2	5.0	10	1	9
	2SK2865	600	2	20	New PW-Mold	4.2	5.0	10	1	9
	2SK4002	600	2	20	New PW-Mold2	4.2	5	10	1	9
	2SK4003	600	3	20	New PW-Mold2	1.7	2.2	10	1.5	20
	2SK3975	600	3	20	New PW-Mold	1.7	2.2	10	1.5	20
	2SK3085	600	3.5	75	TO-220AB	1.7	2.2	10	1.8	20
	2SK3130	600	6	40	TO-220NIS	1.26	1.55	10	3	30
	2SK2777	600	6	65	TO-220FL/SM	0.9	1.25	10	3	30
	2SK2602	600	6	125	TO-3P(N)	0.9	1.25	10	3	30
	2SK3312	600	6	65	TO-220FL/SM	0.95	1.25	10	3	22
	2SK3438	600	10	80	TFP	0.78	1.0	10	5	28
	2SK2889	600	10	100	TO-220FL/SM	0.54	0.75	10	5	45
	2SK2866	600	10	125	TO-220AB	0.54	0.75	10	5	45
	2SK2699	600	10	150	TO-3P(N)	0.5	0.65	10	6	58
	2SK2953	600	12	90	TO-3P(N)IS	0.31	0.4	10	8	80
	2SK3265	700	10	45	TO-220NIS	0.72	1.0	10	5	53
	2SK3453	700	10	80	TO-3P(N)IS	0.72	1.0	10	5	53

■ π-MOSIII Series (V_{DSS} = 800 V to 1000 V)

Applications	Absolute Maximum Ratings			Package	$R_{DS(ON)}$ (Ω)				Qg Typ. (nC)
	V_{DSS} (V)	I_D (A)	P_D (W)		Typ.	Max	V_{GS}(V)	I_D(A)	
2SK2603	800	3	100	TO-220AB	3.0	3.6	10	1.5	25
2SK2883	800	3	75	TO-220FL/SM	3.0	3.6	10	15	25
2SK2884	800	5	100	TO-220FL/SM	1.9	2.2	10	3.0	34
2SK2746	800	7	150	TO-3P(N)	1.3	1.7	10	3.5	55
2SK2606	800	8	85	TO-3P(N)IS	1.0	1.2	10	4.0	68
2SK2607	800	9	150	TO-3P(N)	1.0	1.2	10	4.0	68
2SK3301	900	1	20	PW-Mold	15	20	10	0.5	6
2SK2845	900	1	40	DP	8.0	9.0	10	0.5	15
2SK2733	900	1	60	TO-220AB	8.0	9.0	10	0.5	15
2SK2608	900	3	100	TO-220AB	3.73	4.3	10	1.5	25
2SK2719	900	3	125	TO-3P(N)	3.7	4.3	10	1.5	25
2SK2847	900	8	85	TO-3P(N)IS	1.05	1.25	10	4.0	58
2SK3017	900	8.5	90	TO-3P(N)IS	1.2	1.4	10	4.0	70
2SK2968	900	10	150	TO-3P(N)	1.05	1.25	10	4	70
2SK2613	1000	8	150	TO-3P(N)	1.4	1.7	10	8.0	65

7-1 Alphanumeric Index of Part Numbers

Part Number	Series	Package	Main Characteristics			Page
			V_{DSS} (V)	I_D (A)	$R_{DS(ON)}$ Max (Ω)	
2SJ168	π-MOSIII	S-MINI	–60	–0.2	2	36
2SJ200	π-MOSII	TO-3P (N)	–180	–10	0.83	–
2SJ201	π-MOSII	TO-3P (L)	–200	–12	0.63	–
2SJ304	L²-π-MOSIV	TO-220NIS	–60	–14	0.12	–
2SJ305	π-MOSIII	S-MINI	–30	–0.2	4	36
2SJ312	L²-π-MOSIV	TO-220FL/SM	–60	–14	0.12	–
2SJ313	π-MOSII	TO-220NIS	–180	–1	5	–
2SJ334	L²-π-MOSV	TO-220NIS	–60	–30	0.038	43
2SJ338	π-MOSII	PW-Mold	–180	–1	5	–
2SJ343	π-MOSIII	S-MINI	–50	–0.05	50	36
2SJ344	π-MOSIII	USM	–50	–0.05	50	36
2SJ349	L²-π-MOSV	TO-220NIS	–60	–20	0.045	43
2SJ360	L²-π-MOSV	PW-Mini	–60	–1	0.73	43
2SJ378	L²-π-MOSV	TPS	–60	–5	0.19	43
2SJ380	L²-π-MOSV	TO-220NIS	–100	–12	0.21	43
2SJ401	L²-π-MOSV	TO-220FL/SM	–60	–20	0.045	43
2SJ402	L²-π-MOSV	TO-220FL/SM	–60	–30	0.038	43
2SJ407	π-MOSV	TO-220NIS	–200	–5	1	44
2SJ412	L²-π-MOSV	TO-220FL/SM	–100	–16	0.21	43
2SJ438	L²-π-MOSV	TO-220NIS	–60	–5	0.19	43
2SJ440	π-MOSII	TO-3P (N)IS	–180	–9	0.8	–
2SJ464	L²-π-MOSV	TO-220NIS	–100	–18	0.09	43
2SJ507	L²-π-MOSV	LSTM	–60	–1	0.7	43
2SJ508	L²-π-MOSV	PW-Mini	–100	–1	1.9	43
2SJ509	L²-π-MOSV	LSTM	–100	–1	1.9	43
2SJ512	π-MOSV	TO-220NIS	–250	–5	1.25	44
2SJ516	π-MOSV	TO-220NIS	–250	–6.5	0.8	44
2SJ537	L²-π-MOSV	LSTM	–50	–5	0.19	43
2SJ567	π-MOSV	New PW-Mold	–200	–2.5	2	44
2SJ610	π-MOSV	PW-Mold	–250	–2	2.55	44
2SJ618	π-MOSV	TO-3P (N)	–180	–10	0.37	44
2SJ619	L²-π-MOSV	TFP	–100	–16	0.21	43
2SJ620	L²-π-MOSV	TFP	–100	–18	0.09	43
2SJ668	U-MOSIII	New PW-Mold	–60	–5	0.17	38
2SJ669	U-MOSIII	TPS	–60	–5	0.17	38
2SJ676	π-MOSV	TPS	–200	–2.5	2	44
2SJ680	π-MOSV	New PW-Mold2	–200	–2.5	2	44
2SJ681	U-MOSIII	New PW-Mold2	–60	–5	0.17	38
2SK1062	π-MOSIII	S-MINI	60	0.2	1	36
2SK1119	π-MOSII.5	TO-220AB	1000	4	3.8	–
2SK1359	π-MOSII.5	TO-3P (N)	100	5	3.8	–
2SK1365	π-MOSII.5	TO-3P (N)IS	1000	7	1.8	–
2SK1381	L²-π-MOSIII	TO-3P (N)	100	50	0.032	–
2SK1382	L²-π-MOSIII	TO-3P (L)	100	60	0.02	–
2SK1486	π-MOSIII.5	TO-3P (L)	300	32	0.095	–
2SK1489	π-MOSIII.5	TO-3P (L)	1000	12	1	–
2SK1529	π-MOSII	TO-3P (N)	180	10	0.83	–
2SK1530	π-MOSII	TO-3P (N)	200	12	0.63	–
2SK1544	π-MOSIII.5	TO-3P (L)	500	25	0.2	–
2SK1930	π-MOSII.5	TO-220FL/SM	1000	4	3.8	–
2SK2009	π-MOSIII	S-MINI	30	0.2	2	36
2SK2013	π-MOSII	TO-220NIS	180	1	5	–

Part Number	Series	Package	Main Characteristics			Page
			V_{DSS} (V)	I_D (A)	$R_{DS(ON)}$ Max (Ω)	
2SK2162	π-MOSII	PW-Mold	180	1	5	–
2SK2173	L²-π-MOSV	TO-3P (N)	60	50	0.017	44
2SK2200	L²-π-MOSV	TPS	100	3	0.35	44
2SK2201	L²-π-MOSV	New PW-Mold	100	3	0.35	44
2SK2229	L²-π-MOSV	TPS	60	5	0.16	44
2SK2232	L²-π-MOSV	TO-220NIS	60	25	0.046	44
2SK2233	L²-π-MOSV	TO-3P (N)	60	45	0.03	44
2SK2266	L²-π-MOSV	TO-220FL/SM	60	45	0.03	44
2SK2267	L²-π-MOSV	TO-3P (L)	60	60	0.011	44
2SK2274	π-MOSII.5	TO-220NIS	700	5	1.7	–
2SK2311	L²-π-MOSV	TO-220FL/SM	60	25	0.046	44
2SK2313	L²-π-MOSV	TO-3P (N)	60	60	0.011	44
2SK2314	L²-π-MOSV	TO-220AB	100	27	0.085	44
2SK2350	π-MOSV	TO-220NIS	200	8.5	0.4	44
2SK2376	L²-π-MOSV	TO-220FL/SM	60	45	0.017	44
2SK2381	π-MOSV	TO-220NIS	200	5	0.8	44
2SK2382	π-MOSV	TO-220NIS	200	15	0.18	44
2SK2385	L²-π-MOSV	TO-220NIS	60	36	0.03	44
2SK2391	L²-π-MOSV	TO-220NIS	100	20	0.085	44
2SK2398	L²-π-MOSV	TO-3P (N)	60	45	0.03	44
2SK2399	L²-π-MOSV	New PW-Mold	100	5	0.23	44
2SK2400	L²-π-MOSV	TPS	100	5	0.23	44
2SK2401	π-MOSV	TO-220FL/SM	200	15	0.18	44
2SK2417	π-MOSV	TO-220NIS	250	7.5	0.5	44
2SK2445	L²-π-MOSV	TO-3P (N)	60	50	0.018	44
2SK2467	π-MOSII	TO-3P (N)IS	180	9	0.8	–
2SK2507	L²-π-MOSV	TO-220NIS	50	25	0.046	43
2SK2508	π-MOSV	TO-220NIS	250	13	0.25	44
2SK2542	π-MOSV	TO-220AB	500	8	0.85	45
2SK2550	L²-π-MOSV	TO-3P (N)	50	45	0.03	43
2SK2551	L²-π-MOSV	TO-3P (N)	50	50	0.011	43
2SK2598	π-MOSV	TO-220FL/SM	250	13	0.25	44
2SK2599	π-MOSV	TPS	500	2	3.2	45
2SK2601	π-MOSV	TO-3P (N)	500	10	1	45
2SK2602	π-MOSV	TO-3P (N)	600	6	1.25	45
2SK2603	π-MOSIII	TO-220AB	800	3	3.6	45
2SK2606	π-MOSIII	TO-3P (N)IS	800	8	1.2	45
2SK2607	π-MOSIII	TO-3P (N)	800	9	1.2	45
2SK2608	π-MOSIII	TO-220AB	900	3	4.3	45
2SK2613	π-MOSIII	TO-3P (N)	1000	8	1.7	45
2SK2614	L²-π-MOSV	DP	50	20	0.046	43
2SK2615	L²-π-MOSV	PW-Mini	60	2	0.3	44
2SK2679	π-MOSV	TO-220NIS	400	5.5	1.2	45
2SK2699	π-MOSV	TO-3P (N)	600	12	0.65	45
2SK2719	π-MOSIII	TO-3P (N)	900	3	4.3	45
2SK2733	π-MOSIII	TO-220AB	900	1	9	45
2SK2744	L²-π-MOSV	TO-3P (N)	50	45	0.02	43
2SK2745	L²-π-MOSV	TO-3P (N)	50	50	0.0095	43
2SK2776	π-MOSV	TO-220FL/SM	500	8	0.85	45
2SK2777	π-MOSV	TO-220FL/SM	600	6	1.25	45
2SK2782	L²-π-MOSV	DP	60	20	0.055	44
2SK2789	L²-π-MOSV	TO-220FL/SM	100	27	0.085	44

Part Number	Series	Package	Main Characteristics			Page
			V_{DSS} (V)	I_D (A)	$R_{DS(ON)}$ Max (Ω)	
2SK2835	π-MOSV	TPS	200	5	0.8	44
2SK2838	π-MOSV	TO-220FL/SM	400	5.5	1.2	45
2SK2841	π-MOSV	TO-220AB	400	10	0.55	45
2SK2845	π-MOSIII	DP	900	1	9	45
2SK2846	π-MOSV	TPS	600	2	5	45
2SK2847	π-MOSIII	TO-3P (N)IS	900	8	1.4	45
2SK2862	π-MOSV	TO-220NIS	500	3	3.2	45
2SK2865	π-MOSV	New PW-Mold	600	2	5	45
2SK2866	π-MOSV	TO-220AB	600	10	0.75	42,45
2SK2882	π-MOSV	TO-220NIS	150	18	0.12	44
2SK2883	π-MOSIII	TO-220FL/SM	800	3	3.6	45
2SK2884	π-MOSIII	TO-220FL/SM	800	5	2.2	45
2SK2886	L^2-π-MOSV	TO-220NIS	50	45	0.02	43
2SK2889	π-MOSV	TO-220FL/SM	600	10	0.75	45
2SK2914	π-MOSV	TO-220AB	250	7.5	0.5	44
2SK2916	π-MOSV	TO-3P (N)IS	500	14	0.4	45
2SK2917	π-MOSV	TO-3P (N)IS	500	18	0.27	45
2SK2920	π-MOSV	New PW-Mold	200	5	0.8	44
2SK2949	π-MOSV	TO-220FL/SM	400	10	0.55	45
2SK2952	π-MOSV	TO-220NIS	400	8.5	0.55	45
2SK2953	π-MOSV	TO-3P (N)IS	600	15	0.4	45
2SK2961	L^2-π-MOSV	LSTM	60	2	0.27	44
2SK2962	L^2-π-MOSV	LSTM	100	1	0.7	44
2SK2963	L^2-π-MOSV	PW-Mini	100	1	0.7	44
2SK2965	π-MOSV	TO-220NIS	200	11	0.26	44
2SK2967	π-MOSV	TO-3P (N)	250	30	0.068	44
2SK2968	π-MOSIII	TO-3P (N)	900	10	1.25	45
2SK2989	L^2-π-MOSV	LSTM	50	5	0.15	43
2SK2991	π-MOSV	TO-220FL/SM	500	5	1.5	42,45
2SK2992	π-MOSV	PW-Mini	200	1	3.5	44
2SK2993	π-MOSV	TO-220FL/SM	250	20	0.105	44
2SK2995	π-MOSV	TO-3P (N)IS	250	30	0.068	44
2SK2998	π-MOSV	LSTM	500	0.5	18	45
2SK3017	π-MOSIII	TO-3P (N)IS	900	8.5	1.25	45
2SK3051	L^2-π-MOSV	TO-220FL/SM	50	45	0.03	43
2SK3068	π-MOSV	TO-220FL/SM	500	12	0.52	45
2SK3085	π-MOSV	TO-220AB	600	3.5	2.2	45
2SK3130	π-MOSV	TO-220NIS	600	6	1.55	45
2SK3131	π-MOSV(HSD)	TO-3P (L)	500	50	0.11	42
2SK3132	π-MOSV	TO-3P (L)	500	50	0.095	42,45
2SK3176	π-MOSV	TO-3P (N)	200	30	0.052	44
2SK3205	π-MOSV	PW-Mold	150	5	0.5	44
2SK3265	π-MOSV	TO-220NIS	700	10	1	45
2SK3301	π-MOSIII	PW-Mold	900	1	20	45
2SK3302	π-MOSV	TPS	500	0.5	18	45
2SK3309	MACH	TO-220FL/SM	450	10	0.65	42
2SK3310	MACH	TO-220NIS	450	10	0.65	42
2SK3312	π-MOSV	TO-220FL/SM	600	6	1.25	42,45
2SK3313	π-MOSV(HSD)	TO-220NIS	500	12	0.62	42
2SK3314	π-MOSV(HSD)	TO-3P (N)	500	15	0.49	42
2SK3342	π-MOSV	New PW-Mold	250	4.5	1	44
2SK3371	π-MOSV	New PW-Mold	600	1	9	45
2SK3373	π-MOSV	New PW-Mold	500	2	3.2	45
2SK3374	π-MOSV	TPS	450	1	4.6	45
2SK3387	L^2-π-MOSV	TFP	150	18	0.12	44

Part Number	Series	Package	Main Characteristics			Page
			V_{DSS} (V)	I_D (A)	$R_{DS(ON)}$ Max (Ω)	
2SK3388	π-MOSV	TFP	250	20	0.105	44
2SK3398	π-MOSV	TFP	500	12	0.52	45
2SK3399	MACH	TO-220FL/SM	600	10	0.75	42
2SK3403	MACH	TO-220FL/SM	450	13	0.4	42
2SK3417	π-MOSV(HSD)	TO-220FL/SM	500	5	1.8	42
2SK3437	MACH	TO-220FL/SM	600	10	1	42
2SK3438	π-MOSV	TFP	600	10	1	45
2SK3444	π-MOSV	TFP	200	25	0.082	44
2SK3445	π-MOSV	TFP	250	20	0.105	44
2SK3453	π-MOSIV	TO-3P (N)IS	700	10	1	45
2SK3462	π-MOSV	New PW-Mold	250	3	1.7	44
2SK3466	π-MOSV	TFP	500	5	1.5	45
2SK3471	π-MOSV	PW-Mini	500	0.5	18	45
2SK3472	π-MOSV	PW-Mold	450	1	4.6	45
2SK3473	π-MOSIV	TO-3P (N)	900	9	1.6	43
2SK3497	π-MOSV	TO-3P (N)	180	10	0.15	44
2SK3498	π-MOSV	PW-Mold	400	1	5.5	45
2SK3499	π-MOSV	TFP	400	10	0.55	45
2SK3506	π-MOSVI	TO-3P (N)	30	45	0.02	43
2SK3538	π-MOSV	TFP	500	8	0.85	45
2SK3544	π-MOSV	TFP	450	13	0.4	45
2SK3561	π-MOSVI	TO-220SIS	500	8	0.85	40,42,43
2SK3562	π-MOSVI	TO-220SIS	600	6	1.25	40,42,43
2SK3563	π-MOSVI	TO-220SIS	500	5	1.5	40,42,43
2SK3564	π-MOSIV	TO-220SIS	900	3	4.3	43
2SK3565	π-MOSIV	TO-220SIS	900	5	2.5	43
2SK3566	π-MOSIV	TO-220SIS	900	2.5	6.4	43
2SK3567	π-MOSVI	TO-220SIS	600	3.5	2.2	40,43
2SK3568	π-MOSVI	TO-220SIS	500	12	0.52	40,43
2SK3569	π-MOSVI	TO-220SIS	600	10	0.75	40,42,43
2SK3625	π-MOSV	TO-220FL/SM	200	25	0.082	44
2SK3633	π-MOSIV	TO-3P (N)	800	7	1.7	43
2SK3662	U-MOSIII	TO-220NIS	60	35	0.0125	38
2SK3667	π-MOSVI	TO-220SIS	600	7.5	1	40,43
2SK3669	π-MOSVII	New PW-Mold	100	10	0.125	–
2SK3670	π-MOSV	LSTM	150	0.67	1.7	44
2SK3700	π-MOSIV	TO-3P (N)	900	5	2.5	43
2SK3742	π-MOSIV	TO-220SIS	900	5	2.5	43
2SK3743	MACH	TO-220NIS	450	13	0.6	40,42
2SK3754	U-MOSIII	TO-220NIS	30	5	0.089	38
2SK3757	π-MOSVI	TO-220SIS	450	2	2.45	43
2SK3766	π-MOSVI	TO-220SIS	450	2	2.45	43
2SK3767	π-MOSVI	TO-220SIS	600	2	4.5	43
2SK3797	π-MOSVI	TO-220SIS	600	13	0.43	40,42,43
2SK3798	π-MOSIV	TO-220SIS	900	4	3.5	43
2SK3799	π-MOSIV	TO-220SIS	900	8	1.3	43
2SK3842	U-MOSIII	TFP	60	75	0.0058	38
2SK3843	U-MOSIII	TFP	40	75	0.0035	38
2SK3844	U-MOSIII	TO-220NIS	60	45	0.0058	38
2SK3845	U-MOSIII	TO-3P (N)	60	70	0.0058	38
2SK3846	U-MOSIII	TO-220NIS	40	26	0.018	38
2SK3847	U-MOSIII	TO-220SM	40	32	0.016	38
2SK3863	π-MOSVI	DP	500	5	1.5	43
2SK3868	π-MOSVI (HSD)	TO-220SIS	500	5	1.7	42
2SK3869	π-MOSVI	TO-220SIS	450	10	0.68	43

7 MOSFET Part Numbers

Part Number	Series	Package	Main Characteristics			Page
			V_{DSS} (V)	I_D (A)	$R_{DS(ON)}$ Max (Ω)	
2SK3878	π-MOSIV	TO-3P (N)	900	9	1.3	43
2SK3879	π-MOSIV	TO-220FL/SM	800	6.5	1.7	43
2SK3880	π-MOSIV	TO-3P (N)IS	800	6.5	1.7	43
2SK3903	π-MOSVI	TO-3P (N)	600	14	0.44	43
2SK3904	π-MOSVI	TO-3P (N)	450	19	0.26	43
2SK3905	π-MOSVI	TO-3P (N)	500	17	0.31	43
2SK3906	MACH (HSD)	TO-3P (N)	600	20	0.33	42
2SK3907	MACH	TO-3P (N)	500	23	0.23	42
2SK3911	MACH	TO-3P (N)	600	20	0.32	41,42
2SK3934	π-MOSVI	TO-220SIS	500	15	0.3	40,43
2SK3935	π-MOSVI	TO-220SIS	450	17	0.25	43
2SK3936	MACH (HSD)	TO-3P (N)	500	23	0.25	42
2SK3947	π-MOSVI (HSD)	TO-220SIS	600	6	1.4	42
2SK3975	π-MOSV	New PW-Mold	600	3	2.2	45
2SK3994	π-MOSV	TO-220NIS	250	20	0.105	44
2SK4002	π-MOSV	New PW-Mold2	600	2	5	40,45
2SK4003	π-MOSV	New PW-Mold2	600	3	2.2	45
2SK4012	π-MOSVI	TO-220SIS	500	13	0.4	40,43
2SK4013	π-MOSIV	TO-220SIS	800	6	1.7	43
2SK4014	π-MOSIV	TO-220SIS	900	6	2	43
2SK4015	π-MOSVI (HSD)	TO-220SIS	600	10	0.86	42
2SK4016	π-MOSVI (HSD)	TO-220SIS	600	13	0.5	42
2SK4017	U-MOSIII	New PW-Mold2	60	5	0.1	38
2SK4018	L^2-π-MOSV	New PW-Mold2	100	3	0.35	44
2SK4019	L^2-π-MOSV	New PW-Mold2	100	5	0.23	44
2SK4020	π-MOSV	New PW-Mold2	200	5	0.8	44
2SK4021	π-MOSV	New PW-Mold2	250	4.5	1	44
2SK4022	π-MOSV	New PW-Mold2	250	3	1.7	44
2SK4023	π-MOSV	New PW-Mold2	450	1	4.6	45
2SK4026	π-MOSV	New PW-Mold2	600	1	9	45
2SK4033	U-MOSIII	New PW-Mold	60	5	0.1	38
2SK4034	U-MOSIII	TFP	60	75	0.0058	38
2SK4042	π-MOSVI (HSD)	TO-220SIS	500	8	0.97	42
2SK4103	π-MOSVI	New PW-Mold	500	5	1.5	43
2SK4107	π-MOSVI	TO-3P (N)	500	15	0.4	40,43
2SK4108	π-MOSVI	TO-3P (N)	500	20	0.27	40,43
2SK4115	π-MOSIV	TO-3P (N)	900	7	2	43
2SK4207	π-MOSIV	TO-3P (N)	900	13	0.95	43
S3U72	U-MOSV-H	SOP Advance	30	TBD	TBD	35
S3W16	U-MOSIV-H	SOP Advance	30	(40)	(0.0035)	–
SSM3J01T	π-MOSVI	TSM	–30	–1.7	0.4	28
SSM3J02T	π-MOSVI	TSM	–30	–1.5	0.5	28
SSM3J05FU	π-MOSVI	USM	–20	–0.2	4	36
SSM3J09FU	π-MOSVI	USM	–30	–0.2	4.2	36
SSM3J108TU	U-MOSIII	UFM	–20	–1.8	0.158	28
SSM3J109TU	U-MOSII	UFM	–20	–2	0.13	28
SSM3J110TU	U-MOSIII	UFM	–12	–2.3	0.094	28
SSM3J111TU	U-MOSIII	UFM	–20	–1	0.48	28
SSM3J112TU	U-MOSII	UFM	–30	–1.1	0.79	28
SSM3J113TU	U-MOSIII	UFM	–20	–1.7	0.169	28
SSM3J114TU	U-MOSIV	UFM	–20	–1.8	0.149	28
SSM3J115TU	U-MOSIV	UFM	–20	–2.2	0.098	28
SSM3J117TU	U-MOSII	UFM	–30	–2	0.225	28
SSM3J118TU	U-MOSII	UFM	–30	–1.4	0.48	28
SSM3J120TU	U-MOSIV	UFM	–20	–4	0.038	28

Part Number	Series	Package	Main Characteristics			Page
			V_{DSS} (V)	I_D (A)	$R_{DS(ON)}$ Max (Ω)	
SSM3J129TU	U-MOSV	UFM	–20	–4.6	0.046	28
SSM3J130TU	U-MOSVI	UFM	–20	–4.4	0.0258	28
SSM3J132TU	U-MOSVI	UFM	–12	–5	0.0178	28
SSM3J13T	U-MOSIII	TSM	–12	–3	0.07	28
SSM3J14T	U-MOSII	TSM	–30	–2.7	0.17	28
SSM3J15CT	π-MOSVI	CST3	–30	–0.1	32	36
SSM3J15F	π-MOSVI	S-MINI	–30	–0.1	32	36
SSM3J15FS	π-MOSVI	SSM	–30	–0.1	32	36
SSM3J15FU	πMOSVI	USM	–30	–0.1	32	36
SSM3J15FV	π-MOSVI	VESM	–30	–0.1	32	36
SSM3J16CT	π-MOSVI	CST3	–20	–0.1	45	36
SSM3J16FS	π-MOSVI	SSM	–20	–0.1	45	36
SSM3J16FU	π-MOSVI	USM	–20	–0.1	45	36
SSM3J16FV	π-MOSVI	VESM	–20	–0.1	45	48
SSM3J304T	U-MOSIII	TSM	–20	–2.3	0.127	28
SSM3J305T	U-MOSII	TSM	–30	–1.7	0.477	28
SSM3J306T	U-MOSII	TSM	–30	–2.4	0.225	28
SSM3J307T	U-MOSV	TSM	–20	–5.0	0.031	28
SSM3J312T	U-MOSIII	TSM	–12	–2.7	0.091	28
SSM3J313T	U-MOSIII	TSM	–20	–1.6	0.268	28
SSM3J314T	U-MOSIII-H	TSM	–30	–3.5	0.1	28
SSM3J317T	U-MOSIII	TSM	–20	–3.6	0.107	28
SSM3J321T	U-MOSV	TSM	–20	–5.2	0.046	28
SSM3J325F	U-MOSVI	S-MINI	–20	–2.0	0.155	28
SSM3J326T	U-MOSVI	TSM	–30	–5.6	0.0457	28
SSM3J327F	U-MOSVI	S-MINI	–20	–3.5	0.095	28
SSM3J35CT	π-MOSVI	CST3	–20	–0.1	44	36
SSM3J35FS	π-MOSVI	SSM	–20	–0.1	44	36
SSM3J35MFV	π-MOSVI	VESM	–20	–0.1	44	36
SSM3J36FS	U-MOSIII	SSM	–20	–0.33	3.6	36
SSM3J36MFV	U-MOSIII	VESM	–20	–0.33	3.6	36
SSM3J36TU	U-MOSIII	UFM	–20	–0.33	3.6	36
SSM3J46CTB	U-MOSVI	CST3B	–20	–2	0.103	28
SSM3K01T	π-MOSVI	TSM	30	3.2	0.12	29
SSM3K02T	π-MOSVI	TSM	30	2.5	0.2	29
SSM3K03FV	π-MOSVI	VESM	20	0.1	12	36
SSM3K04FS	π-MOSVI	SSM	20	0.1	12	36
SSM3K04FU	π-MOSVI	USM	20	0.1	12	36
SSM3K04FV	π-MOSVI	VESM	20	0.1	12	36
SSM3K05FU	π-MOSVI	USM	20	0.4	1.2	36
SSM3K09FU	π-MOSVI	USM	30	0.4	1.2	36
SSM3K101TU	U-MOSIII	UFM	20	2.2	0.103	29
SSM3K102TU	U-MOSIII	UFM	20	2.6	0.071	29
SSM3K104TU	U-MOSIII	UFM	20	3	0.056	29
SSM3K105TU	π-MOSVI	UFM	30	2.1	0.2	29
SSM3K106TU	π-MOSVII	UFM	20	1.2	0.53	29
SSM3K107TU	π-MOSVI	UFM	20	1.5	0.41	29
SSM3K116TU	U-MOSIII	UFM	30	2.2	0.1	29
SSM3K119TU	U-MOSIII	UFM	30	2.5	0.074	29
SSM3K121TU	U-MOSIII	UFM	20	3.2	0.048	29
SSM3K122TU	U-MOSIII	UFM	20	2	0.123	29
SSM3K123TU	U-MOSIII	UFM	20	4.2	0.028	29
SSM3K124TU	π-MOSVII	UFM	30	2.4	0.12	29
SSM3K127TU	U-MOSIII	UFM	30	2	0.123	29
SSM3K128TU	U-MOSIII	UFM	30	1.5	0.36	29

Part Number	Series	Package	Main Characteristics			Page
			V_{DSS} (V)	I_D (A)	$R_{DS(ON)}$ Max (Ω)	
SSM3K12T	π-MOSVII	TSM	30	3	0.175	29
SSM3K131TU	U-MOSIV	UFM	30	6.0	0.0415	29
SSM3K14T	U-MOSII	TSM	30	4	0.067	29
SSM3K15CT	π-MOSVI	CST3	30	0.1	7	36
SSM3K15F	π-MOSVI	S-MINI	30	0.1	7	36
SSM3K15FS	π-MOSVI	SSM	30	0.1	7	36
SSM3K15FU	π-MOSVI	USM	30	0.1	7	36
SSM3K15FV	π-MOSVI	VESM	30	0.1	7	36
SSM3K16CT	π-MOSVI	CST3	20	0.1	15	36
SSM3K16FS	π-MOSVI	SSM	20	0.1	15	36
SSM3K16FU	π-MOSVI	USM	20	0.1	15	36
SSM3K16FV	π-MOSVI	VESM	20	0.1	15	36
SSM3K17FU	π-MOSV	USM	50	0.1	40	36
SSM3K301T	U-MOSIII	TSM	20	3.5	0.056	29
SSM3K303T	π-MOSVII	TSM	30	2.9	0.12	29
SSM3K309T	U-MOSIII	TSM	20	4.7	0.031	29
SSM3K310T	U-MOSIII	TSM	20	5	0.028	29
SSM3K315T	U-MOSIV	TSM	30	6	0.0415	29
SSM3K316T	U-MOSIII	TSM	30	4	0.065	29
SSM3K318T	U-MOSIV	TSM	60	2.5	0.145	29
SSM3K320T	U-MOSIV	TSM	30	4.2	0.077	29
SSM3K35CT	π-MOSVI	CST3	20	0.18	20	36
SSM3K35FS	π-MOSVI	SSM	20	0.18	20	36
SSM3K35MFV	π-MOSVI	VESM	20	0.18	20	36
SSM3K36FS	U-MOSIII	SSM	20	0.5	1.52	36
SSM3K36MFV	U-MOSIII	VESM	20	0.5	1.52	36
SSM3K36TU	U-MOSIII	UFM	20	0.5	1.52	36
SSM3K43FS	U-MOSIII	SSM	20	0.5	1.52	36
SSM3K44FS	π-MOSVI	SSM	30	0.1	7	36
SSM3K44MFV	π-MOSVI	VESM	30	0.1	7	36
SSM3K7002AF	π-MOSV	S-MINI	60	0.2	3.3	36
SSM3K7002AFU	π-MOSV	USM	60	0.2	3.3	36
SSM3K7002BF	U-MOSIV	S-MINI	60	0.2	3.3	36
SSM3K7002BFS	U-MOSIV	SSM	60	0.2	3.3	36
SSM3K7002BFU	U-MOSIV	USM	60	0.2	3.3	36
SSM3K7002F	π-MOSVI	S-MINI	60	0.2	3.3	36
SSM3K7002FU	π-MOSVI	USM	60	0.2	3.3	36
SSM4K27CT	U-MOSIII	CST4	20	0.5	0.205	29
SSM5G01TU	U-MOSII	UFV	–30	–1	0.8	30
SSM5G02TU	U-MOSII	UFV	–12	–1	0.16	30
SSM5G04TU	U-MOSII	UFV	–12	–1	0.24	30
SSM5G09TU	U-MOSII	UFV	–12	–1.5	0.13	30
SSM5G10TU	U-MOSIII	UFV	–20	–1.5	0.213	30
SSM5G11TU	U-MOSIII-H	UFV	–30	–1.4	0.403	30
SSM5H01TU	U-MOSII	UFV	30	1.4	0.45	30
SSM5H03TU	U-MOSII	UFV	12	1.4	0.3	30
SSM5H05TU	U-MOSIII	UFV	20	1.5	0.16	30
SSM5H07TU	π-MOSVII	UFV	20	1.2	0.54	30
SSM5H08TU	U-MOSIII	UFV	20	1.5	0.16	30
SSM5H10TU	U-MOSIII	UFV	20	1.6	0.119	30
SSM5H11TU	U-MOSIII	UFV	30	1.6	0.182	30
SSM5H12TU	U-MOSIII	UFV	30	1.9	0.133	30
SSM5H14F	U-MOSIII	SMV	30	3	0.078	31
SSM5N03FE	π-MOSVI	ES6	20	0.1	12	36
SSM5N05FU	π-MOSVI	US6	20	0.4	1.2	36

Part Number	Series	Package	Main Characteristics			Page
			V_{DSS} (V)	I_D (A)	$R_{DS(ON)}$ Max (Ω)	
SSM5N15FE	π-MOSVI	ES6	30	0.1	7	36
SSM5N15FU	π-MOSVI	US6	30	0.1	7	36
SSM5N16FE	π-MOSVI	ES6	20	0.1	15	36
SSM5N16FU	π-MOSVI	US6	20	0.1	15	36
SSM5P05FU	π-MOSVI	US6	–20	–0.2	4	36
SSM5P15FE	π-MOSVI	ES6	–30	–0.1	32	36
SSM5P15FU	π-MOSVI	US6	–30	–0.1	32	36
SSM5P16FE	π-MOSVI	ES6	–20	–0.1	45	36
SSM5P16FU	π-MOSVI	US6	–20	–0.1	45	36
SSM6E01TU	U-MOSIII	UF6	–12	–1	0.16	30
SSM6E02TU	U-MOSIV	UF6	–20	–1.8	0.136	30
SSM6E03TU	U-MOSIII	UF6	–20	–1.8	0.144	30
SSM6J06FU	π-MOSVI	US6	–20	–0.65	0.5	28
SSM6J07FU	π-MOSVI	US6	–30	–0.8	0.8	28
SSM6J08FU	U-MOSII	US6	–20	–1.3	0.18	28
SSM6J205FE	U-MOSIII	ES6	–20	–0.8	0.234	28
SSM6J206FE	U-MOSIII	ES6	–20	–2	0.13	28
SSM6J207FE	U-MOSII	ES6	–30	–1.3	0.491	28
SSM6J21TU	U-MOSIII	UF6	–12	–3	0.05	28
SSM6J212FE	U-MOSVI	ES6	–20	–3.3	0.0434	28
SSM6J23FE	U-MOSIII	ES6	–12	–1.2	0.16	28
SSM6J25FE	U-MOSIII	ES6	–20	–0.5	0.26	28
SSM6J26FE	U-MOSIII	ES6	–20	–0.5	0.23	28
SSM6J401TU	U-MOSIII	UF6	–30	–2.5	0.145	28
SSM6J402TU	U-MOSIII	UF6	–30	–2	0.225	28
SSM6J409TU	U-MOSV	UF6	–20	–9.5	0.0221	28
SSM6J50TU	U-MOSIV	UF6	–20	–2.5	0.064	28
SSM6J51TU	U-MOSIV	UF6	–12	–4	0.054	28
SSM6J53FE	U-MOSIV	ES6	–20	–1.8	0.136	28
SSM6K06FU	π-MOSVI	US6	20	1.1	0.16	29
SSM6K07FU	π-MOSVI	US6	30	1.5	0.22	29
SSM6K08FU	U-MOSII	US6	20	1.6	0.105	29
SSM6K18TU	U-MOSIII	UF6	20	4	0.04	29
SSM6K202FE	U-MOSIII	ES6	30	2.3	0.085	29
SSM6K203FE	U-MOSIII	ES6	20	2.8	0.061	29
SSM6K204FE	U-MOSIII	ES6	20	2	0.126	29
SSM6K208FE	U-MOSIII	ES6	30	1.9	0.133	29
SSM6K210FE	U-MOSIII	ES6	30	1.4	0.371	29
SSM6K211FE	U-MOSIII	ES6	20	3.2	0.047	29
SSM6K22FE	U-MOSIII	ES6	20	1.4	0.17	29
SSM6K24FE	U-MOSIII	ES6	30	0.5	0.145	29
SSM6K25FE	U-MOSIII	ES6	20	0.5	0.145	29
SSM6K30FE	π-MOSVII	ES6	20	1.2	0.42	29
SSM6K31FE	π-MOSVII	ES6	20	1.2	0.54	29
SSM6K32TU	π-MOSV	UF6	60	2	0.44	29
SSM6K34TU	U-MOSIII	UF6	30	3	0.077	29
SSM6K403TU	U-MOSIII	UF6	20	4.2	0.028	29
SSM6K404TU	U-MOSIII	UF6	20	3	0.055	29
SSM6K405TU	U-MOSIII	UF6	20	2	0.126	29
SSM6K406TU	U-MOSIV	UF6	30	4.4	0.0385	29
SSM6K407TU	π-MOSV	UF6	60	2	0.44	29
SSM6L05FU	π-MOSVI	US6	20	0.4	1.2	36
SSM6L09FU	π-MOSVI	US6	30	0.4	1.2	36
SSM6L10TU	U-MOSIII	UF6	20	0.5	0.145	30
SSM6L11TU	U-MOSIII	UF6	20	0.5	0.145	30

Part Number	Series	Package	Main Characteristics			Page
			V_{DSS} (V)	I_D (A)	$R_{DS(ON)}$ Max (Ω)	
SSM6L12TU	U-MOSIII	UF6	30	0.5	0.145	30
SSM6L13TU	U-MOSIII	UF6	20	0.8	0.143	30
SSM6L16FE	π-MOSVI	ES6	20	0.1	15	36
SSM6L35FE	π-MOSVI	ES6	20	0.18	20	36
SSM6L35FU	π-MOSVI	US6	20	0.18	20	36
SSM6L36FE	U-MOSIII	ES6	20	0.5	1.52	36
SSM6L36TU	U-MOSIII	UF6	20	0.5	1.52	36
SSM6L39TU	U-MOSIII	UF6	20	1.6	0.119	30
SSM6L40TU	U-MOSIII	UF6	30	1.6	0.182	30
SSM6N03FE	π-MOSVI	ES6	20	0.1	12	36
SSM6N04FU	π-MOSVI	US6	20	0.1	12	36
SSM6N05FU	π-MOSVI	US6	20	0.4	1.2	36
SSM6N09FU	π-MOSVI	US6	30	0.4	1.2	36
SSM6N15FE	π-MOSVI	ES6	30	0.1	7	36
SSM6N15FU	π-MOSVI	US6	30	0.1	7	36
SSM6N16FE	π-MOSVI	ES6	20	0.1	15	36
SSM6N16FU	π-MOSVI	US6	20	0.1	15	36
SSM6N17FU	π-MOSV	US6	50	0.1	40	36
SSM6N24TU	U-MOSIII	UF6	30	0.5	0.145	30
SSM6N25TU	U-MOSIII	UF6	20	0.5	0.145	30
SSM6N29TU	U-MOSIII	UF6	20	0.8	0.143	30
SSM6N35FE	π-MOSVI	ES6	20	0.18	20	36
SSM6N35FU	π-MOSVI	US6	20	0.18	20	36
SSM6N36FE	U-MOSIII	ES6	20	0.5	1.52	36
SSM6N36TU	U-MOSIII	UF6	20	0.5	1.52	36
SSM6N37CTD	U-MOSIII	CST6D	20	0.25	5.6	36
SSM6N39TU	U-MOSIII	UF6	20	1.6	0.119	30
SSM6N40TU	U-MOSIII	UF6	30	1.6	0.182	30
SSM6N42FE	U-MOSIII	ES6	20	0.77	0.26	30
SSM6N43FU	U-MOSIII	US6	20	0.5	1.52	36
SSM6N44FE	π-MOSVI	ES6	30	0.1	7	36
SSM6N44FU	π-MOSVI	US6	30	0.1	7	36
SSM6N7002AFU	π-MOSV	US6	60	0.2	3.3	36
SSM6N7002BFE	U-MOSIV	ES6	60	0.2	3.3	36
SSM6N7002BFU	U-MOSIV	US6	60	0.2	3.3	36
SSM6N7002FU	π-MOSVI	US6	60	0.2	3.3	36
SSM6P05FU	π-MOSVI	US6	–20	–0.2	4	36
SSM6P09FU	π-MOSVI	US6	–30	–0.2	4.2	36
SSM6P15FE	π-MOSVI	ES6	–30	–0.1	32	36
SSM6P15FU	π-MOSVI	US6	–30	–0.1	32	36
SSM6P16FE	π-MOSVI	ES6	–20	–0.1	45	36
SSM6P16FU	π-MOSVI	US6	–20	–0.1	45	36
SSM6P25TU	U-MOSIII	UF6	–20	–0.5	0.26	30
SSM6P26TU	U-MOSIII	UF6	–20	–0.5	0.23	30
SSM6P28TU	U-MOSIII	UF6	–20	–0.8	0.234	30
SSM6P35FE	π-MOSVI	ES6	–20	–0.1	44	36
SSM6P35FU	π-MOSVI	US6	–20	–0.1	44	36
SSM6P36FE	U-MOSIII	ES6	–20	–0.33	3.6	36
SSM6P36TU	U-MOSIII	UF6	–20	–0.33	3.6	36
SSM6P39TU	U-MOSIII	UF6	–20	–1.5	0.213	30
SSM6P40TU	U-MOSIII	UF6	–30	–1.4	0.403	30
SSM6P41FE	U-MOSV	ES6	–20	–0.72	0.3	30
SSM6P54TU	U-MOSIV	UF6	–20	–1.2	0.228	30
TJ20A10M3	U-MOSVI	TO-220SIS	–100	–20	0.09	38
TJ70A06J3	U-MOSIII	TO-220SIS	–60	–70	0.008	38
TJ120F06J3	U-MOSIII	TO-220SM(W)	–60	–120	0.008	37,38

Part Number	Series	Package	Main Characteristics			Page
			V_{DSS} (V)	I_D (A)	$R_{DS(ON)}$ Max (Ω)	
TK100F04K3	U-MOSIV	TO-220SM(W)	40	100	0.003	37,38
TK100F04K3L	U-MOSIV	TO-220SM(W)	40	100	0.003	37,38
TK100F06K3	U-MOSIV	TO-220SM(W)	60	100	0.005	37,38
TK10A50D	π-MOSVII	TO-220SIS	500	10	0.72	40
TK10A60D	π-MOSVII	TO-220SIS	600	10	0.75	40
TK11A50D	π-MOSVII	TO-220SIS	500	11	0.6	40
TK11A55D	π-MOSVII	TO-220SIS	550	11	0.63	40
TK11A60D	π-MOSVII	TO-220SIS	600	11	0.65	40
TK12A50D	π-MOSVII	TO-220SIS	500	12	0.52	40
TK12A53D	π-MOSVII	TO-220SIS	525	12	0.58	40
TK12A55D	π-MOSVII	TO-220SIS	550	12	0.57	40
TK12A60D	π-MOSVII	TO-220SIS	600	12	0.55	40
TK12A60U	DTMOSII	TO-220SIS	600	12	0.4	41
TK12D60U	DTMOSII	TO-220(W)	600	12	0.4	41
TK12J55D	π-MOSVII	TO-3P(N)	550	12	0.57	40
TK12J60U	DTMOSII	TO-3P(N)	600	12	0.4	41
TK12X53D	π-MOSVII	TFP	550	12	0.58	40
TK130F06K3	U-MOSIV	TO-220SM(W)	60	130	0.0034	37
TK13A45D	π-MOSVII	TO-220SIS	450	13	0.46	40
TK13A50D	π-MOSVII	TO-220SIS	500	13	0.4	40
TK13A50DA	π-MOSVII	TO-220SIS	500	12.5	0.47	40
TK13A55DA	π-MOSVII	TO-220SIS	550	12.5	0.48	40
TK13A60D	π-MOSVII	TO-220SIS	600	13	0.43	40
TK13A65U	DTMOSII	TO-220SIS	650	13	0.38	41
TK14A55D	π-MOSVII	TO-220SIS	550	14	0.37	40
TK150F04K3	U-MOSIV	TO-220SM(W)	40	150	0.0021	37
TK150F04K3L	U-MOSIV	TO-220SM(W)	40	150	0.0021	37
TK15A50D	π-MOSVII	TO-220SIS	500	15	0.3	40
TK15A60D	π-MOSVII	TO-220SIS	600	15	0.37	40
TK15A60U	DTMOSII	TO-220SIS	600	15	0.3	41
TK15D60U	DTMOSII	TO-220(W)	600	15	0.3	41
TK15J50D	π-MOSVII	TO-3P(N)	500	15	0.4	40
TK15J60T	DTMOSI	TO-3P(N)	600	15	0.28	41
TK15J60U	DTMOSII	TO-3P(N)	600	15	0.3	41
TK16J55D	π-MOSVII	TO-3P(N)	550	16	0.37	40
TK18A50D	π-MOSVII	TO-220SIS	500	18	0.27	40
TK20A60T	DTMOSI	TO-220SIS	600	20	0.19	41
TK20A60U	DTMOSII	TO-220SIS	600	20	0.19	41
TK20D60T	DTMOSI	TO-220(W)	600	20	0.19	41
TK20D60U	DTMOSII	TO-220(W)	600	20	0.19	41
TK20J50D	π-MOSVII	TO-3P(N)	500	20	0.27	40
TK20J60T	DTMOSI	TO-3P(N)	600	20	0.19	41
TK20J60U	DTMOSII	TO-3P(N)	600	20	0.19	41
TK25A10K3	U-MOSIV	TO-220SIS	100	25	0.04	38
TK2Q60D	π-MOSVII	NewPW-Mold2	600	2	5	40
TK30A06J3A	U-MOSIII	TO-220SIS	60	30	0.026	38
TK3A60DA	π-MOSVII	TO-220SIS	600	2.5	2.8	40
TK40A08K3	U-MOSIV	TO-220SIS	75	40	0.009	39
TK40A10J1	U-MOSIII-H	TO-220SIS	100	40	0.015	39
TK40A10K3	U-MOSIV	TO-220SIS	100	40	0.015	39
TK40D10J1	U-MOSIII-H	TO-220(W)	100	40	0.015	39
TK40J60T	DTMOSI	TO-3P(N)	600	40	0.08	41
TK40P03M1	U-MOSVI-H	DPAK	30	40	0.0108	35
TK40P04M1	U-MOSVI-H	DPAK	40	40	0.0103	35
TK40X10J1	U-MOSIII-H	TFP	100	40	0.02	38,39
TK4A50D	π-MOSVII	TO-220SIS	500	4	2	40

Part Number	Series	Package	Main Characteristics			Page
			V_{DSS} (V)	I_D (A)	$R_{DS(ON)}$ Max (Ω)	
TK4A53D	π-MOSVII	TO-220SIS	525	4	1.7	40
TK4A55D	π-MOSVII	TO-220SIS	550	4	1.9	40
TK4A55DA	π-MOSVII	TO-220SIS	550	3.5	2.45	40
TK4A60D	π-MOSVII	TO-220SIS	600	4	1.7	40
TK4A60DA	π-MOSVII	TO-220SIS	600	3.5	2.2	40
TK4A60DB	π-MOSVII	TO-220SIS	600	3.7	2	40
TK50F15J1	U-MOSIII	TO-220SM(W)	150	50	0.03	37,38
TK50P03M1	U-MOSVI-H	DPAK	30	50	0.0075	35
TK50P04M1	U-MOSVI-H	DPAK	40	50	0.0087	35
TK50X15J1	U-MOSIII-H	TFP	150	50	0.03	39
TK55A10J1	U-MOSIII-H	TO-220SIS	100	55	0.0105	39
TK55D10J1	U-MOSIII-H	TO-220(W)	100	55	0.0105	39
TK5A50D	π-MOSVII	TO-220SIS	500	5	1.5	40
TK5A53D	π-MOSVII	TO-220SIS	525	5	1.5	40
TK5A55D	π-MOSVII	TO-220SIS	550	5	1.88	40
TK5A65D	π-MOSVII	TO-220SIS	650	5	1.45	40
TK60A08J1	U-MOSIII-H	TO-220SIS	75	60	0.0078	39
TK60D08J1	U-MOSIII-H	TO-220(W)	75	60	0.0078	39
TK6A50D	π-MOSVII	TO-220(W)	500	6	1.4	40
TK6A53D	π-MOSVII	TO-220SIS	525	6	1.3	40
TK6A55DA	π-MOSVII	TO-220SIS	550	5.5	1.48	40
TK6A60D	π-MOSVII	TO-220SIS	600	6	1.25	40
TK6A65D	π-MOSVII	TO-220SIS	650	6	1.11	40
TK6P53D	π-MOSVII	DPAK	525	6	1.3	40
TK70A06J1	U-MOSIII-H	TO-220SIS	60	70	0.0064	39
TK70D06J1	U-MOSIII-H	TO-220(W)	60	70	0.0064	39
TK70J04J3	U-MOSIII	TO-3P(N)	40	70	0.0038	38
TK70X04K3	U-MOSIV	TFP	40	70	0.0056	38
TK70X04K3L	U-MOSIV	TFP	40	70	0.0056	–
TK70X04K3Z	U-MOSIV	TFP	40	70	0.0056	38
TK70X06K3	U-MOSIV	TFP	60	70	0.008	38
TK7A50D	π-MOSVII	TO-220SIS	500	7	1.22	40
TK80A08K3	U-MOSIV	TO-220SIS	75	80	0.0045	39
TK80D08K3	U-MOSIV	TO-220(W)	75	80	0.0045	39
TK80X04K3	U-MOSIV	TFP	40	80	0.0035	38
TK8A50D	π-MOSVII	TO-220SIS	500	8	0.85	40
TK8A50DA	π-MOSVII	TO-220SIS	500	7.5	1.0	40
TK8A55DA	π-MOSVII	TO-220SIS	550	7.5	1.07	40
TK8A60DA	π-MOSVII	TO-220SIS	600	7.5	1	40
TK8A65D	π-MOSVII	TO-220SIS	650	8	0.84	40
TK9A55DA	π-MOSVII	TO-220SIS	550	8.5	0.86	40
TPC6004	U-MOSIII	VS-6	20	6	0.024	31
TPC6005	U-MOSIII	VS-6	30	6	0.028	31
TPC6006-H	U-MOSIII-H	VS-6	40	3.9	0.075	24,31
TPC6007-H	U-MOSIII-H	VS-6	30	5	0.054	24,31
TPC6011	U-MOSIV	VS-6	30	6	0.020	31
TPC6103	U-MOSIII	VS-6	–12	–5.5	0.035	31
TPC6105	U-MOSIII	VS-6	–20	–2.7	0.11	31
TPC6107	U-MOSIV	VS-6	–20	–4.5	0.055	31
TPC6108	U-MOSIV	VS-6	–30	–4.5	0.06	31
TPC6109-H	U-MOSIII-H	VS-6	–30	–5	0.059	24,31
TPC6111	U-MOSV	VS-6	–20	–5.5	0.04	31
TPC6201	U-MOSII	VS-6	30	2.5	0.095	–
TPC8012-H	π-MOSV	SOP-8	200	1.8	0.4	34
TPC8014	U-MOSIII	SOP-8	30	11	0.014	27
TPC8017-H	U-MOSIII-H	SOP-8	30	15	0.0066	–

Part Number	Series	Package	Main Characteristics			Page
			V_{DSS} (V)	I_D (A)	$R_{DS(ON)}$ Max (Ω)	
TPC8018-H	U-MOSIII-H	SOP-8	30	18	0.0046	–
TPC8020-H	U-MOSIII-H	SOP-8	30	13	0.009	–
TPC8021-H	U-MOSIII-H	SOP-8	30	11	0.017	24,33
TPC8022-H	U-MOSIII-H	SOP-8	40	7.5	0.027	24,34
TPC8025	U-MOSIV	SOP-8	30	11	0.009	27,33
TPC8026	U-MOSIV	SOP-8	30	13	0.0066	27,33
TPC8027	U-MOSIV	SOP-8	30	18	0.0027	27,34
TPC8028	U-MOSIV	SOP-8	30	18	0.0043	27,34
TPC8029	U-MOSIV	SOP-8	30	18	0.0038	27,34
TPC8030	U-MOSIV	SOP-8	30	11	0.0095	27,33
TPC8031-H	U-MOSV-H	SOP-8	30	11	0.0133	24
TPC8032-H	U-MOSV-H	SOP-8	30	15	0.0065	24,33
TPC8033-H	U-MOSV-H	SOP-8	30	17	0.0053	24,33
TPC8034-H	U-MOSV-H	SOP-8	30	18	0.0035	24,34
TPC8035-H	U-MOSVI-H	SOP-8	30	18	0.0032	24,34
TPC8036-H	U-MOSVI-H	SOP-8	30	18	0.0045	24,34
TPC8037-H	U-MOSV-H	SOP-8	30	12	0.0114	24,33
TPC8038-H	U-MOSV-H	SOP-8	30	12	0.0114	24,33
TPC8039-H	U-MOSVI-H	SOP-8	30	17	0.006	24,33
TPC8040-H	U-MOSVI-H	SOP-8	30	13	0.0097	24,33
TPC8045-H	U-MOSVI-H	SOP-8	40	18	0.0039	24,34
TPC8046-H	U-MOSVI-H	SOP-8	40	18	0.0057	24,34
TPC8047-H	U-MOSVI-H	SOP-8	40	16	0.0076	24,34
TPC8048-H	U-MOSVI-H	SOP-8	60	16	0.0069	25,34
TPC8049-H	U-MOSVI-H	SOP-8	60	13	0.0107	25,34
TPC8050-H	U-MOSVI-H	SOP-8	60	11	0.0145	25,34
TPC8051-H	U-MOSVI-H	SOP-8	80	13	0.0097	25,34
TPC8052-H	U-MOSVI-H	SOP-8	40	12	0.0115	24,34
TPC8053-H	U-MOSVI-H	SOP-8	60	9	0.0225	25,34
TPC8107	U-MOSIII	SOP-8	–30	–13	0.007	–
TPC8109	U-MOSIII	SOP-8	–30	–10	0.02	–
TPC8110	U-MOSIII	SOP-8	–40	–8	0.025	34
TPC8111	U-MOSIV	SOP-8	–30	–11	0.012	34
TPC8112	U-MOSIII	SOP-8	–30	–13	0.006	–
TPC8113	U-MOSIV	SOP-8	–30	–11	0.01	27,34
TPC8114	U-MOSIV	SOP-8	–30	–18	0.0045	27,34
TPC8115	U-MOSIV	SOP-8	–20	–10	0.01	27,34
TPC8116-H	U-MOSIII-H	SOP-8	–40	–7.5	0.03	25,34
TPC8117	U-MOSV	SOP-8	–30	–18	0.0039	27,34
TPC8118	U-MOSV	SOP-8	30	13	0.007	27,34
TPC8120	U-MOSVI	SOP-8	–30	–18	0.0032	27,34
TPC8122	U-MOSV	SOP-8	–30	–11	0.008	27,34
TPC8123	U-MOSVI	SOP-8	–30	–11	0.0095	27,34
TPC8207	U-MOSIII	SOP-8	20	6	0.02	27,34
TPC8208	U-MOSIII	SOP-8	20	5	0.05	27,34
TPC8210	U-MOSIII	SOP-8	30	8	0.015	27,34
TPC8211	U-MOSIII	SOP-8	30	5.5	0.036	27,34
TPC8212-H	U-MOSIII-H	SOP-8	30	6	0.021	34
TPC8213-H	U-MOSIII-H	SOP-8	60	5	0.05	25,34
TPC8214-H	U-MOSIII-H	SOP-8	100	2.2	0.18	25,34
TPC8218-H	U-MOSVI-H	SOP-8	60	3.8	0.057	25,34
TPC8404	π-MOSV/π-MOSV	SOP-8	–250/250	1.1/–0.9	1.7/2.55	34
TPC8405	U-MOSIV/U-MOSIII	SOP-8	–30/30	–4.5/6	0.027	27,34
TPC8406-H	U-MOSIII-H	SOP-8	40	6.5	0.03	25,34
TPC8406-H	U-MOSIII-H	SOP-8	–40	–6.5	0.025	25,34
TPC8A01	High-speed U-MOSIII	SOP-8	30	6	0.018	34

Part Number	Series	Package	Main Characteristics			Page
			V_{DSS} (V)	I_D (A)	$R_{DS(ON)}$ Max (Ω)	
TPC8A01	U-MOSIII	SOP-8	30	8.5/1	0.0056	34
TPC8A02-H	U-MOSIII-H	SOP-8	30	16/1	0.0056	–
TPC8A03-H	U-MOSV-H	SOP-8	30	17/1	0.0036	25,34
TPC8A04-H	U-MOSV-H	SOP-8	30	18/1	0.0133	25,34
TPC8A05-H	U-MOSV-H	SOP-8	30	10/1	0.0066	25,34
TPC8A06-H	U-MOSV-H	SOP-8	30	12	0.0101	25,34
TPCA8003-H	U-MOSIII-H	SOP Advance	30	35	0.0046	–
TPCA8004-H	U-MOSIII-H	SOP Advance	30	40	0.009	–
TPCA8005-H	U-MOSIII-H	SOP Advance	30	27	0.067	–
TPCA8006-H	π-MOSVII	SOP Advance	100	18	0.58	35
TPCA8008-H	π-MOSV	SOP Advance	250	4	0.35	25,35
TPCA8009-H	π-MOSV	SOP Advance	150	7	0.45	25,35
TPCA8010-H	π-MOSV	SOP Advance	200	5.5	0.0035	25,35
TPCA8011-H	U-MOSIII-H	SOP Advance	20	40	0.0049	24,35
TPCA8012-H	U-MOSV-H	SOP Advance	30	35	0.0049	24,35
TPCA8014-H	U-MOSIII-H	SOP Advance	40	30	0.0054	24,35
TPCA8015-H	U-MOSIII-H	SOP Advance	40	35	0.021	24,35
TPCA8016-H	U-MOSIII-H	SOP Advance	60	25	0.0062	25,35
TPCA8018-H	U-MOSV-H	SOP Advance	30	27	0.0031	24,35
TPCA8019-H	U-MOSV-H	SOP Advance	30	40	0.027	24,35
TPCA8020-H	U-MOSIII-H	SOP Advance	40	7.5	0.027	24,35
TPCA8022-H	U-MOSIII-H	SOP Advance	100	22	0.026	25,35
TPCA8023-H	U-MOSV-H	SOP Advance	30	21	0.0129	24
TPCA8024	U-MOSIV	SOP Advance	30	35	0.0043	27,35
TPCA8025	U-MOSIV	SOP Advance	30	40	0.0036	27,35
TPCA8026	U-MOSIV	SOP Advance	30	45	0.0022	27,35
TPCA8027-H	U-MOSIII	SOP Advance	40	30	0.01	24,35
TPCA8028-H	U-MOSVI-H	SOP Advance	30	50	0.0028	24,35
TPCA8030-H	U-MOSV-H	SOP Advance	30	24	0.011	24,35
TPCA8031-H	U-MOSV-H	SOP Advance	30	24	0.011	24,35
TPCA8036-H	U-MOSVI-H	SOP Advance	30	38	0.0042	24,35
TPCA8039-H	U-MOSVI-H	SOP Advance	30	34	0.0057	24,35
TPCA8040-H	U-MOSVI-H	SOP Advance	30	23	0.0094	24,35
TPCA8045-H	U-MOSVI-H	SOP Advance	40	46	0.0036	24,35
TPCA8046-H	U-MOSVI-H	SOP Advance	40	38	0.0054	24,35
TPCA8047-H	U-MOSVI-H	SOP Advance	40	32	0.0073	24,35
TPCA8048-H	U-MOSVI-H	SOP Advance	60	35	0.0066	25,35
TPCA8049-H	U-MOSVI-H	SOP Advance	60	28	0.0104	25,35
TPCA8050-H	U-MOSVI-H	SOP Advance	60	24	0.0142	25,35
TPCA8051-H	U-MOSVI-H	SOP Advance	80	28	0.0094	25,35
TPCA8052-H	U-MOSVI-H	SOP Advance	40	20	0.0113	24,35
TPCA8053-H	U-MOSVI-H	SOP Advance	60	15	0.0223	25,35
TPCA8060-H	U-MOSVI-H	SOP Advance	30	45	0.0034	24,35
TPCA8101	U-MOSIII	SOP Advance	–30	–40	0.007	–
TPCA8102	U-MOSIII	SOP Advance	–30	–40	0.006	–
TPCA8103	U-MOSIV	SOP Advance	–30	–40	0.0042	27,35
TPCA8104	U-MOSIII	SOP Advance	–60	–40	0.016	35,38
TPCA8105	U-MOSIII	SOP Advance	–12	–6	0.0033	27,35
TPCA8106	U-MOSV	SOP Advance	–30	–40	0.0037	27,35
TPCA8107-H	U-MOSIII-H	SOP Advance	–40	–7.5	0.03	25,35
TPCA8108	U-MOSIII	SOP Advance	–40	–40	0.0095	35
TPCA8A01-H	U-MOSIII-H	SOP Advance	30	36	0.0056	–
TPCA8A02-H	U-MOSV-H	SOP Advance	30	34	0.0053	25,35
TPCA8A04-H	U-MOSV-H	SOP Advance	30	44	0.0032	25,35
TPCA8A05-H	U-MOSV-H	SOP Advance	30	10	0.0129	25,35
TPCA8A08-H	U-MOSV-H	SOP Advance	30	38	0.0042	25,35

Part Number	Series	Package	Main Characteristics			Page
			V_{DSS} (V)	I_D (A)	$R_{DS(ON)}$ Max (Ω)	
TPCC8001-H	U-MOSV-H	TSON Advance	30	22	0.0083	24,33
TPCC8002-H	U-MOSV-H	TSON Advance	30	22	0.0083	24,33
TPCC8003-H	U-MOSIV-H	TSON Advance	30	13	0.0169	24,33
TPCC8005-H	U-MOSV-H	TSON Advance	30	26	0.0064	24,33
TPCC8006-H	U-MOSIV-H	TSON Advance	30	22	0.008	24,33
TPCC8007	U-MOSIV	TSON Advance	20	27	(0.0046)	27,33
TPCC8008	U-MOSIV	TSON Advance	30	25	0.0068	27,33
TPCC8102	U-MOSV	TSON Advance	–30	–15	0.0189	27,33
TPCC8103	U-MOSV	TSON Advance	–30	–18	0.012	27,33
TPCC8A01-H	U-MOSV-H	TSON Advance	30	21	0.0099	25,33
TPCF8002	U-MOSIV	VS-8	30	7	0.023	31
TPCF8101	U-MOSIII	VS-8	–12	–6	0.028	31
TPCF8102	U-MOSIII	VS-8	–20	–6	0.03	31
TPCF8103	U-MOSIII	VS-8	–20	–2.7	0.11	31
TPCF8104	U-MOSIII	VS-8	–30	–6	0.028	31
TPCF8201	U-MOSIII	VS-8	20	3	0.049	31
TPCF8301	U-MOSIII	VS-8	–20	–2.7	0.11	31
TPCF8302	U-MOSIII	VS-8	–20	–3	0.059	31
TPCF8303	U-MOSIII	VS-8	–20	–3	0.058	31
TPCF8304	U-MOSIV	VS-8	–30	–3.2	0.072	31
TPCF8402	U-MOSIII	VS-8	–30/30	–3.2/4	0.072/0.05	31
TPCF8A01	U-MOSIII	VS-8	20	3	0.049	31
TPCF8B01	U-MOSIII	VS-8	–20	–2.7	0.11	31
TPCL4201	U-MOSV	Chip LGA	20	6	0.031	27,32
TPCL4202	U-MOSV	Chip LGA	30	6	0.04	27,32
TPCL4203	U-MOSV	Chip LGA	24	6	0.036	27,32
TPCM8001-H	U-MOSIII-H	TSSOP Advance	30	20	0.0095	33
TPCM8002-H	U-MOSV-H	TSSOP Advance	30	30	0.0062	24,33
TPCM8003-H	U-MOSV-H	TSSOP Advance	30	21	0.0129	24,33
TPCM8004-H	U-MOSV-H	TSSOP Advance	30	24	0.011	24,33
TPCM8A05-H	U-MOSV-H	TSSOP Advance	30	20	0.0129	25,33
TPCP8001-H	U-MOSIII-H	PS-8	30	7.2	0.016	32
TPCP8003-H	U-MOSIII-H	PS-8	100	2.2	0.19	25,32
TPCP8004	U-MOSIV	PS-8	30	8.3	0.009	27,32
TPCP8005-H	U-MOSV-H	PS-8	30	11	0.0133	24,32
TPCP8006	U-MOSIV	PS-8	20	9.1	0.01	27,32
TPCP8101	U-MOSIII	PS-8	–20	–5.6	0.03	32
TPCP8102	U-MOSIV	PS-8	–20	–7.6	0.018	32
TPCP8103-H	U-MOSIII-H	PS-8	–40	–4.8	0.04	25,32
TPCP8201	U-MOSIII	PS-8	30	4.2	0.05	32
TPCP8202	U-MOSIV	PS-8	30	5.5	0.023	27,32
TPCP8203	U-MOSIII	PS-8	40	4.7	0.04	32
TPCP8301	U-MOSIV	PS-8	–20	–5	0.031	32
TPCP8302	U-MOSIV	PS-8	–20	–5	0.033	32
TPCP8303	U-MOSV	PS-8	–20	–3.8	0.04	32
TPCP8401	U-MOSIII	PS-8	–12/20	–5.5/0.1	0.038/3	32
TPCP8402	U-MOSIII	PS-8	–30/30	–3.4/4.2	0.048/0.072	32
TPCP8403	U-MOSIV/U-MOSIII	PS-8	–40/40	–3.4/4.7	0.170/0.040	32
TPCP8404	U-MOSV/U-MOSIV	PS-8	–30/30	–4/4	0.05/0.05	32
TPCP8A05-H	U-MOSV-H	PS-8	30	8	0.0175	32
TPCP8AA1	U-MOSII	PS-8	20	1.6	0.105	32
TPCP8BA1	U-MOSII	PS-8	–20	–1.3	0.18	32
TPCP8J01	U-MOSIV	PS-8	–32/50	–6/0.1	0.035	32
TPCT4203	U-MOSIV	STP2	20	6	0.031	27,32
TPCT4204	U-MOSIV	STP2	30	6	0.038	27,32

8 Product Obsolescence

8-1 End-of-Life Products

The part numbers in the left-hand column below are end-of-life or obsolete products. When ordering, please choose from the replacement products in the right-hand column.

End-of-Life Products					Replacement Products				
Part Number	Electrical Characteristics			Package	Part Number	Electrical Characteristics			Package
	V_{DSS} (V)	I_D (A)	$R_{DS(ON)}$ Max(Ω)			V_{DSS} (V)	I_D (A)	$R_{DS(ON)}$ Max(Ω)	
2SJ148	–60	–0.2	2	TO-92	**2SJ168**	–60	–0.2	2	S-MINI
2SJ167	–60	–0.2	2	N-MINI	**2SJ168**	–60	–0.2	2	S-MINI
2SJ200	–16	–2	0.71	PW-Mini	**TPC6105**	–20	–2.7	0.11	VS-6
2SJ342	–50	–0.05	50	N-MINI	**2SJ343**	–50	–0.05	50	S-MINI
2SJ345	–20	–0.05	40	S-MINI	**SSM3J16FU**	–20	–0.1	45	USM
2SJ346	–20	–0.05	40	USM	**SSM3J16FU**	–20	–0.1	45	USM
2SJ347	–20	–0.05	40	SSM	**SSM3J16FS**	–20	–0.1	45	SSM
2SJ511	–30	–2	0.76	PW-Mini	**TPC6108**	–30	–4.5	0.006	VS-6
2SJ525	–30	–5	0.12	TPS	**TPCF8104**	–30	–6	0.028	VS-8
2SK1061	60	0.2	1	N-MINI	**SSM3K7002BF**	60	0.2	2.1	S-MINI
2SK1120	1000	8	1.8	TO-3P (N)	**2SK2613**	1000	8	1.7	TO-3P (N)
2SK1825	50	0.05	50	N-MINI	**SSM3K7002BF**	60	0.2	2.1	S-MINI
2SK1826	50	0.05	50	S-MINI	**SSM3K7002BF**	60	0.2	2.1	S-MINI
2SK1827	50	0.05	50	USM	**SSM3K7002BFU**	60	0.2	2.1	USM
2SK1828	20	0.05	40	S-MINI	**SSM3K15F**	30	0.1	7	S-MINI
2SK1829	20	0.05	40	USM	**SSM3K15FU**	30	0.1	7	USM
2SK1830	20	0.05	40	SSM	**SSM3K15FS**	30	0.1	7	SSM
2SK2033	20	0.1	12	S-MINI	**SSM3K15F**	30	0.1	7	S-MINI
2SK2034	20	0.1	12	USM	**SSM3K15FU**	30	0.1	7	USM
2SK2035	20	0.1	12	SSM	**SSM3K15FS**	30	0.1	7	SSM
2SK2036	20	0.1	6	S-MINI	**SSM3K15F**	30	0.1	7	S-MINI
2SK2037	20	0.1	6	USM	**SSM3K15FU**	30	0.1	7	USM
2SK2312	60	45	0.017	TO-220NIS	**2SK3844**	60	45	0.0058	TO-220NIS
2SK2466	100	30	0.046	TO-220NIS	**TK40A10K3**	100	40	0.015	TO-220SIS
2SK2543	500	8	0.85	TO-220NIS	**TK8A50D**	500	8	0.85	TO-220SIS
2SK2544	600	6	1.25	TO-220AB	**2SK3761**	600	6	1.25	TO-220AB
2SK2545	600	6	1.25	TO-220NIS	**TK6A60D**	600	6	1.25	TO-220SIS
2SK2549	16	2	0.29	PW-Mini	**TPC6004**	20	6	0.024	VS-6
2SK2604	800	5	2.2	TO-3P (N)	**2SK3633**	800	7	1.7	TO-3P (N)
2SK2605	800	5	2.2	TO-220NIS	**2SK4013**	800	6	1.7	TO-220SIS
2SK2610	900	5	2.5	TO-3P (N)	**2SK3700**	900	5	2.5	TO-3P (N)
2SK2611	900	9	1.4	TO-3P (N)	**2SK3878**	900	9	1.3	TO-3P (N)
2SK2661	500	5	1.5	TO-220AB	**2SK3758**	500	5	1.5	TO-220AB
2SK2662	500	5	1.5	TO-220NIS	**TK5A50D**	500	5	1.5	TO-220SIS
2SK2698	500	15	0.4	TO-3P (N)	**TK15J50D**	500	15	0.4	TO-3P (N)
2SK2700	900	3	4.3	TO-220NIS	**2SK3564**	900	3	4.3	TO-220SIS
2SK2717	900	5	2.5	TO-220NIS	**2SK3565**	900	5	2.5	TO-220SIS
2SK2718	900	2.5	6.4	TO-220NIS	**2SK3566**	900	2.5	6.4	TO-220SIS
2SK2746	800	7	1.7	TO-3P (N)	**2SK3633**	800	7	1.7	TO-3P (N)
2SK2749	900	7	2	TO-3P (N)	**2SK4115**	900	7	2	TO-3P (N)
2SK2750	600	3.5	2.2	TO-220NIS	**TK4A60DA**	600	3.5	2.2	TO-220SIS
2SK2823	20	0.1	40	S-MINI	**SSM3K35FS**	20	0.18	20	SSM
2SK2824	20	0.1	40	USM	**SSM3K35FS**	20	0.18	20	SSM
2SK2825	20	0.1	40	SSM	**SSM3K35FS**	20	0.18	20	SSM
2SK2837	500	20	0.27	TO-3P (N)	**TK20J50D**	500	20	0.27	TO-3P (N)
2SK2842	500	12	0.52	TO-220NIS	**TK12A50D**	500	12	0.52	TO-220SIS
2SK2843	600	10	0.75	TO-220NIS	**TK10A60D**	600	10	0.75	TO-220SIS
2SK2844	30	35	0.02	TO-220AB	**TK70D06J1**	60	70	0.0064	TO-220 (W)
2SK2915	600	16	0.4	TO-3P (N)	**2SK3903**	600	14	0.44	TO-3P (N)
2SK2996	600	10	1	TO-220NIS	**2SK4112**	600	10	1	TO-220HIS

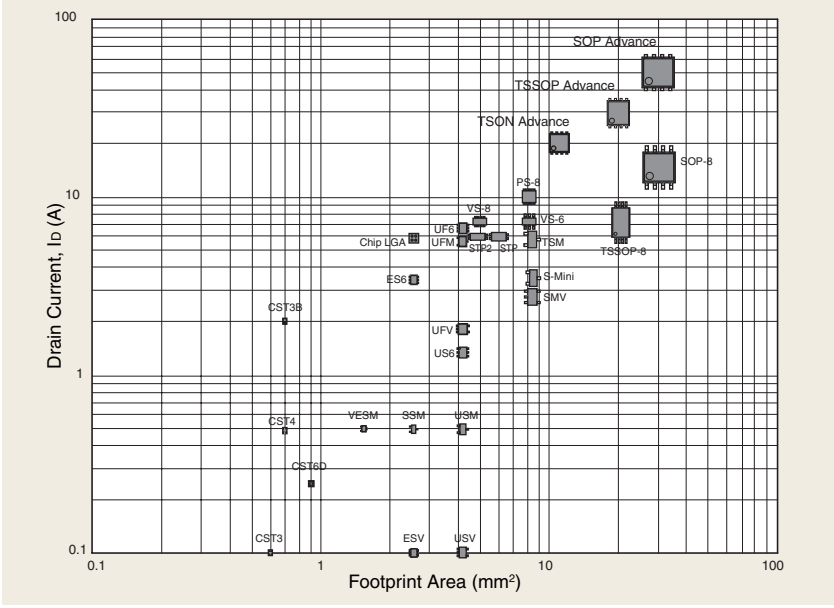
8 Product Obsolescence

End-of-Life Products					Replacement Products				
Part Number	Electrical Characteristics			Package	Part Number	Electrical Characteristics			Package
	V_{DSS} (V)	I_D (A)	$R_{DS(ON)}$ Max(Ω)			V_{DSS} (V)	I_D (A)	$R_{DS(ON)}$ Max(Ω)	
2SK2964	30	2	0.18	PW-Mini	**TPC6003**	30	6	0.024	VS-6
2SK3067	600	2	5	TO-220NIS	**2SK3767**	600	2	4.5	TO-220SIS
2SK3084	100	30	0.046	TO-220FL/SM	–	–	–	–	–
2SK3089	30	40	0.03	TO-220FL/SM	**2SK3847**	40	32	0.018	TO-220SM
2SK3090	30	45	0.02	TO-220FL/SM	**2SK3847**	40	32	0.018	TO-220SM
2SK3125	30	70	0.007	TO-3PSM	**2SK3843**	40	75	0.0035	TFP
2SK3126	450	10	0.65	TO-220NIS	**2SK3869**	450	10	0.68	TO-220SIS
2SK3127	30	45	0.012	TO-220FL/SM	**2SK3847**	40	32	0.018	TO-220SM
2SK3128	30	60	0.012	TO-3P (N)	**2SK3843**	40	75	0.0035	TFP
2SK3129	50	60	0.007	TO-3P (N)	**2SK3845**	60	70	0.0058	TO-3P (N)
2SK3130	600	6	1.55	TO-220NIS	**2SK3947**	600	6	1.4	TO-220SIS
2SK3236	60	35	0.02	TO-220NIS	**2SK3662**	60	35	0.0125	TO-220NIS
2SK3316	500	5	1.8	TO-220NIS	**2SK3868**	500	5	1.7	TO-220NIS
2SK3389	30	75	0.005	TFP	**2SK3843**	40	75	0.008	TFP
2SK3397	30	75	0.006	TFP	**2SK3843**	40	75	0.0035	TFP
2SK3407	450	10	0.65	TO-220NIS	**2SK3869**	450	10	0.68	TO-220SIS
2SK3439	30	75	0.005	TFP	**2SK3843**	40	75	0.0035	TFP
2SK3440	60	50	0.008	TFP	**2SK3842**	60	75	0.0058	TFP
2SK3441	60	75	0.0058	TFP	**2SK4034**	60	75	0.0058	TFP
2SK3442	100	45	0.02	TFP	**TK40D10J1**	100	40	0.015	TO-220 (W)
2SK3443	150	30	0.055	TFP	**TK50X15J1**	150	50	0.03	TFP
2SK3499	400	10	0.55	TFP	**TK10X40D***	400	10	0.55	TFP
2SK3543	450	2	2.45	TO-220NIS	**2SK3757**	450	2	2.45	TO-220SIS
2SK982	60	0.2	1	TO-92	**SSM3K7002BF**	60	0.2	2.1	S-MINI
HN1J02FU	–20	–0.05	40	US6	**SSM6P16FU**	–20	–0.1	45	US6
HN1K02FU	20	0.05	40	US6	**SSM6N16FU**	20	0.1	15	US6
HN1K03FU	20	0.1	12	US6	**SSM6N16FU**	20	0.1	15	US6
HN1K04FU	50	0.05	50	US6	**SSM6K7002BFU**	60	0.2	2.1	US6
HN1K05FU	20	0.1	40	US6	**SSM6N35FU**	20	0.18	20	US6
HN1K06FU	20	0.1	6	US6	**SSM6N15FU**	30	0.1	7	US6
HN1L02FU	20	0.05	40	US6	**SSM6L35FU**	20	0.18	20	US6
HN1L03FU	50	0.05	50	US6	–	–	–	–	–
HN4K03JU	20	0.1	12	UFV	**SSM5N15FU**	30	0.1	7	USV
SSM3J01F	–30	–0.7	0.6	S-MINI	**SSM3J01T**	–30	–1.7	0.6	TSM
SSM3J02F	–30	–0.6	0.7	S-MINI	**SSM3J02T**	–30	–1.6	0.7	TSM
SSM3J15TE	–30	–0.1	32	TESM	**SSM3J15FV**	–30	–0.1	32	VESM
SSM3J16TE	–20	–0.1	45	TESM	**SSM3J16FV**	–20	–0.1	45	VESM
SSM3K01F	30	1.3	0.15	S-MINI	**SSM3K01T**	30	3.2	0.15	TSM
SSM3K02F	30	1	0.25	S-MINI	**SSM3K02T**	30	2.5	0.25	TSM
SSM3K03C	20	0.1	12	SS-CSP	**SSM3K16CT**	20	0.1	15	CST3
SSM3K03FE	20	0.1	12	ESM	**SSM3K16FS**	20	0.1	15	SSM
SSM3K03TE	20	0.1	12	TESM	**SSM3K16FV**	20	0.1	15	VESM
SSM3K04FE	20	0.1	12	ESM	**SSM3K04FS**	20	0.1	12	SSM
SSM3K126TU	30	3.9	0.043	UFM	**SSM3K131TU**	30	6	0.0415	UFM
SSM3K15TE	30	0.1	7	TESM	**SSM3K15FV**	30	0.1	7	VESM
SSM3K16TE	20	0.1	15	TESM	**SSM3K16FV**	20	0.1	15	VESM
SSM3K302T	30	3	0.071	TSM	**SSM3K316T**	30	4	0.065	TSM
SSM3K311T	30	4.6	0.043	TSM	**SSM3K315T**	30	6	0.0415	TSM
SSM6G06FE	–20	–0.1	45	ES6	–	–	–	–	–
SSM6H06FE	20	0.1	15	ES6	–	–	–	–	–
TPC6106	–40	–3.9	0.08	VS-6	–	–	–	–	–
TPCT4201	20	6	0.031	STP	**TPCT4203**	20	6	0.031	STP2
TPCT4202	30	6	0.038	STP	**TPCT4204**	30	6	0.038	STP2
TPC6201	30	2.5	0.095	VS-6	**TPCP8202**	30	5.5	0.023	PS-8
TPC8301	–30	–3.5	0.12	SOP-8	**TPCF8304**	–30	3.2	0.105	SOP-8
TPC8303	–30	–4.5	0.035	SOP-8	–	–	–	–	–

*: Under development

9-1 Compact Surface-Mount Packages

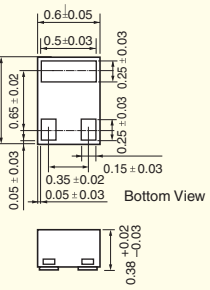
Toshiba offers a broad range of packaging options suitable for various mobile applications, including ultra-small, thin packages; those specifically designed for lithium-ion battery protection circuits; high-current packages with a thermal fin on the bottom.



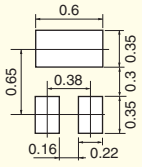
■ CST3

Unit: mm

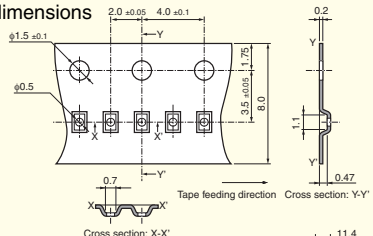
Package dimensions



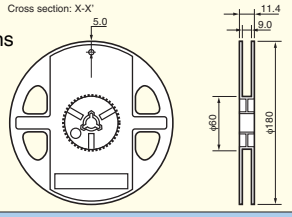
Typical PCB land pad dimensions



Tape dimensions



Reel dimensions

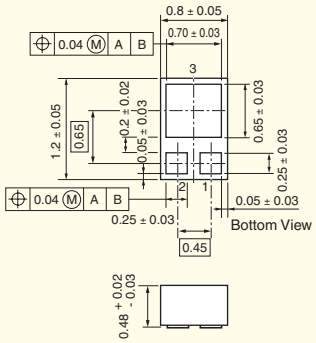


Packing quantity 10000 pcs/reel

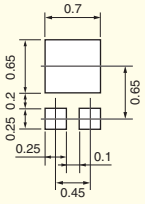
■ CST3B

Unit: mm

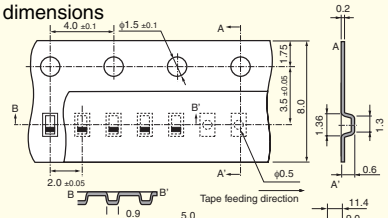
Package dimensions



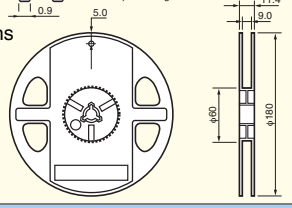
Typical PCB land pad dimensions



Tape dimensions



Reel dimensions



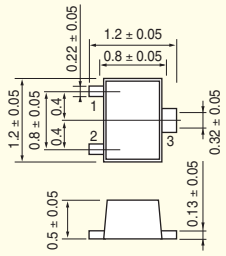
Packing quantity 10000 pcs/reel

9-1 Compact Surface-Mount Packages

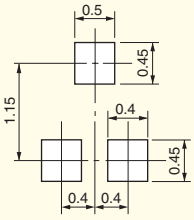
■ VESM (SOT-723)

Unit: mm

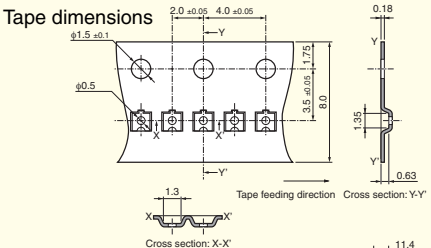
Package dimensions



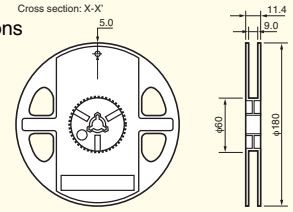
Typical PCB land pad dimensions



Tape dimensions



Reel dimensions

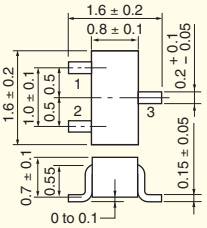


Packing quantity	8000 pcs/reel

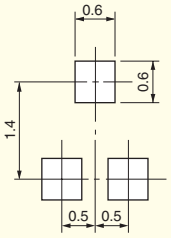
■ SSM (SOT-416)(SC-75)

Unit: mm

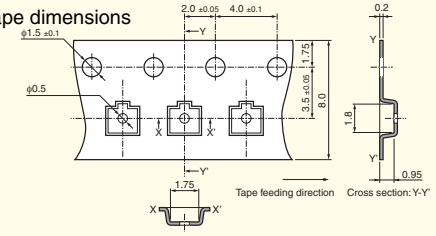
Package dimensions



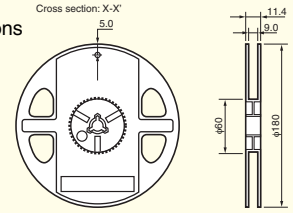
Typical PCB land pad dimensions



Tape dimensions



Reel dimensions

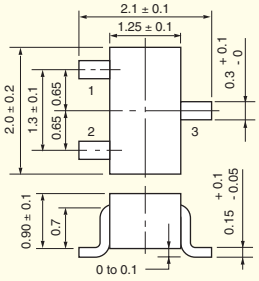


Packing quantity	3000 pcs/reel

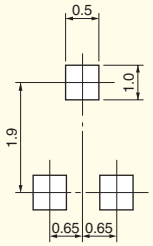
■ USM (SOT-323)(SC-70)

Unit: mm

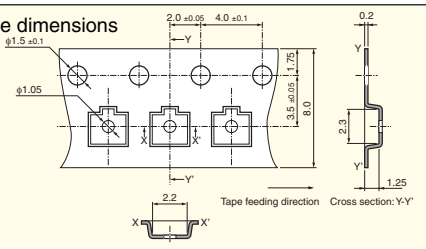
Package dimensions



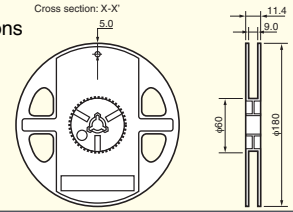
Typical PCB land pad dimensions



Tape dimensions



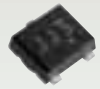
Reel dimensions



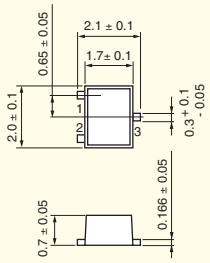
Packing quantity	3000 pcs/reel

■ UFM

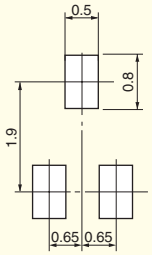
Unit: mm



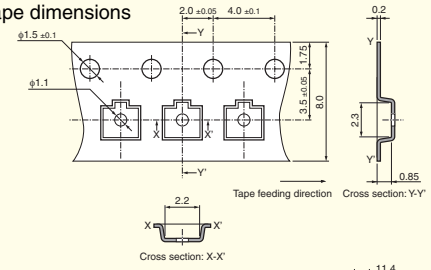
Package dimensions



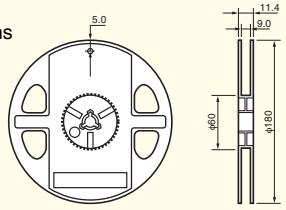
Typical PCB land pad dimensions



Tape dimensions



Reel dimensions

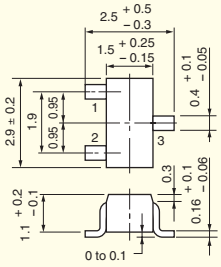


Packing quantity	3000 pcs/reel

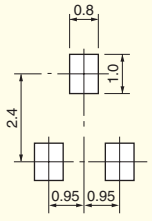
■ S-Mini (SOT-346)(SC-59)

Unit: mm

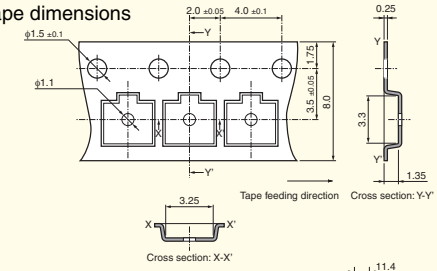
Package dimensions



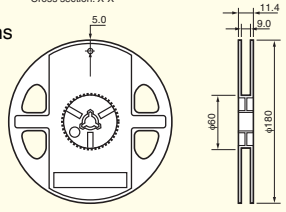
Typical PCB land pad dimensions



Tape dimensions



Reel dimensions

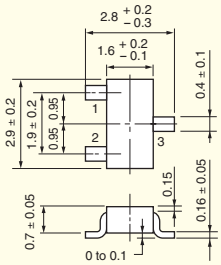


Packing quantity	3000 pcs/reel

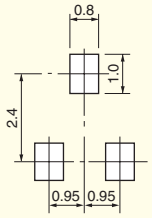
■ TSM

Unit: mm

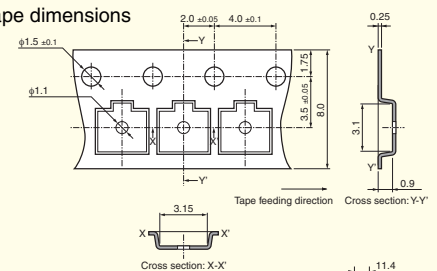
Package dimensions



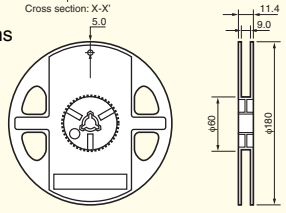
Typical PCB land pad dimensions



Tape dimensions



Reel dimensions

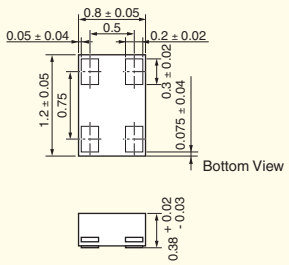


Packing quantity	3000 pcs/reel

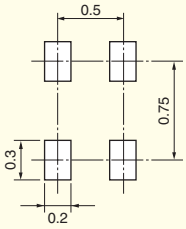
■ CST4

Unit: mm

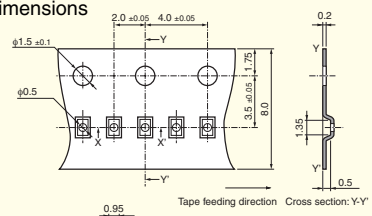
Package dimensions

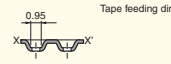


Typical PCB land pad dimensions

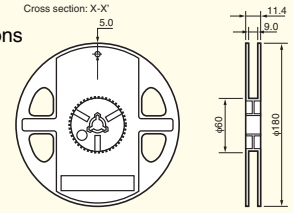


Tape dimensions





Reel dimensions

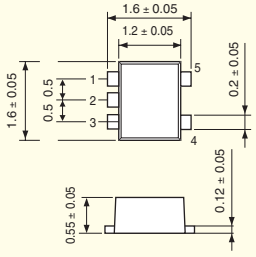


Packing quantity	10000 pcs/reel

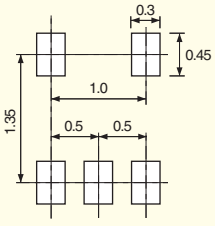
■ ESV (SOT-553)

Unit: mm

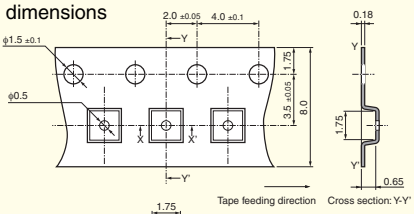
Package dimensions

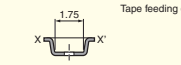


Typical PCB land pad dimensions

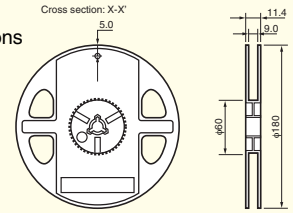


Tape dimensions





Reel dimensions

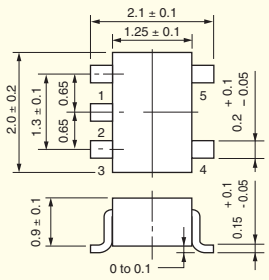


Packing quantity	4000 pcs/reel

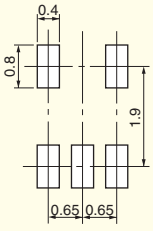
■ USV (SOT-353)(SC-88A)

Unit: mm

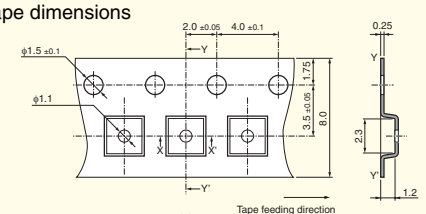
Package dimensions

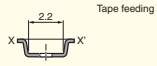


Typical PCB land pad dimensions

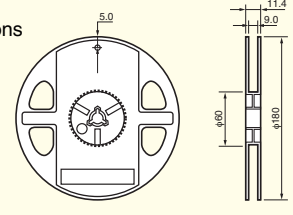


Tape dimensions





Reel dimensions

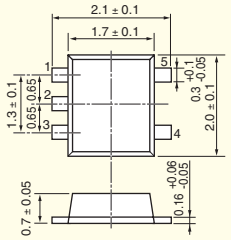


Packing quantity	3000 pcs/reel

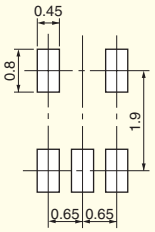
■ UFV

Unit: mm

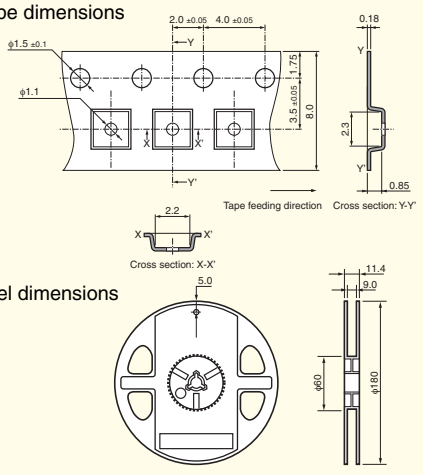
Package dimensions



Typical PCB land pad dimensions



Tape dimensions



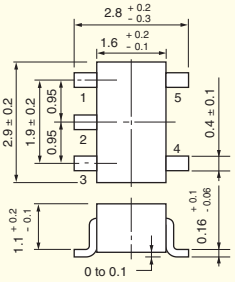
Reel dimensions

Packing quantity	3000 pcs/reel

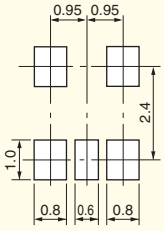
■ SMV (SOT-25)(SC-74A)

Unit: mm

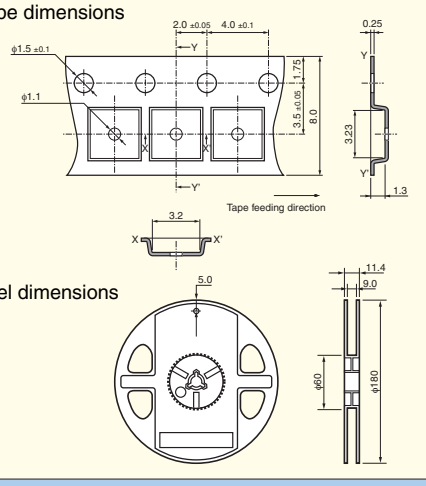
Package dimensions



Typical PCB land pad dimensions



Tape dimensions



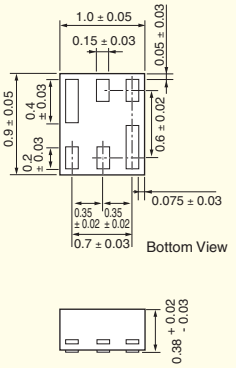
Reel dimensions

Packing quantity	3000 pcs/reel

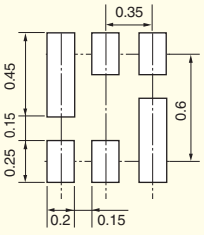
■ CST6D

Unit: mm

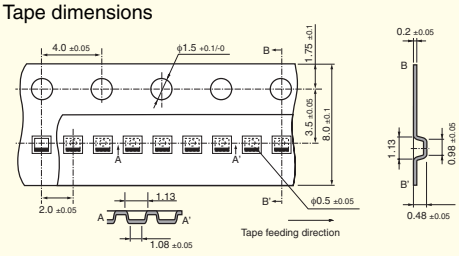
Package dimensions



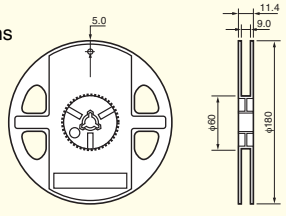
Typical PCB land pad dimensions



Tape dimensions



Reel dimensions

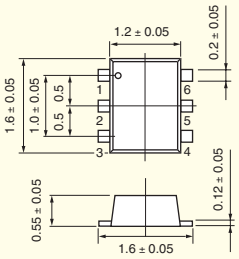


Packing quantity	10000 pcs/reel

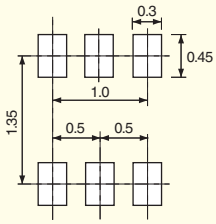
■ ES6 (SOT-563)

Unit: mm

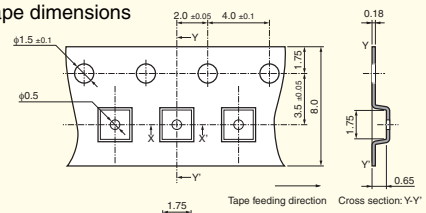
Package dimensions



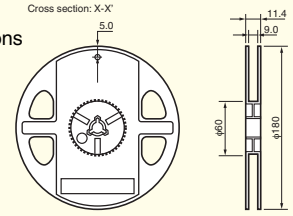
Typical PCB land pad dimensions



Tape dimensions



Reel dimensions

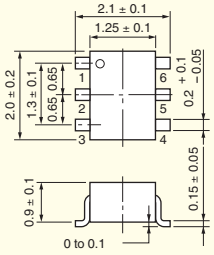


Packing quantity	4000 pcs/reel

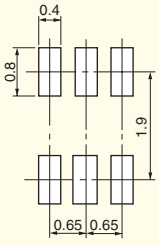
■ US6 (SOT-363)(SC-88)

Unit: mm

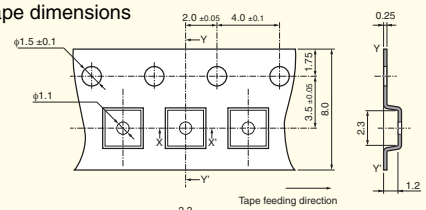
Package dimensions



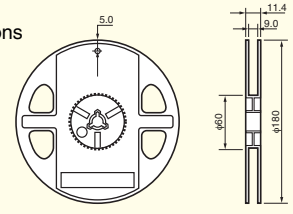
Typical PCB land pad dimensions



Tape dimensions



Reel dimensions

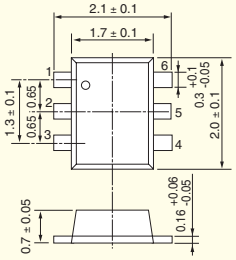


Packing quantity	3000 pcs/reel

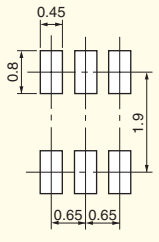
■ UF6

Unit: mm

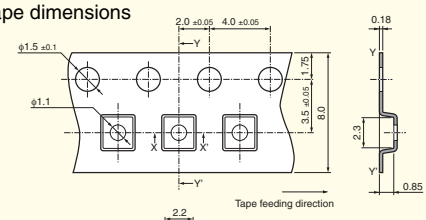
Package dimensions



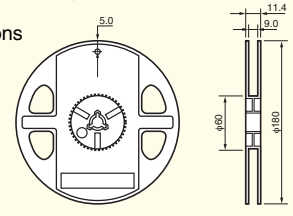
Typical PCB land pad dimensions



Tape dimensions



Reel dimensions

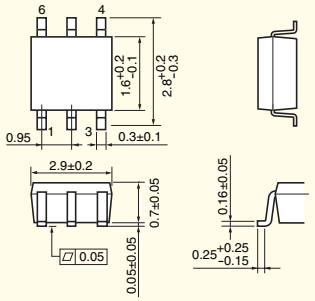


Packing quantity	3000 pcs/reel

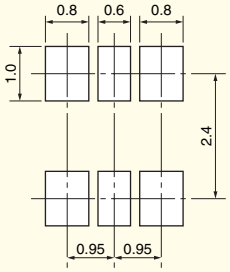
■ VS-6

Unit: mm

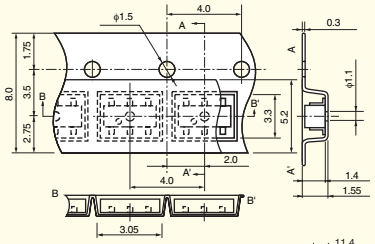
Package dimensions



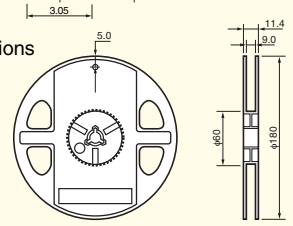
Typical PCB land pad dimensions



Tape dimensions



Reel dimensions

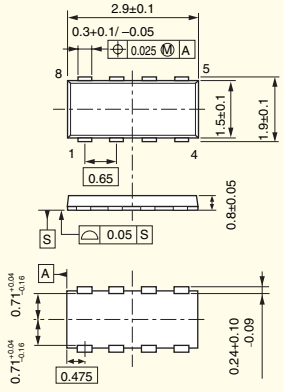


Packing quantity	3000 pcs/reel

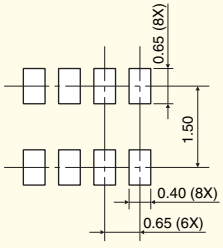
■ VS-8

Unit: mm

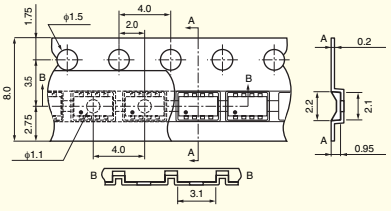
Package dimensions



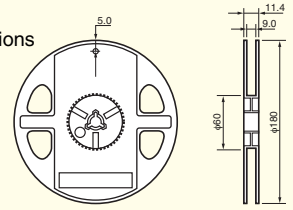
Typical PCB land pad dimensions



Tape dimensions



Reel dimensions

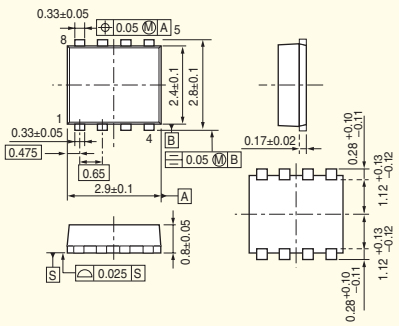


Packing quantity	4000 pcs/reel

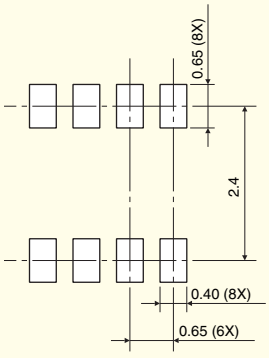
■ PS-8

Unit: mm

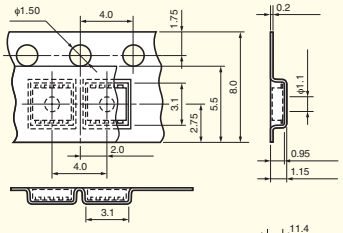
Package dimensions



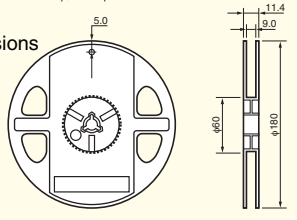
Typical PCB land pad dimensions



Tape dimensions



Reel dimensions

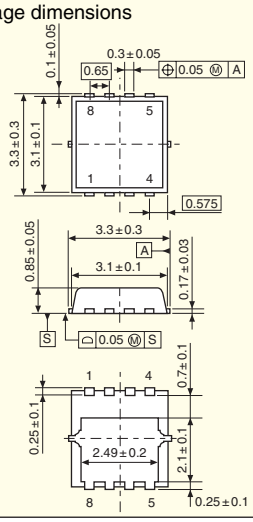


Packing quantity	3000 pcs/reel

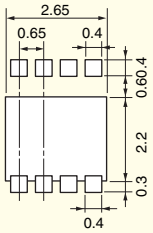
■ TSON

Unit: mm

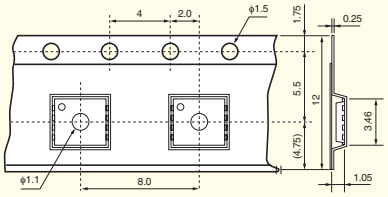
Package dimensions



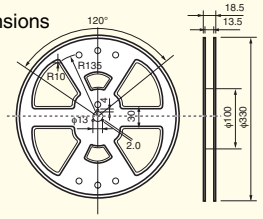
Typical PCB land pad dimensions



Tape dimensions



Reel dimensions

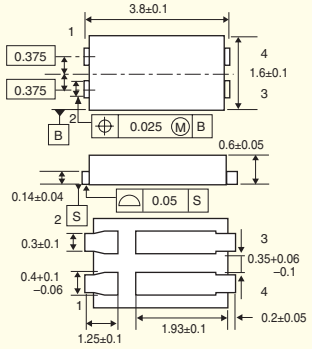


Packing quantity	3000 pcs/reel

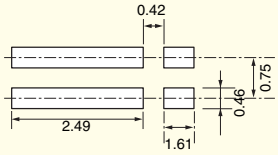
■ STP2

Unit: mm

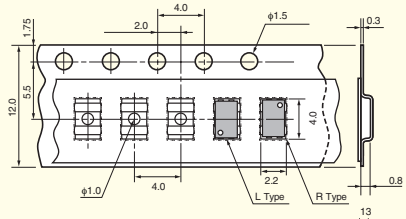
Package dimensions



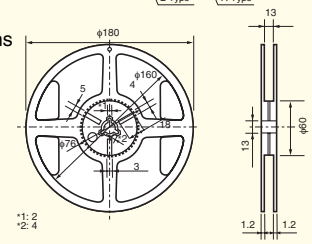
Typical PCB land pad dimensions



Tape dimensions



Reel dimensions

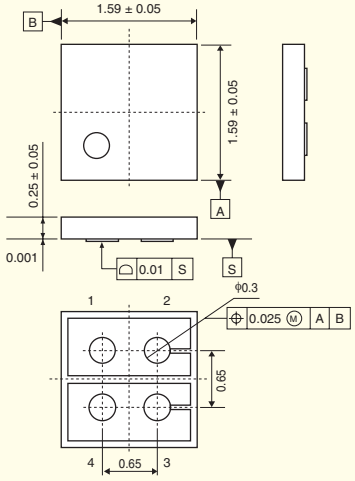


Packing quantity	4000 pcs/reel

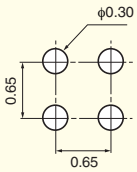
■ Chip LGA

Unit: mm

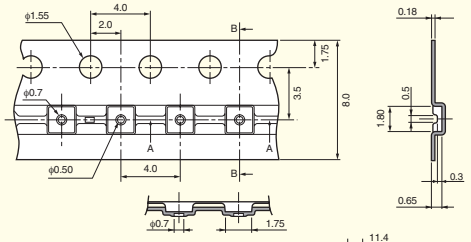
Package dimensions



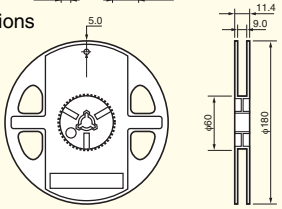
Typical PCB land pad dimensions



Tape dimensions



Reel dimensions

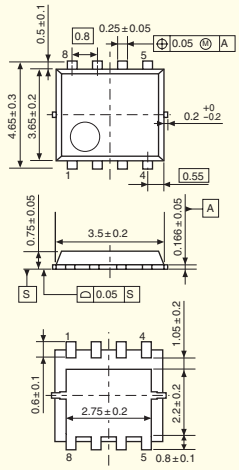


Packing quantity	4000 pcs/reel

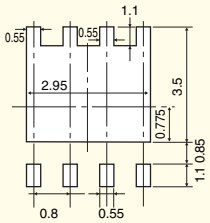
■ TSSOP Advance

Unit: mm

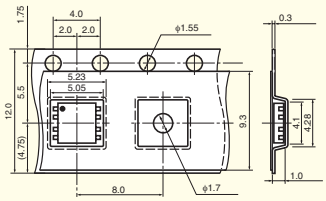
Package dimensions



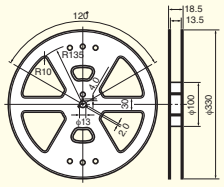
Typical PCB land pad dimensions



Tape dimensions



Reel dimensions

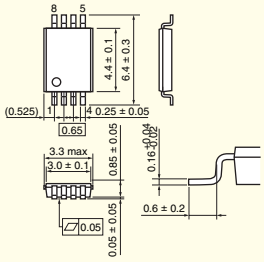


Packing quantity	3000 pcs/reel

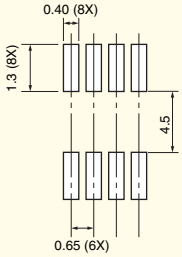
■ TSSOP-8

Unit: mm

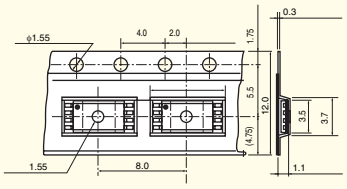
Package dimensions



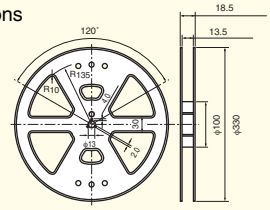
Typical PCB land pad dimensions



Tape dimensions



Reel dimensions

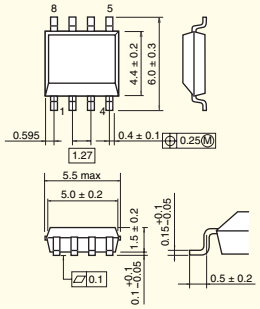


Packing quantity	3000 pcs/reel

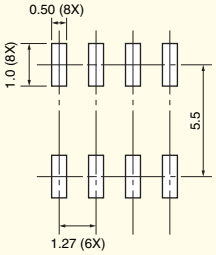
■ SOP-8

Unit: mm

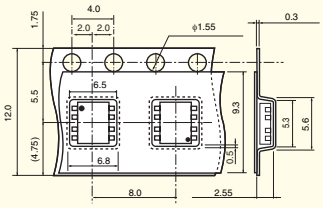
Package dimensions



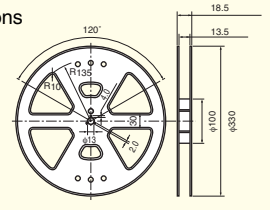
Typical PCB land pad dimensions



Tape dimensions



Reel dimensions

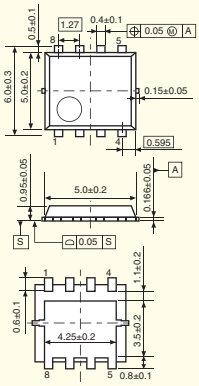


Packing quantity	3000 pcs/reel

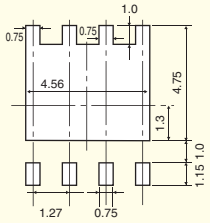
■ SOP Advance

Unit: mm

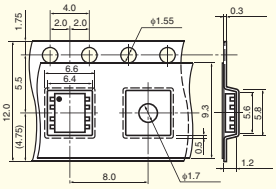
Package dimensions



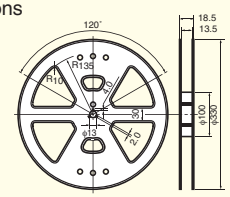
Typical PCB land pad dimensions



Tape dimensions



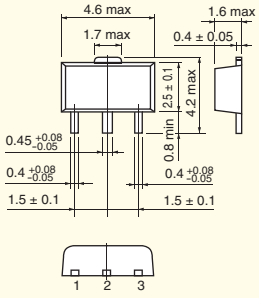
Reel dimensions



Packing quantity	3000 pcs/reel

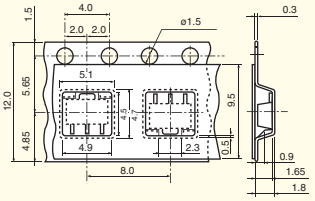
■ PW-Mini

Unit: mm

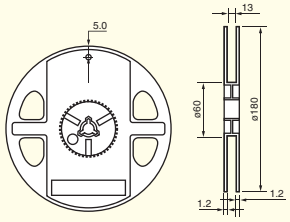


1. Gate
2. Drain (Heatsink)
3. Source

Tape dimensions



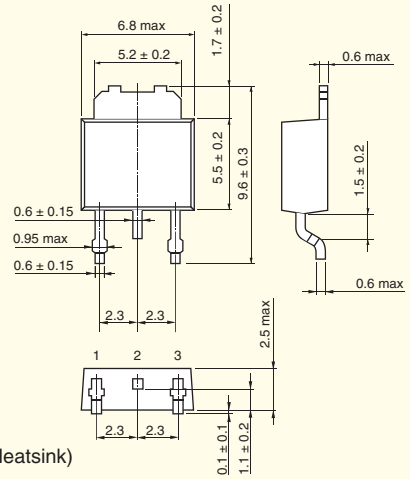
Reel dimensions



Packing quantity	1000 pcs/reel

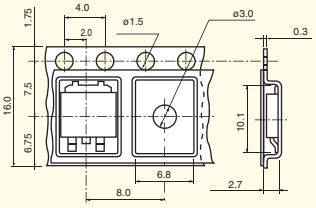
■ DP

Unit: mm

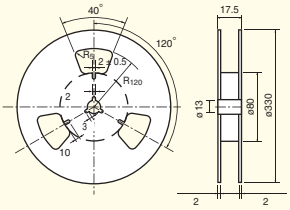


1. Gate
2. Drain (Heatsink)
3. Source

Tape dimensions



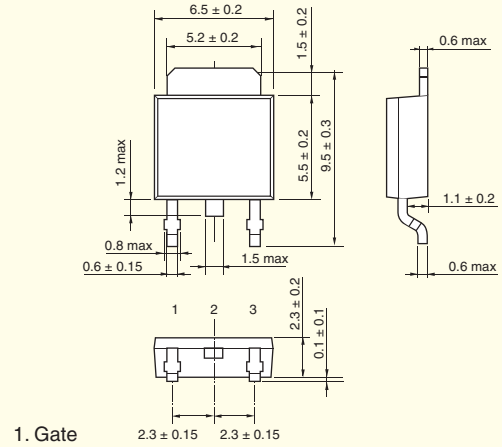
Reel dimensions



Packing quantity	2000 pcs/reel

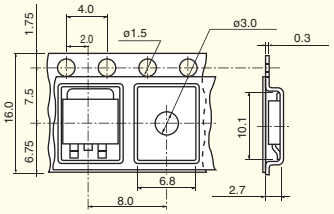
■ New PW-Mold

Unit: mm

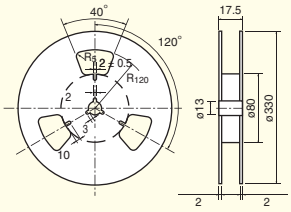


1. Gate
2. Drain (Heatsink)
3. Source

Tape dimensions



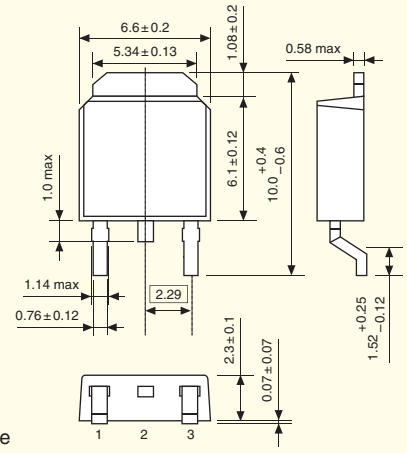
Reel dimensions



Packing quantity	2000 pcs/reel

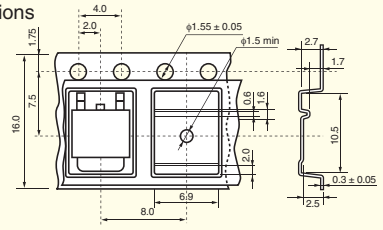
■ DPAK

Unit: mm

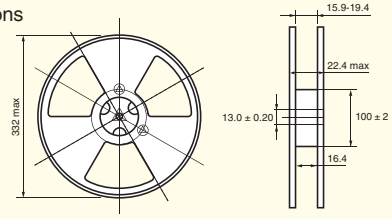


1. Gate
2. Drain (Heatsink)
3. Source

Tape dimensions



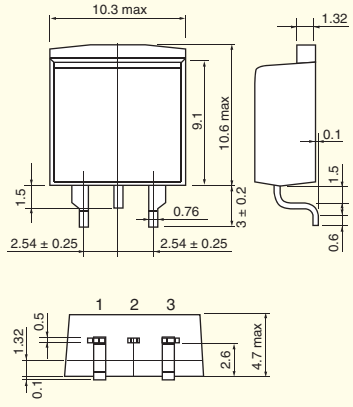
Reel dimensions



Packing quantity	2000 pcs/reel

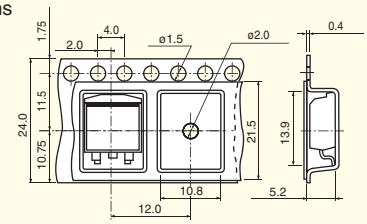
■ TO-220SM

Unit: mm

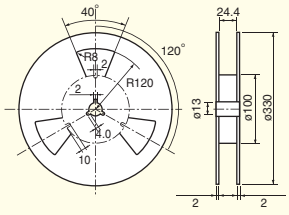


1. Gate
2. Drain (Heatsink)
3. Source

Tape dimensions



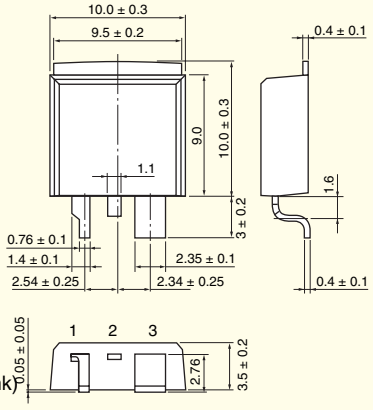
Reel dimensions



Packing quantity	1000 pcs/reel

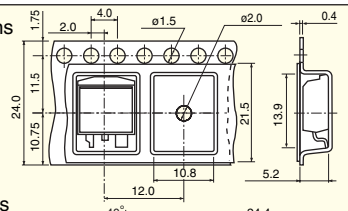
■ TO-220SM(W)

Unit: mm

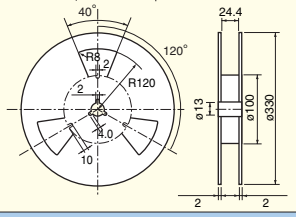


1. Gate
2. Drain (Heatsink)
3. Source

Tape dimensions



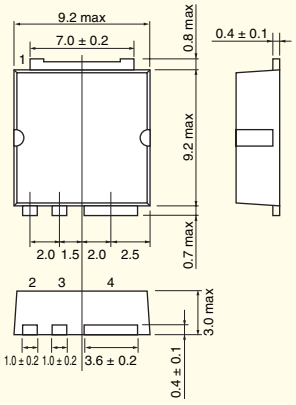
Reel dimensions



Packing quantity 1000 pcs/reel

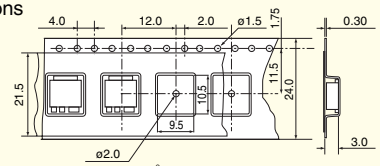
■ TFP

Unit: mm

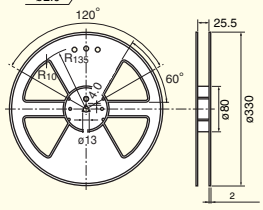


1. Drain (Heatsink)
2. Gate
3. Source 1
4. Source 2

Tape dimensions



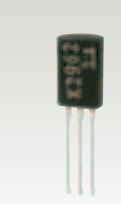
Reel dimensions

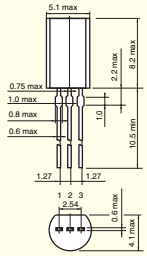


Packing quantity 1500 pcs/reel

9-2 Through-Hole Packages

■ LSTM

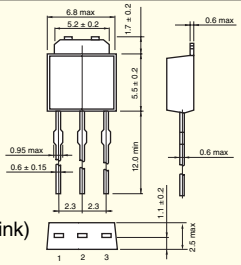




1. Source
2. Drain
3. Gate

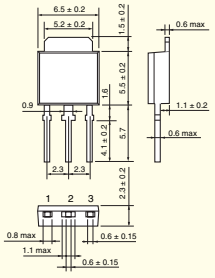
■ PW-Mold (Straight)

Unit: mm



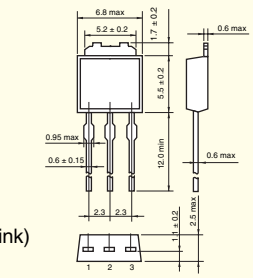
1. Gate
2. Drain (Heatsink)
3. Source

■ New PW-Mold2



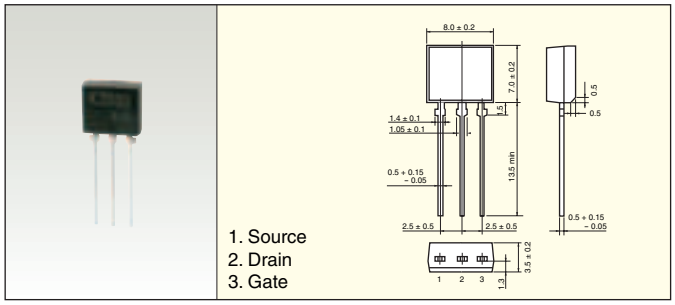
1. Gate
2. Drain (Heatsink)
3. Source

■ DP (Straight)



1. Gate
2. Drain (Heatsink)
3. Source

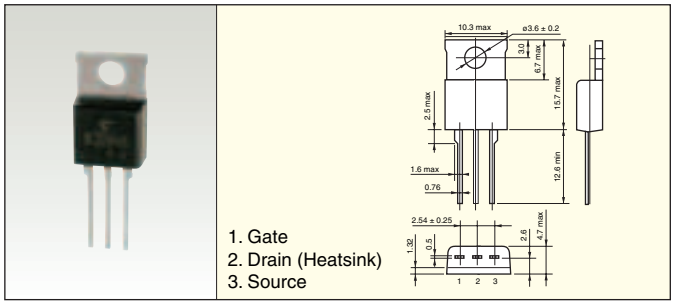
■ TPS



1. Source
2. Drain
3. Gate

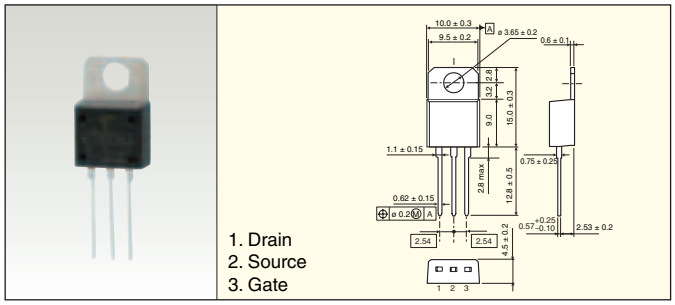
■ TO-220AB

Unit: mm



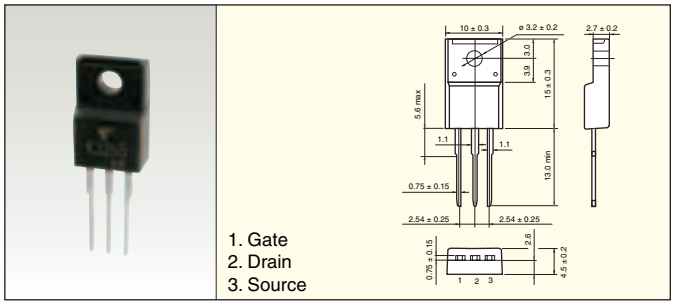
1. Gate
2. Drain (Heatsink)
3. Source

■ TO-220(W)



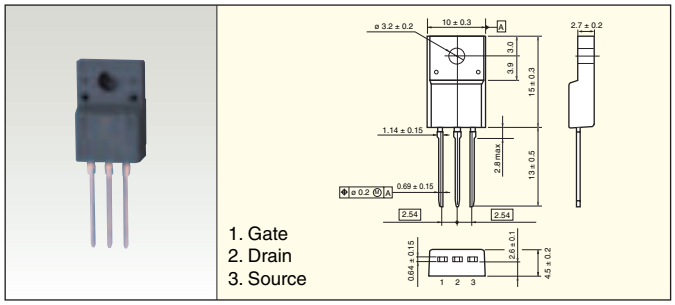
1. Drain
2. Source
3. Gate

■ TO-220NIS



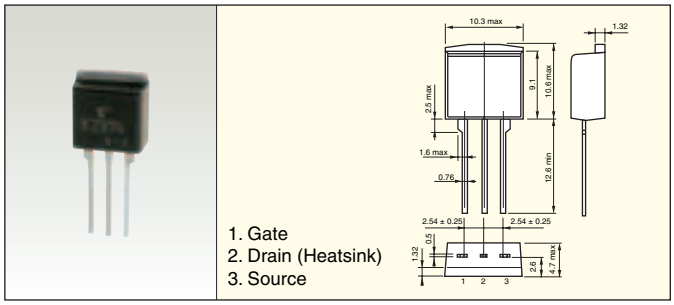
1. Gate
2. Drain
3. Source

■ TO-220SIS



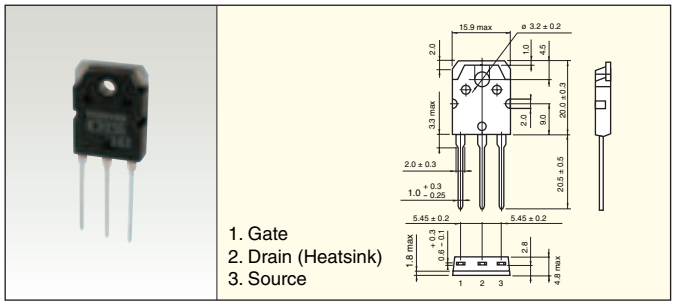
1. Gate
2. Drain
3. Source

■ TO-220FL



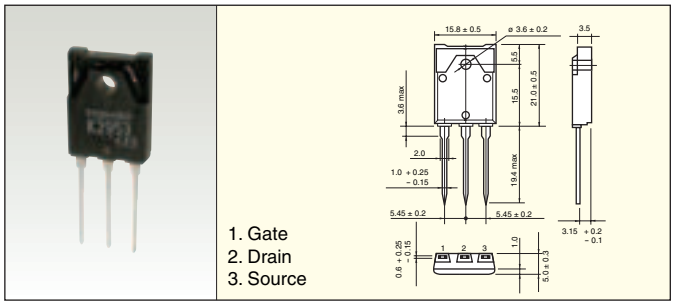
1. Gate
2. Drain (Heatsink)
3. Source

■ TO-3P(N)



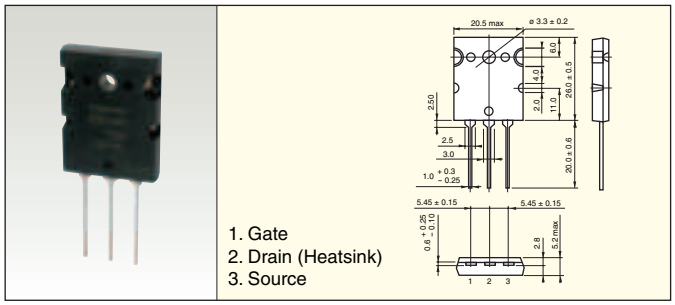
1. Gate
2. Drain (Heatsink)
3. Source

■ TO-3P(N)IS



1. Gate
2. Drain
3. Source

■ TO-3P(L)



1. Gate
2. Drain (Heatsink)
3. Source

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